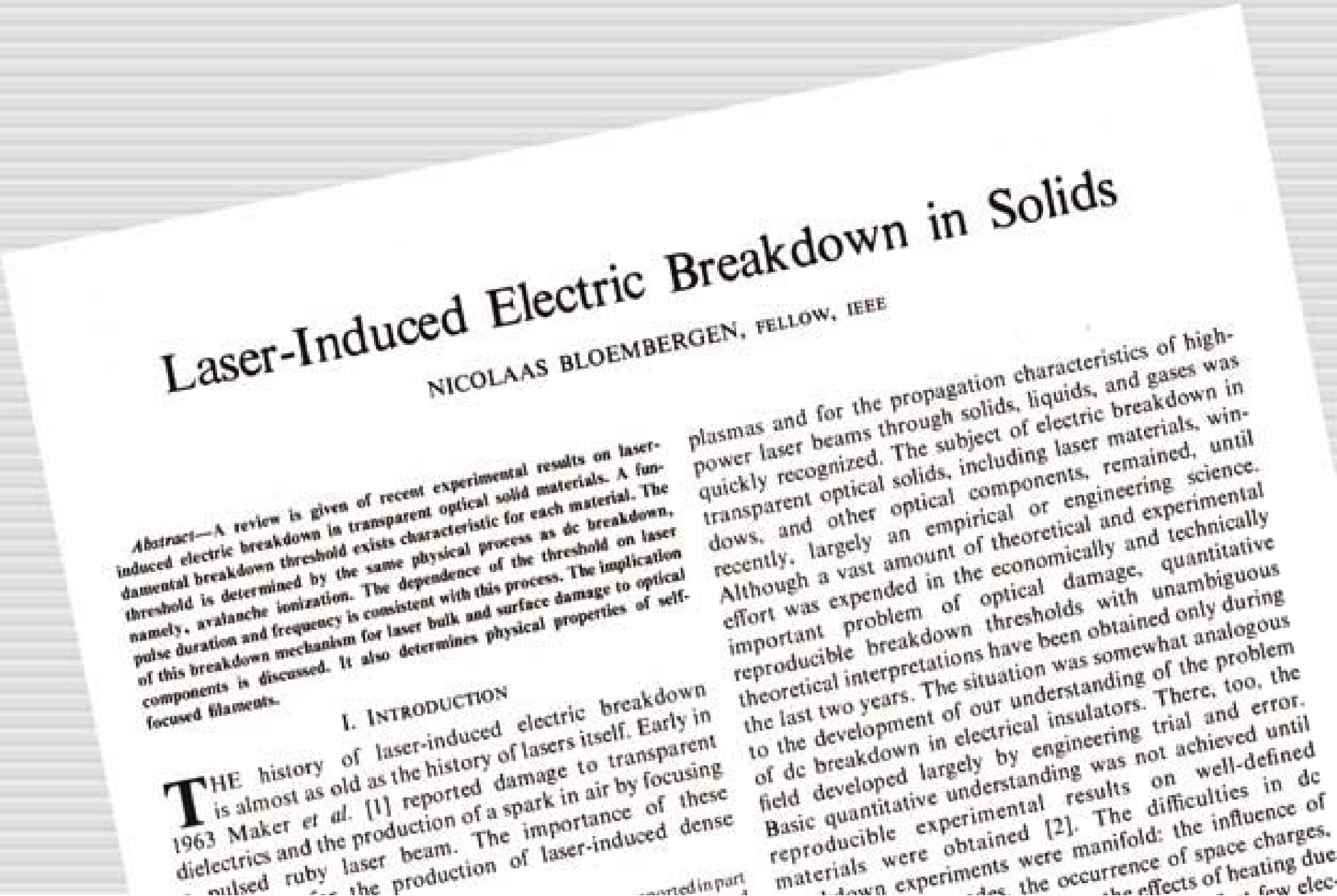
Femtosecond laser micromachining: a new tool for materials and life sciences

Eric Mazur

AP298r
Cambridge, MA, 3 March 2004

Introduction



Laser-Induced Electric Breakdown in Solids

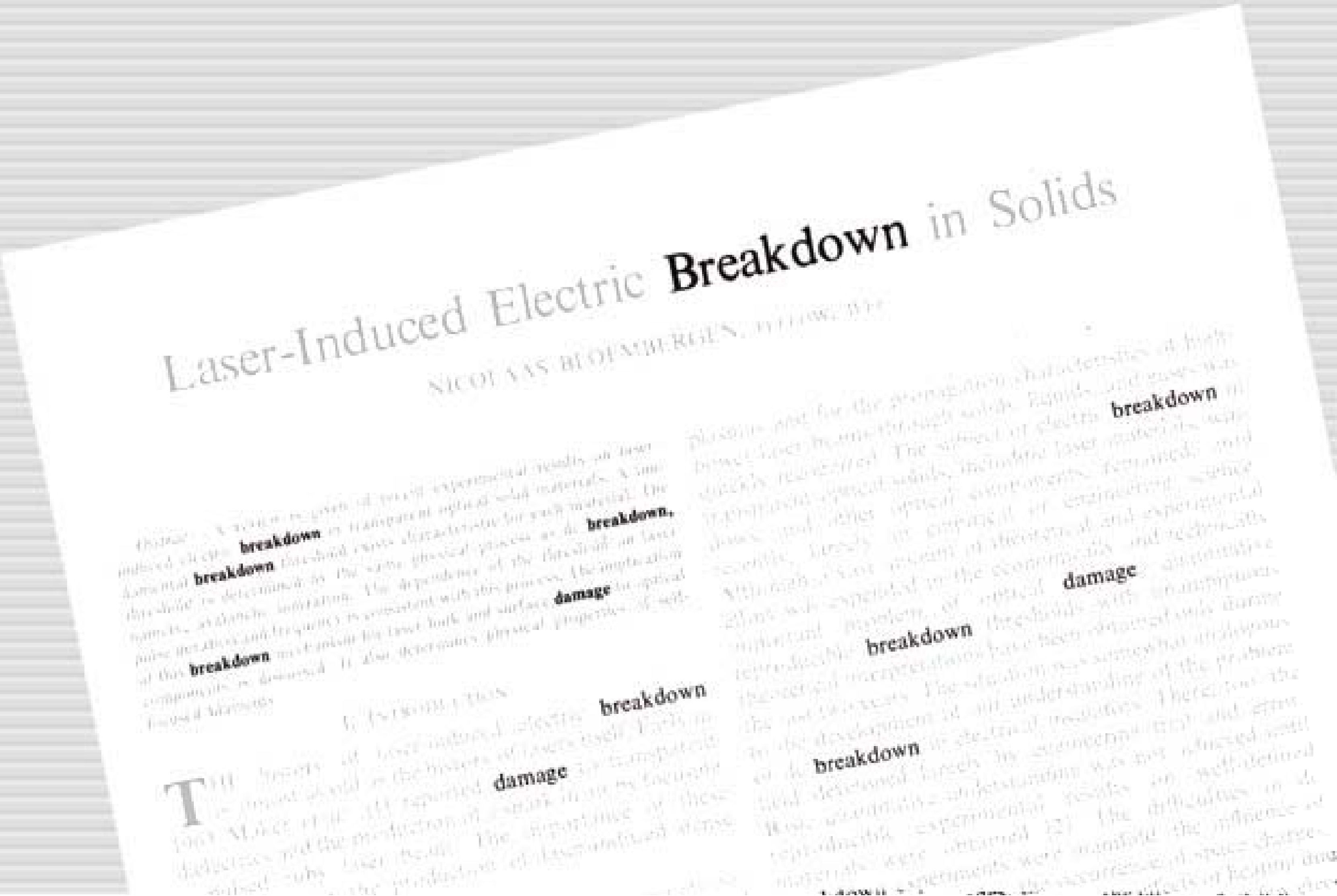
NICOLAAS BLOEMBERGEN, FELLOW, IEEE

Abstract—A review is given of recent experimental results on laser-induced electric breakdown in transparent optical solid materials. A fundamental breakdown threshold exists characteristic for each material. The threshold is determined by the same physical process as dc breakdown, namely, avalanche ionization. The dependence of the threshold on laser pulse duration and frequency is consistent with this process. The implication of this breakdown mechanism for laser bulk and surface damage to optical components is discussed. It also determines physical properties of self-focused filaments.

I. Introduction

THE history of laser-induced electric breakdown is almost as old as the history of lasers itself. Early in 1963 Maker *et al.* [1] reported damage to transparent dielectrics and the production of a spark in air by focusing a pulsed ruby laser beam. The importance of these ... for the production of laser-induced dense plasmas and for the propagation characteristics of high-power laser beams through solids, liquids, and gases was quickly recognized. The subject of electric breakdown in transparent optical solids, including laser materials, windows, and other optical components, remained, until recently, largely an empirical or engineering science. Although a vast amount of theoretical and experimental effort was expended in the economically and technically important problem of optical damage, quantitative reproducible breakdown thresholds with unambiguous theoretical interpretations have been obtained only during the last two years. The situation was somewhat analogous to the development of our understanding of the problem of dc breakdown in electrical insulators. There, too, the field developed largely by engineering trial and error. Basic quantitative understanding was not achieved until reproducible experimental results on well-defined materials were obtained [2]. The difficulties in dc breakdown experiments were manifold: the influence of space charges, the occurrence of heating due ... the effects of ...

Introduction



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Introduction

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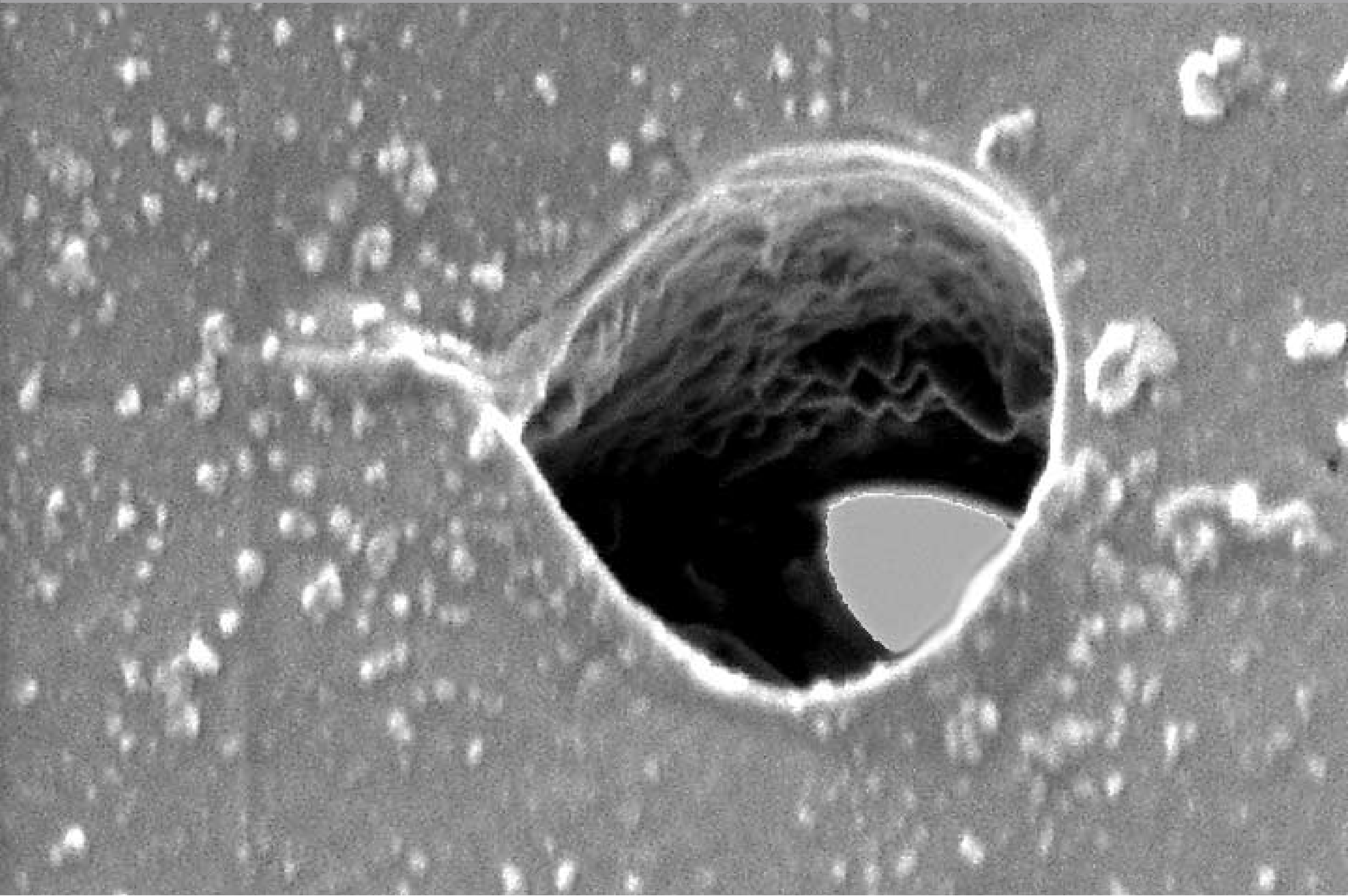
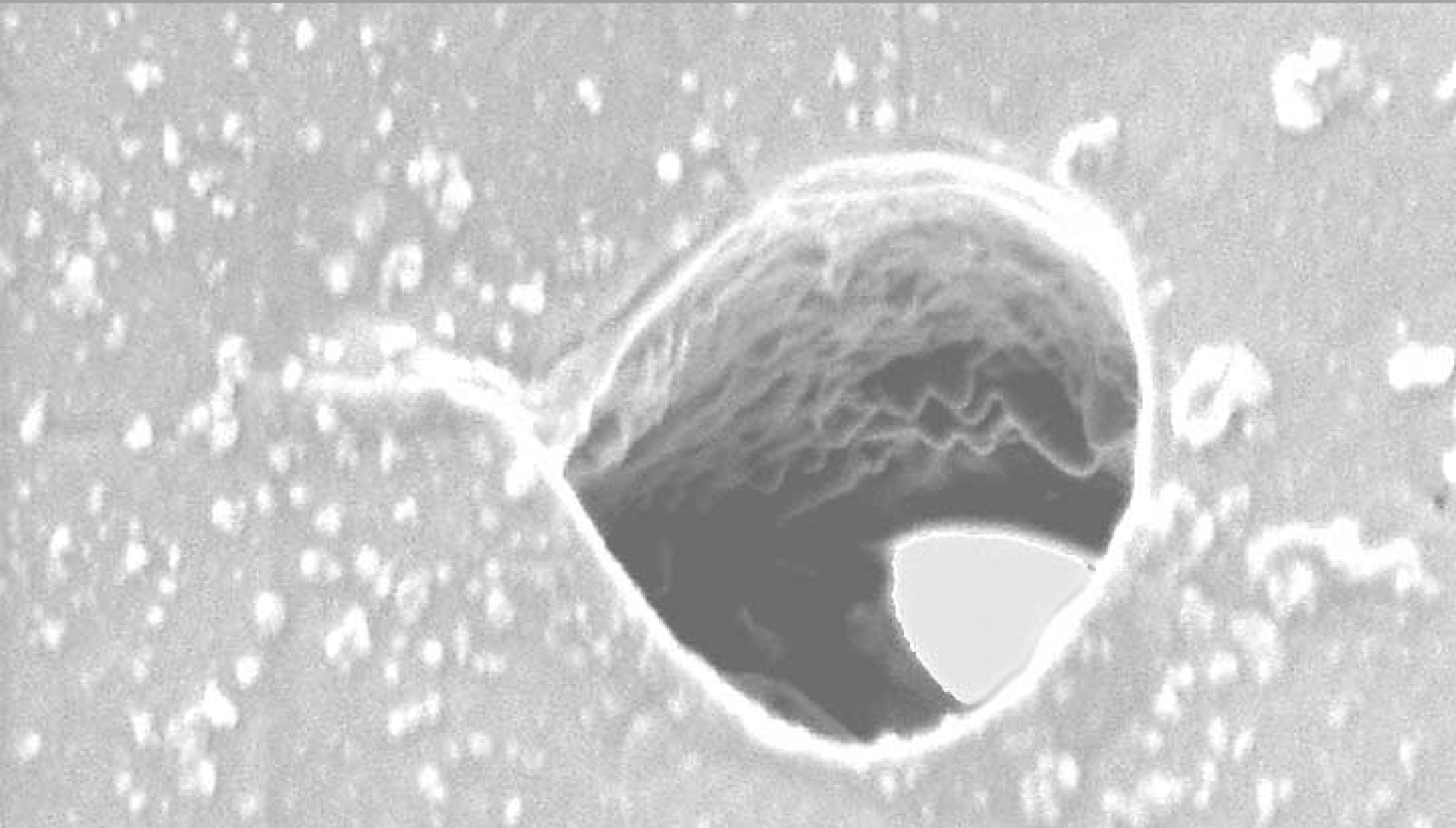
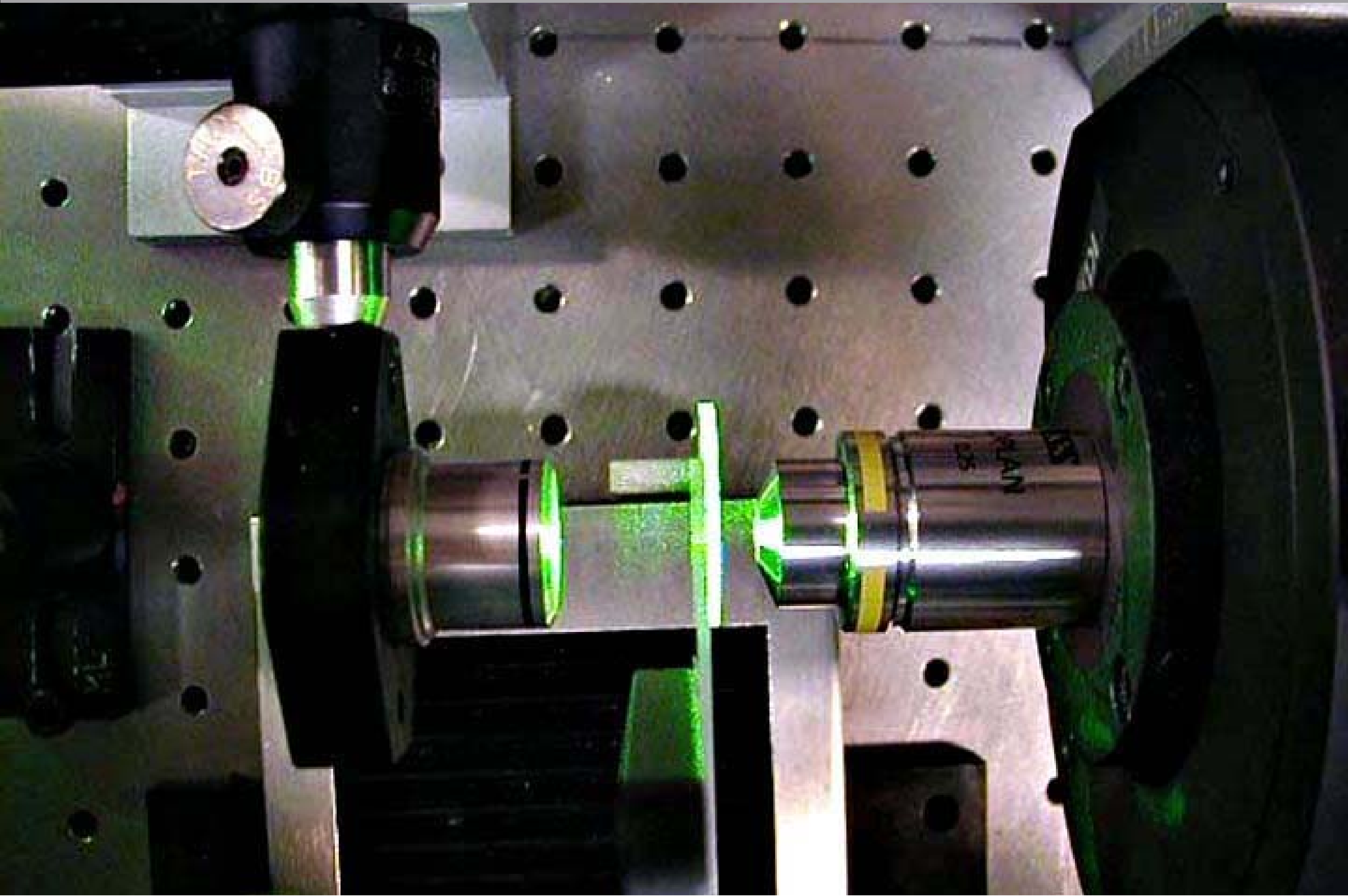




use damage for processing!

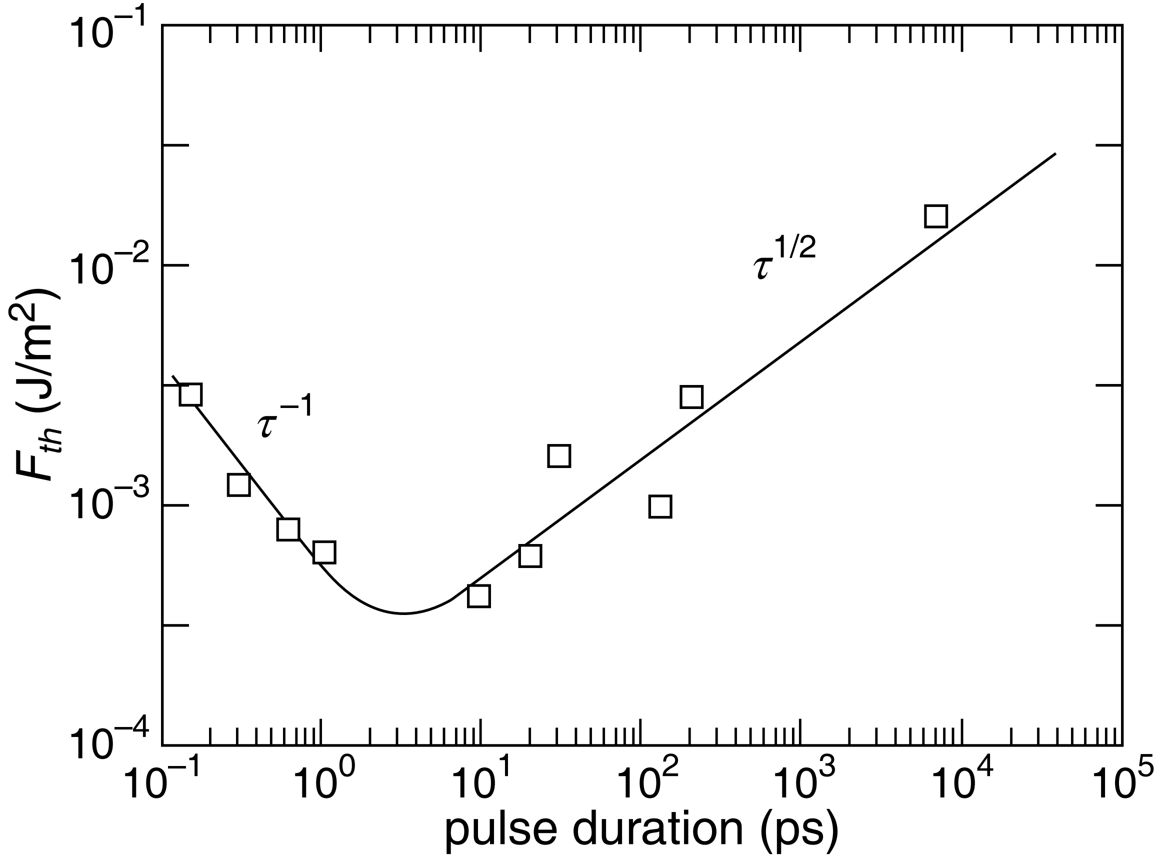
Outline



Outline

- Processing with fs pulses
- Role of focusing
- Low-energy processing

Processing with fs pulses



Du *et al.*, *Appl. Phys. Lett.* 64, 3071 (1994)

Processing with fs pulses

216 J. Opt. Soc. Am. B/Vol. 13, No. 1/January 1996

Breakdown threshold and plasma formation in femtosecond laser–solid interaction

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Combining femtosecond pump–probe techniques with optical microscopy, we have studied laser-induced optical breakdown in optically transparent solids with high temporal and spatial resolution. The threshold of plasma formation has been determined from measurements of the changes of the optical reflectivity associated with the developing plasma. It is shown that plasma generation occurs at the surface. We have observed a remarkable resistance to optical breakdown and material damage in the interaction of femtosecond laser pulses with bulk optical materials.

1. INTRODUCTION

The interaction of intense femtosecond laser pulses with solids offers the possibility of producing a new class of plasmas having approximately solid-state density and spatial density scale lengths much smaller than the wavelength of light. These high-density plasmas with extremely sharp density gradients are currently of great interest, particularly from the point of view of generating ultrashort x-ray pulses. To produce such a ... from the intensity level ... formation to the ... time scale

One of the key points in the research of Bloembergen and his co-workers was the use of very tightly focused laser beams, which allowed them to reach the breakdown threshold of the materials while staying well below the critical power of self-focusing. Self-focusing is one of the major problems in the measurement of bulk breakdown thresholds. In a more recent review Soileau *et al.*[5] carefully examined the role of self-focusing in experiments measuring laser-induced breakdown of bulk dielectric materials. They concluded that the breakdown and damage thresholds are also strongly influenced by extrinsic effects.

Thus far, the issue of breakdown thresholds in femtosecond laser–solid interaction has barely been touched. ... recently, Du *et al.*[6] carried out laser-induced breakdown ... on fused silica with pulses ranging in ... as 150 fs. They reported ... threshold on ... of the

Processing with fs pulses

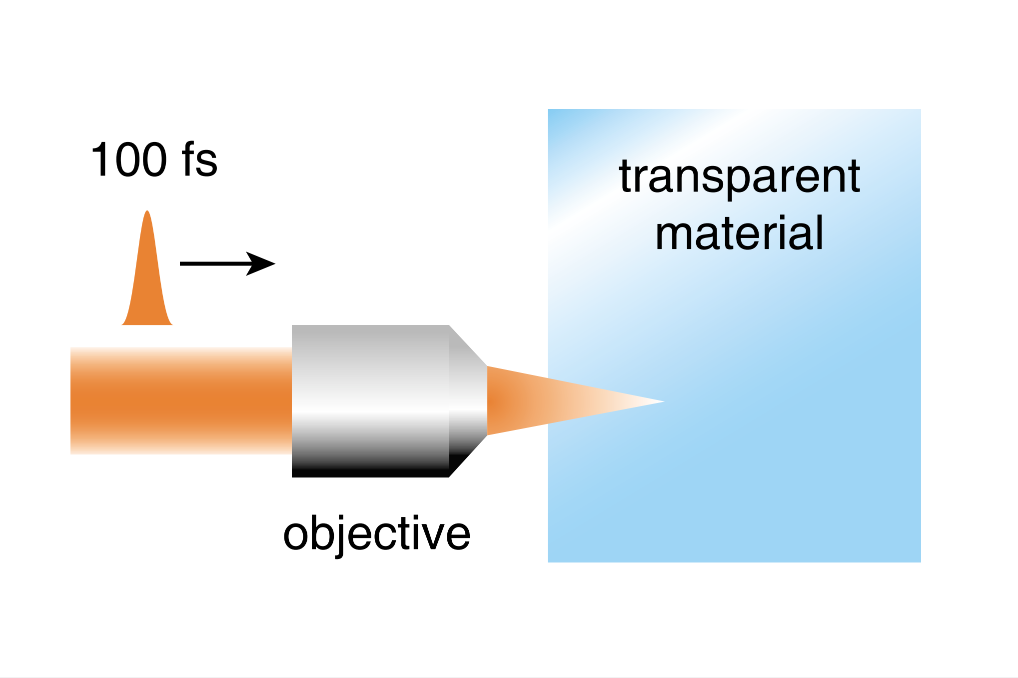
"… clear evidence that no bulk plasmas …

[and] … no bulk damage could be produced

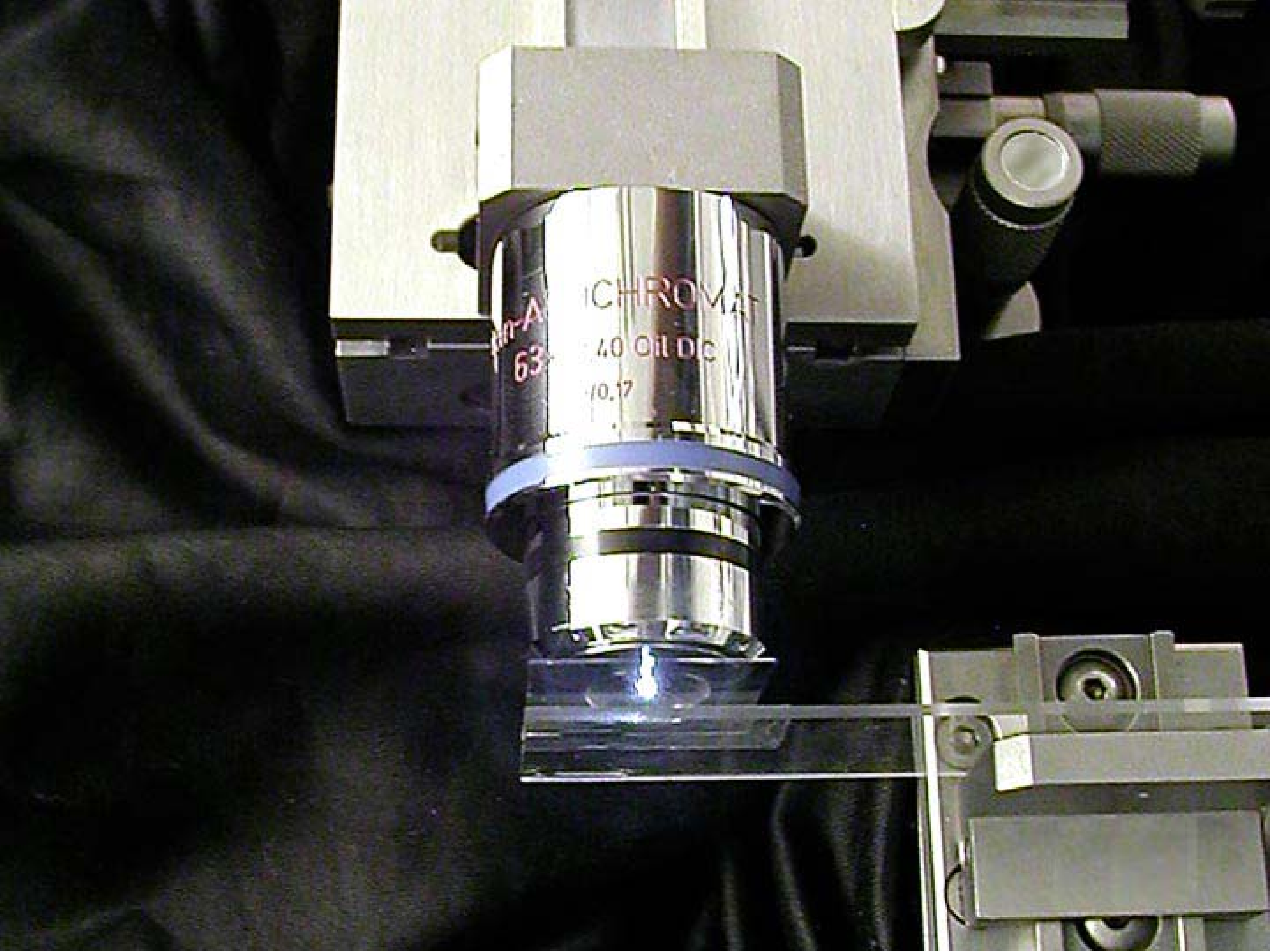
with femtosecond laser pulses."

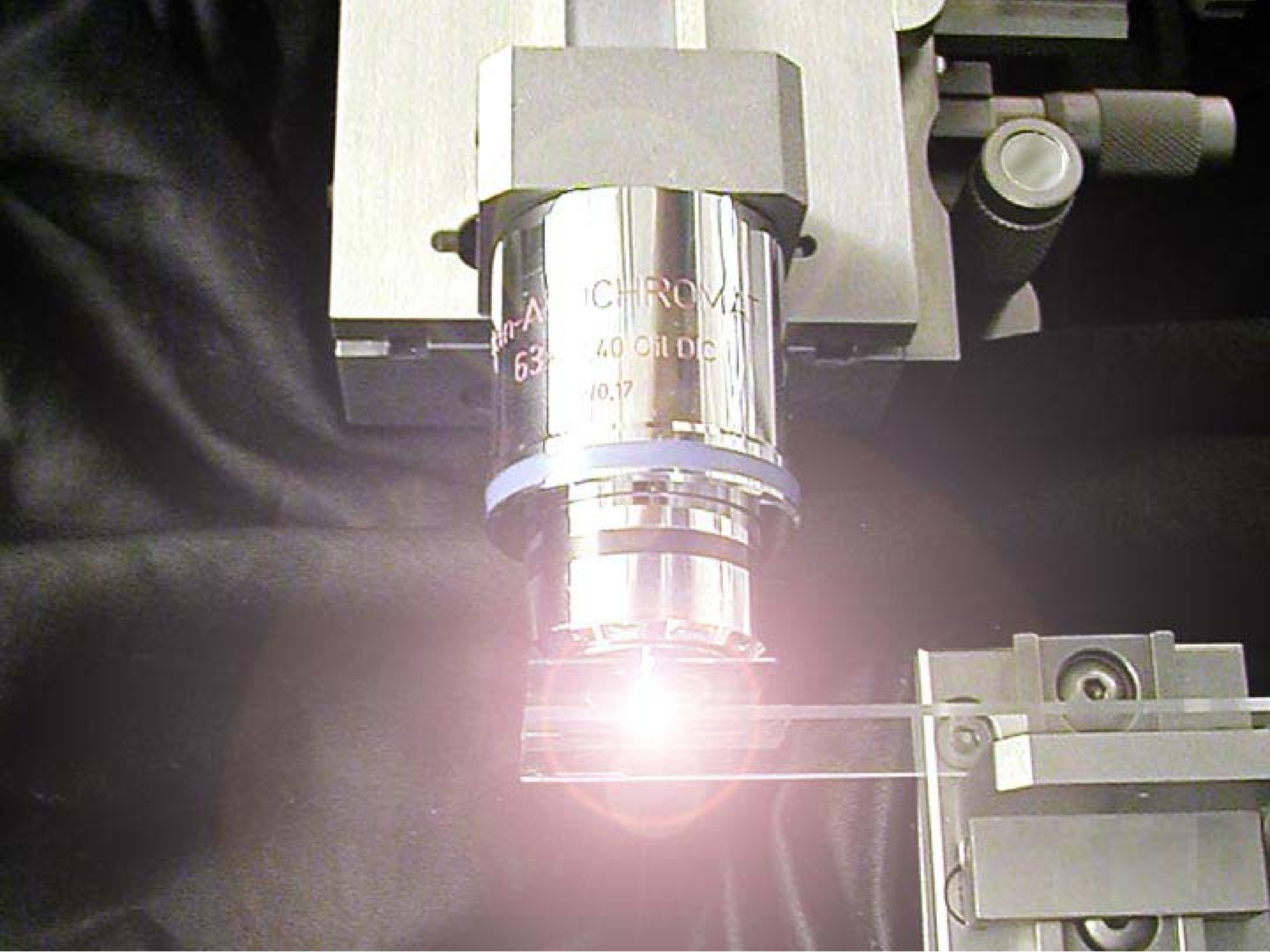
von der Linde, ***et al.*****,** ***J. Opt. Soc. Am.*** **13, 216 (1996)**

focus laser beam inside material

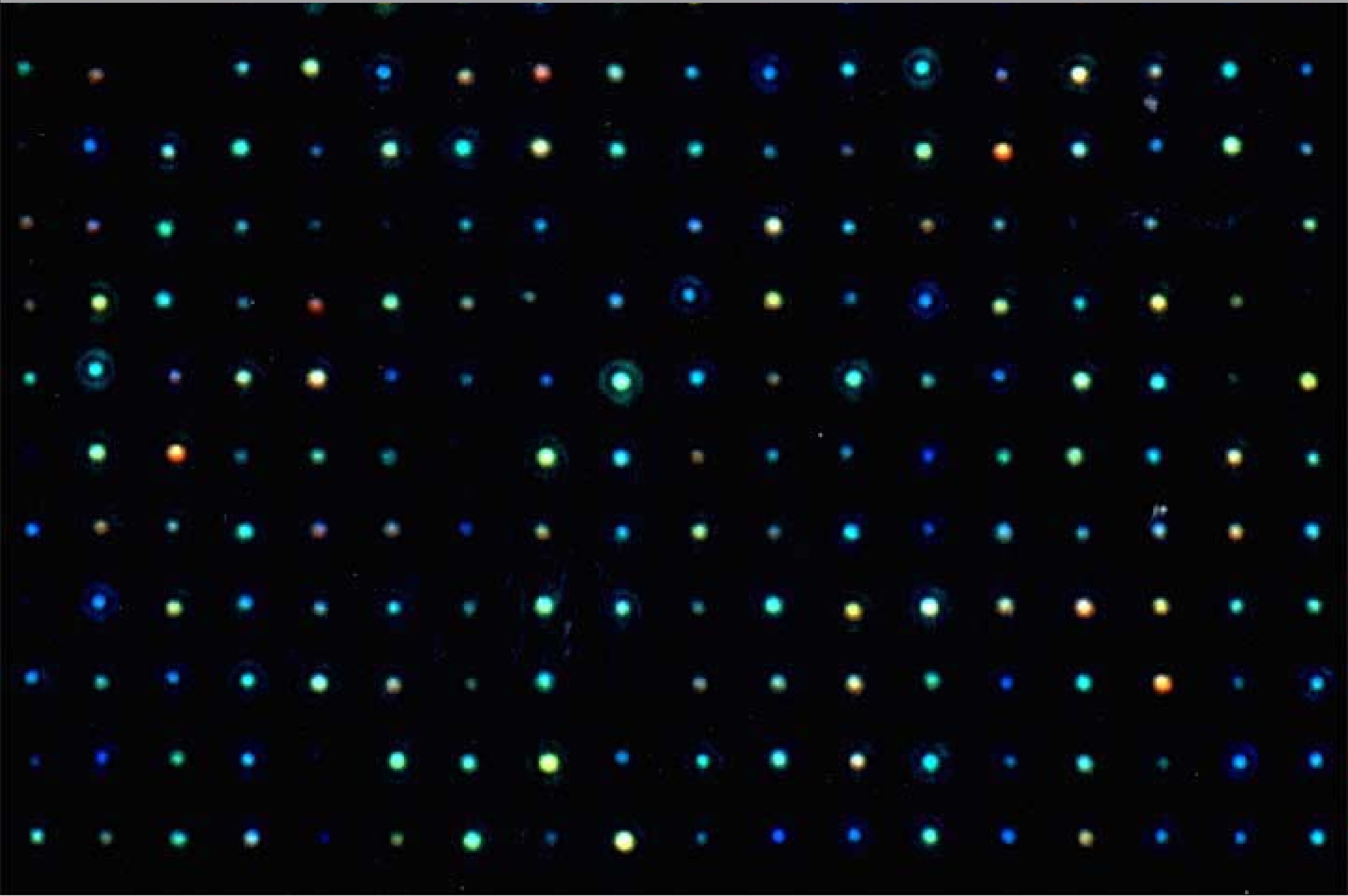


Glezer, *et al.*, *Opt. Lett.* 21, 2023 (1996)

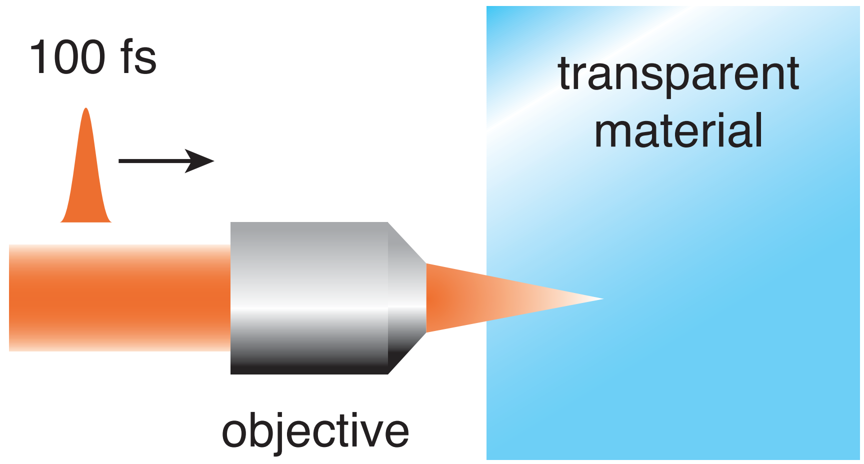

40 Oil DIC


40 Oil DIC
/0.17

Processing with fs pulses

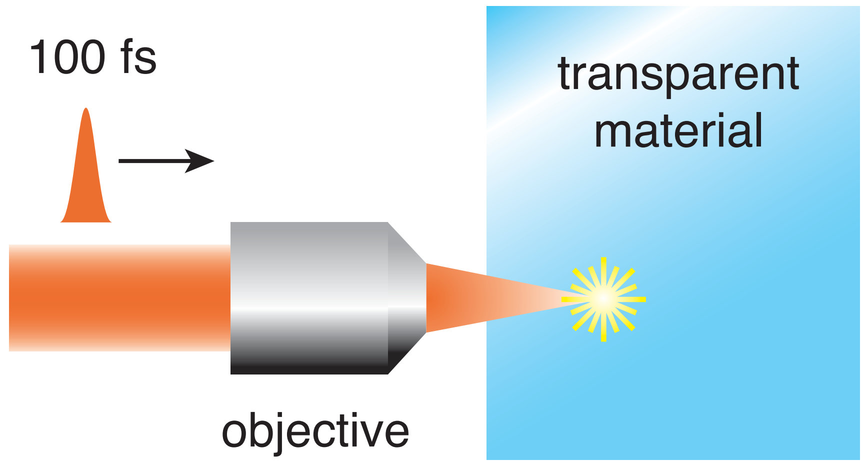


Processing with fs pulses



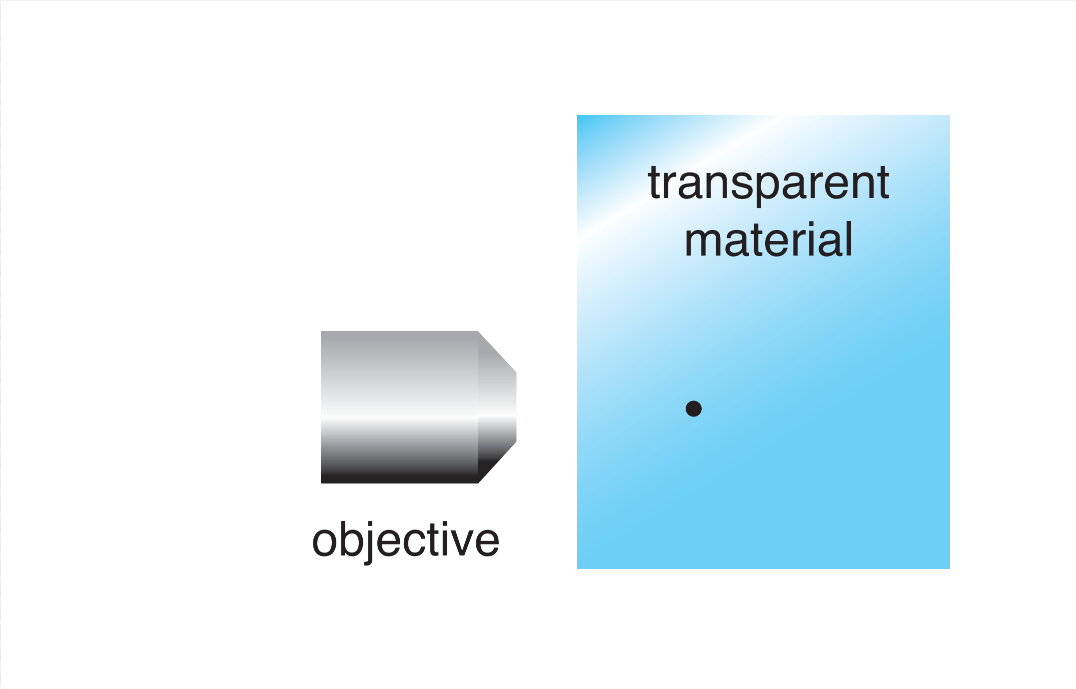
high in ensi y a focus…

Processing with fs pulses



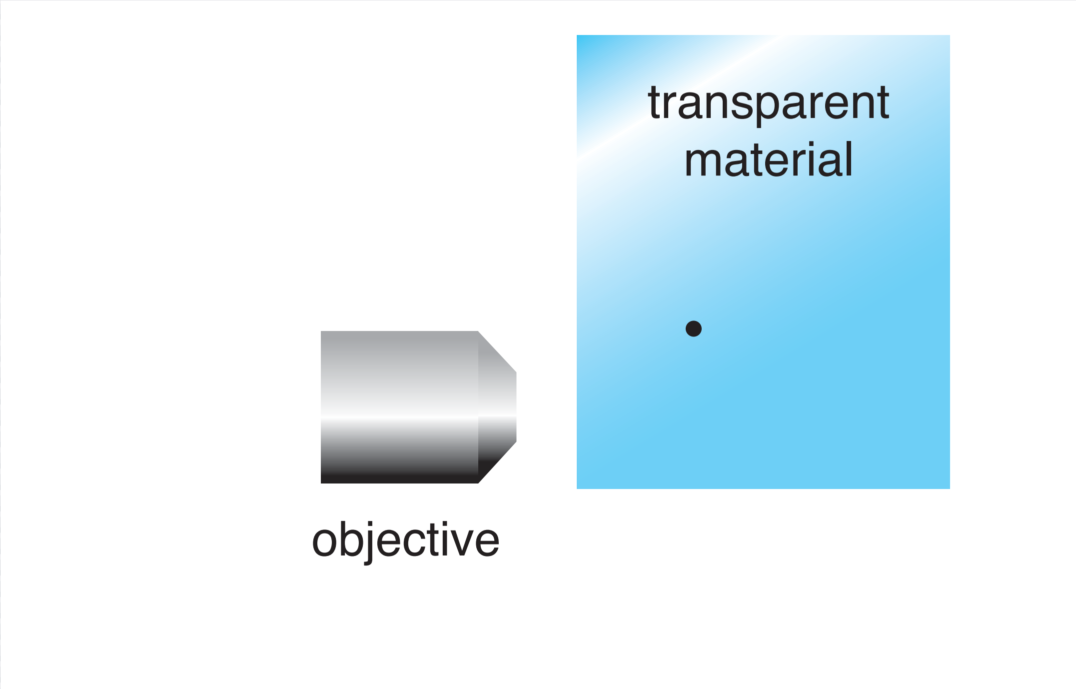
…causes nonlinear ioniza ion…

Processing with fs pulses



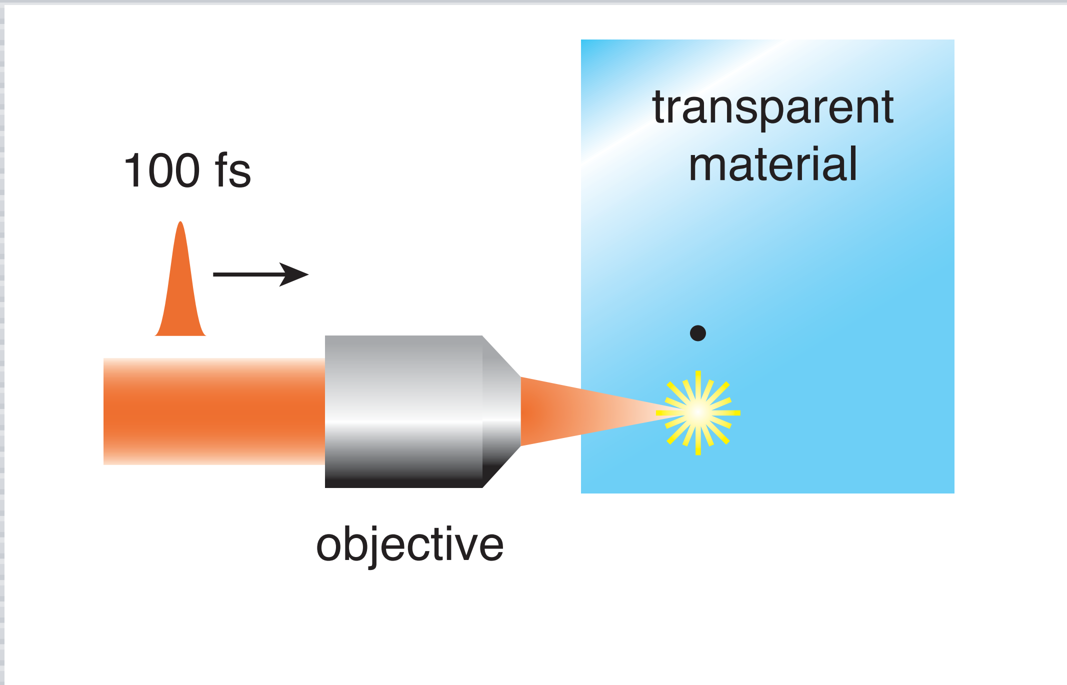
and 'microexplosion' causes microscopic damage

Processing with fs pulses



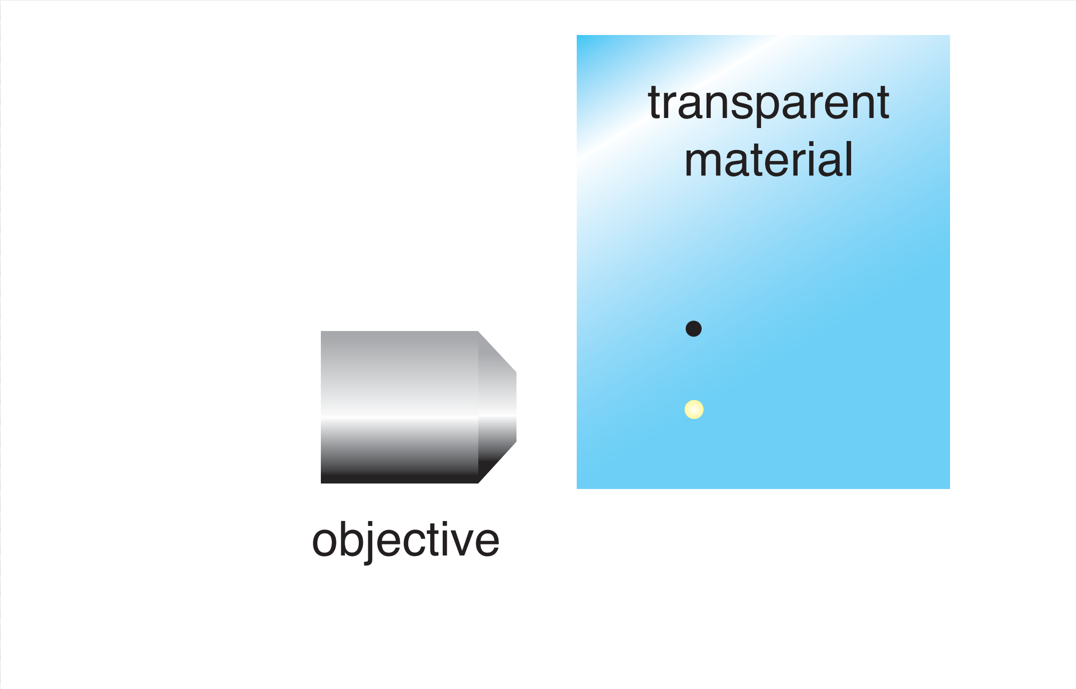
ransla e sample

Processing with fs pulses



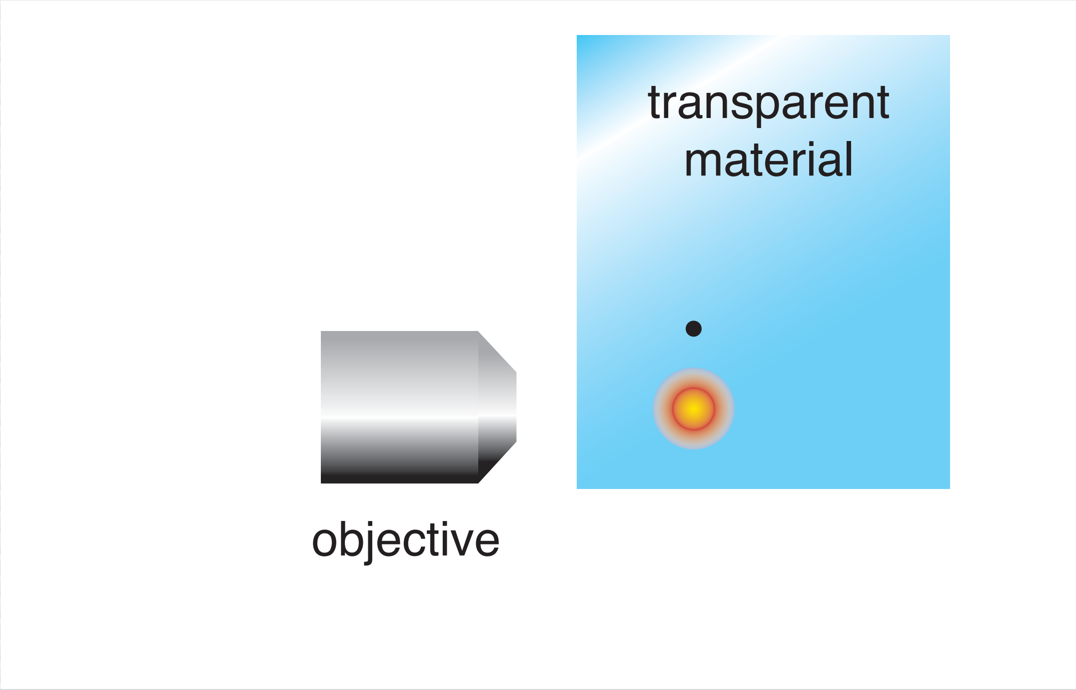
100 fs: laser energy ransfered o elec rons

Processing with fs pulses



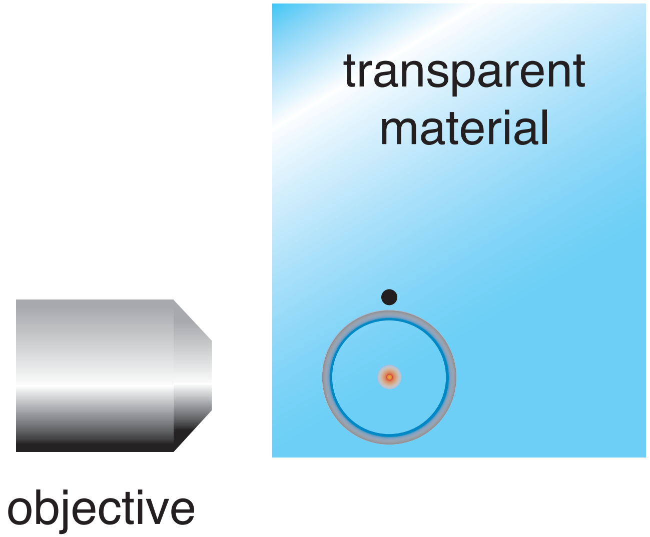
10 ps: energy ransfer o ions

Processing with fs pulses



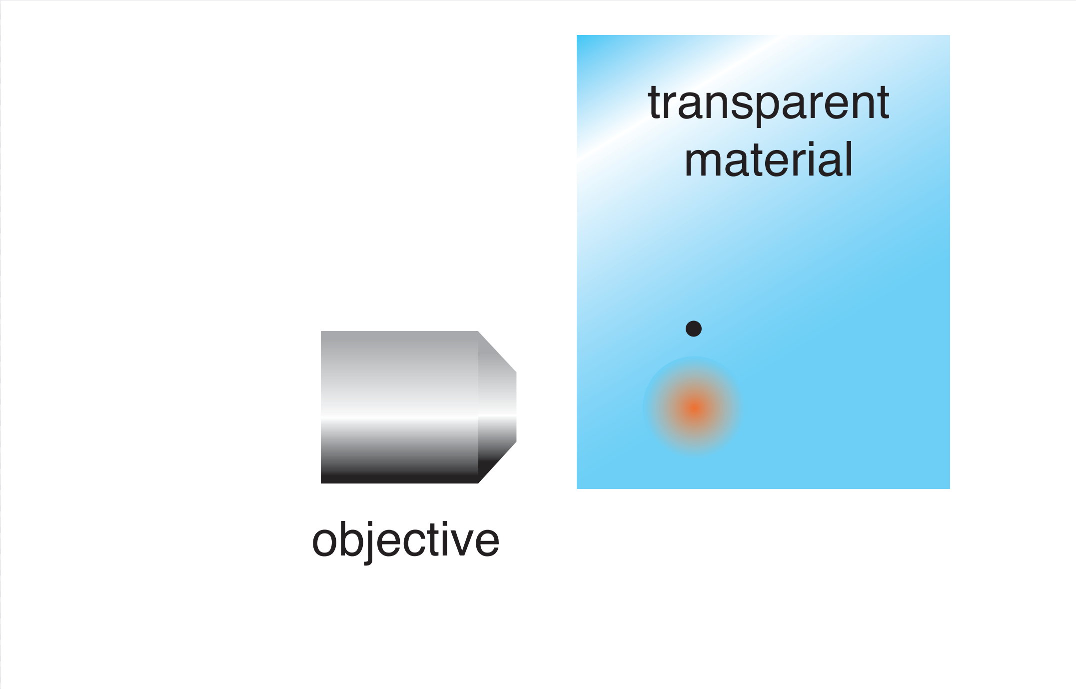
100 ps: plasma expansion

Processing with fs pulses



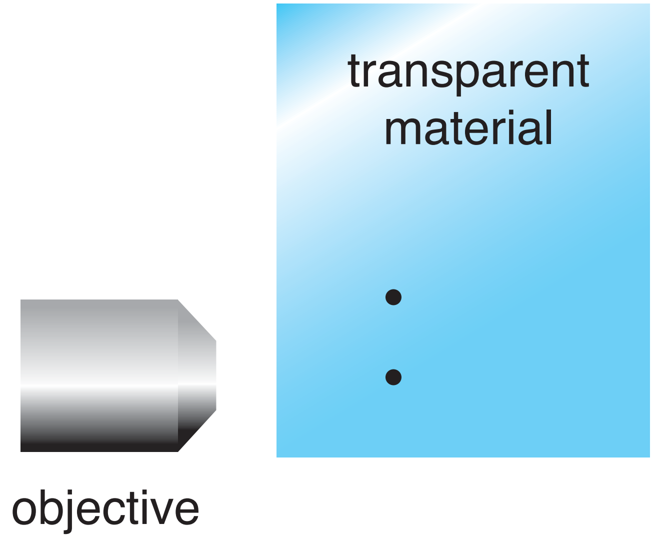
10–100 ns: shock propaga ion

Processing with fs pulses



1 µs: hermal expansion

Processing with fs pulses



1 ms: permanen s ruc ural damage

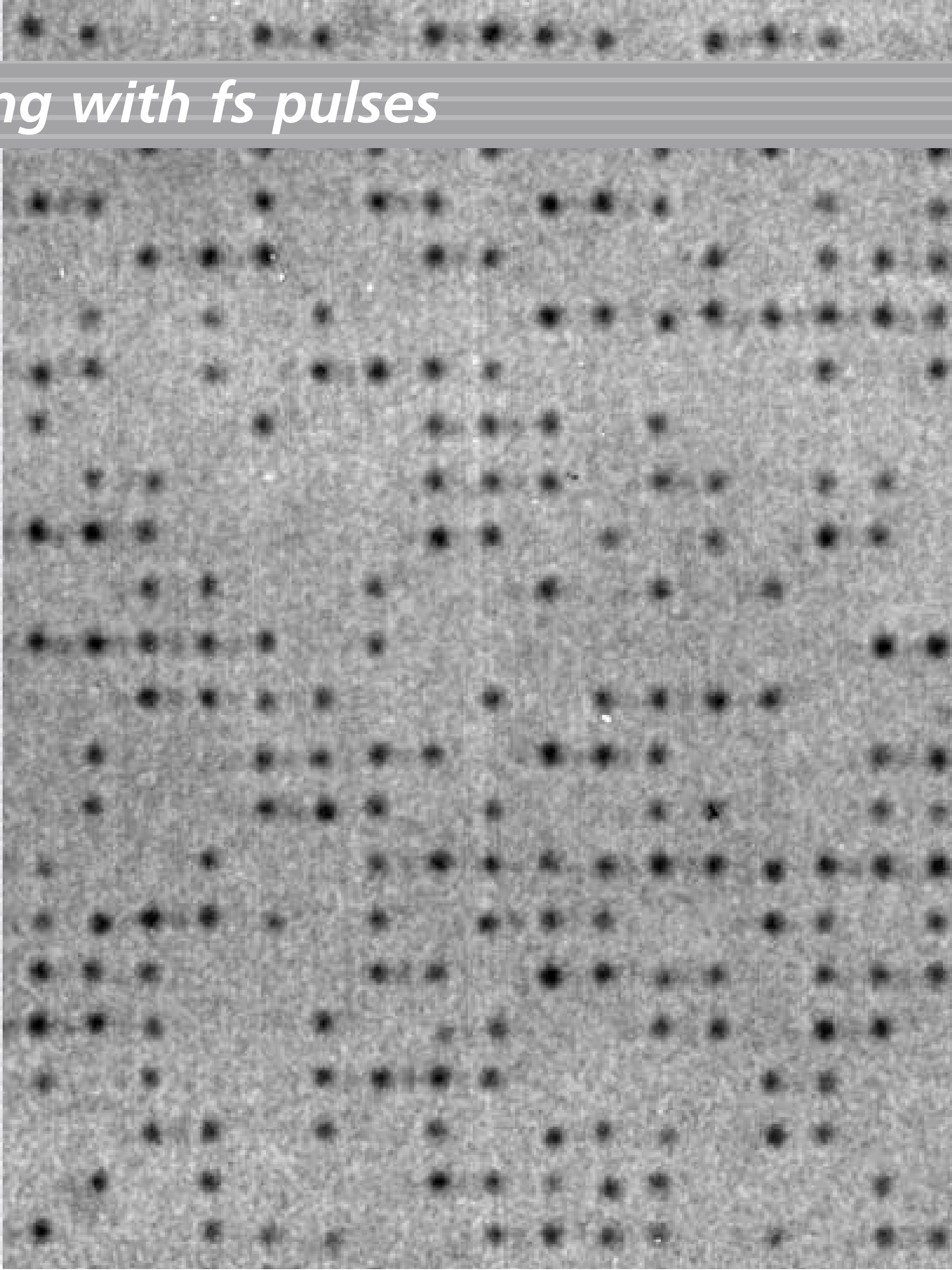
Processing with fs pulses

2 x 2 μm array

fused silica, 0.65 NA

0.5 μJ, 100 fs, 800 nm

***Opt. Lett.* 21, 2023 (1996)**



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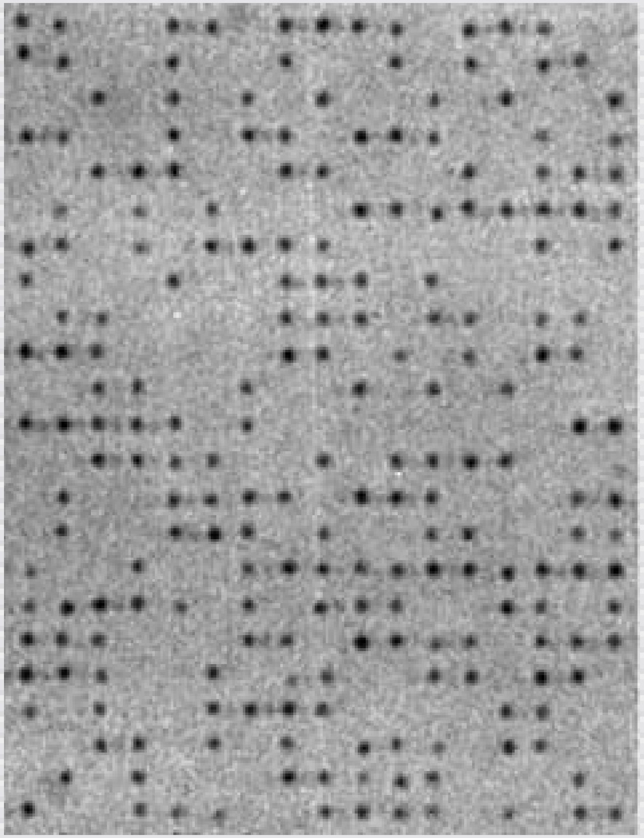

***Opt. Lett.* 21, 2023 (1996)**

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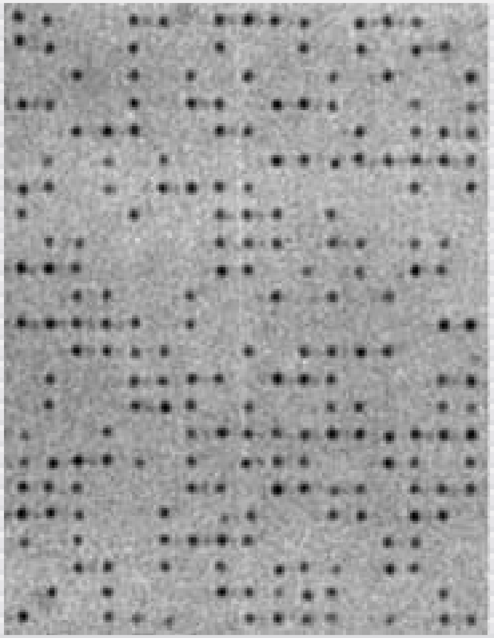

Opt. Lett. **21, 2023 (1996)**

Processing with fs pulses

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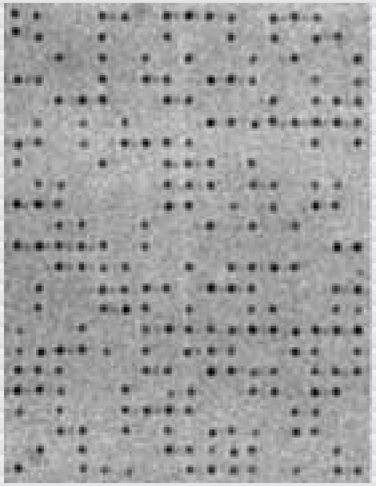
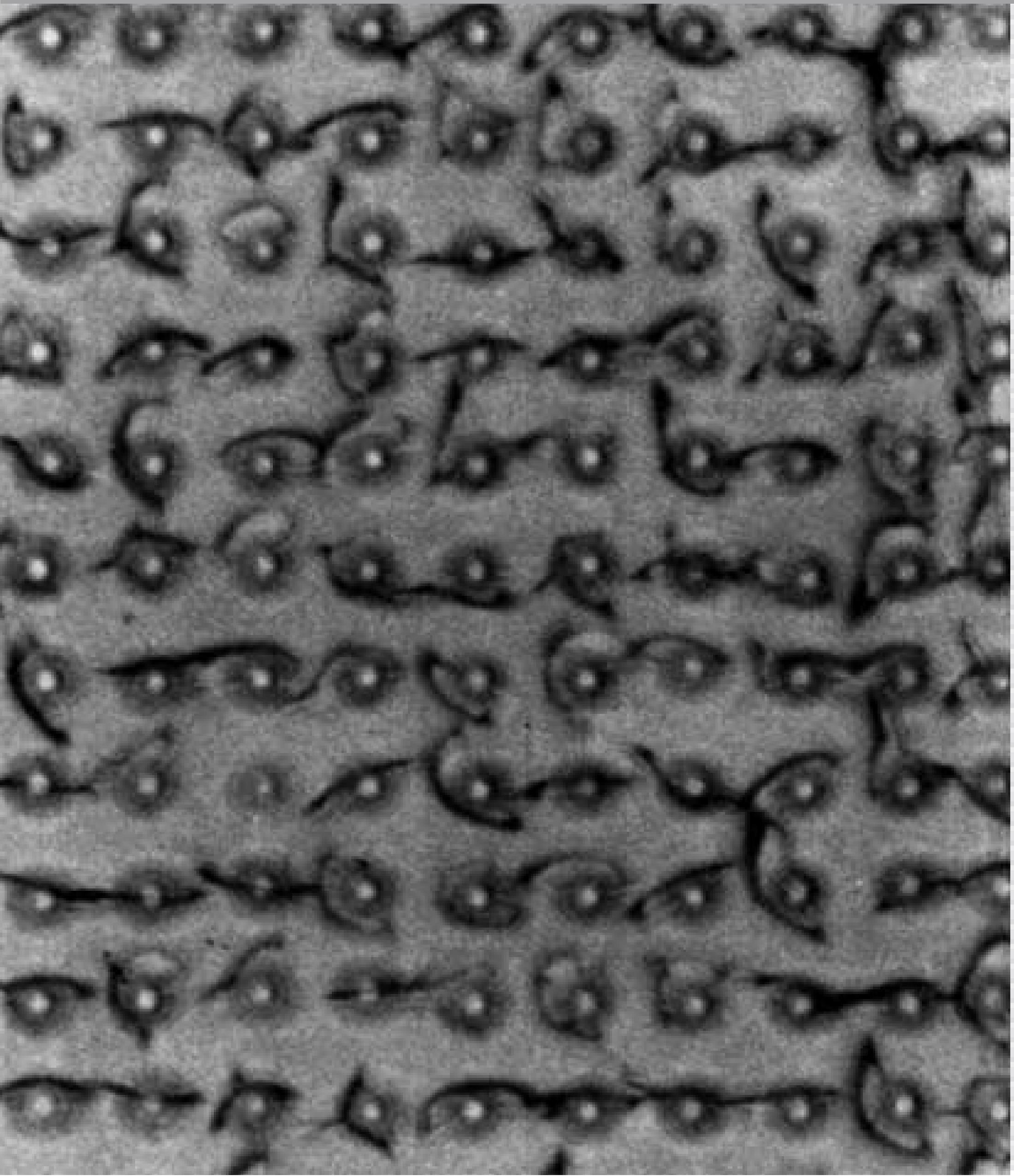
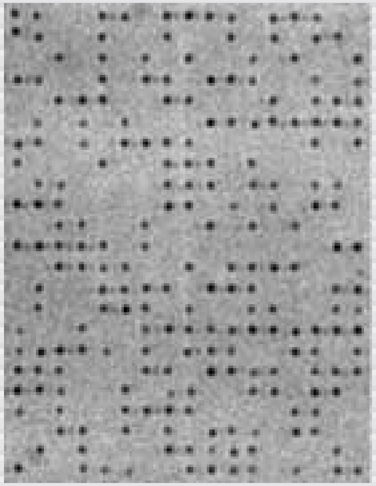


***Opt. Lett.* 21, 2023 (1996)**

Processing with fs pulses

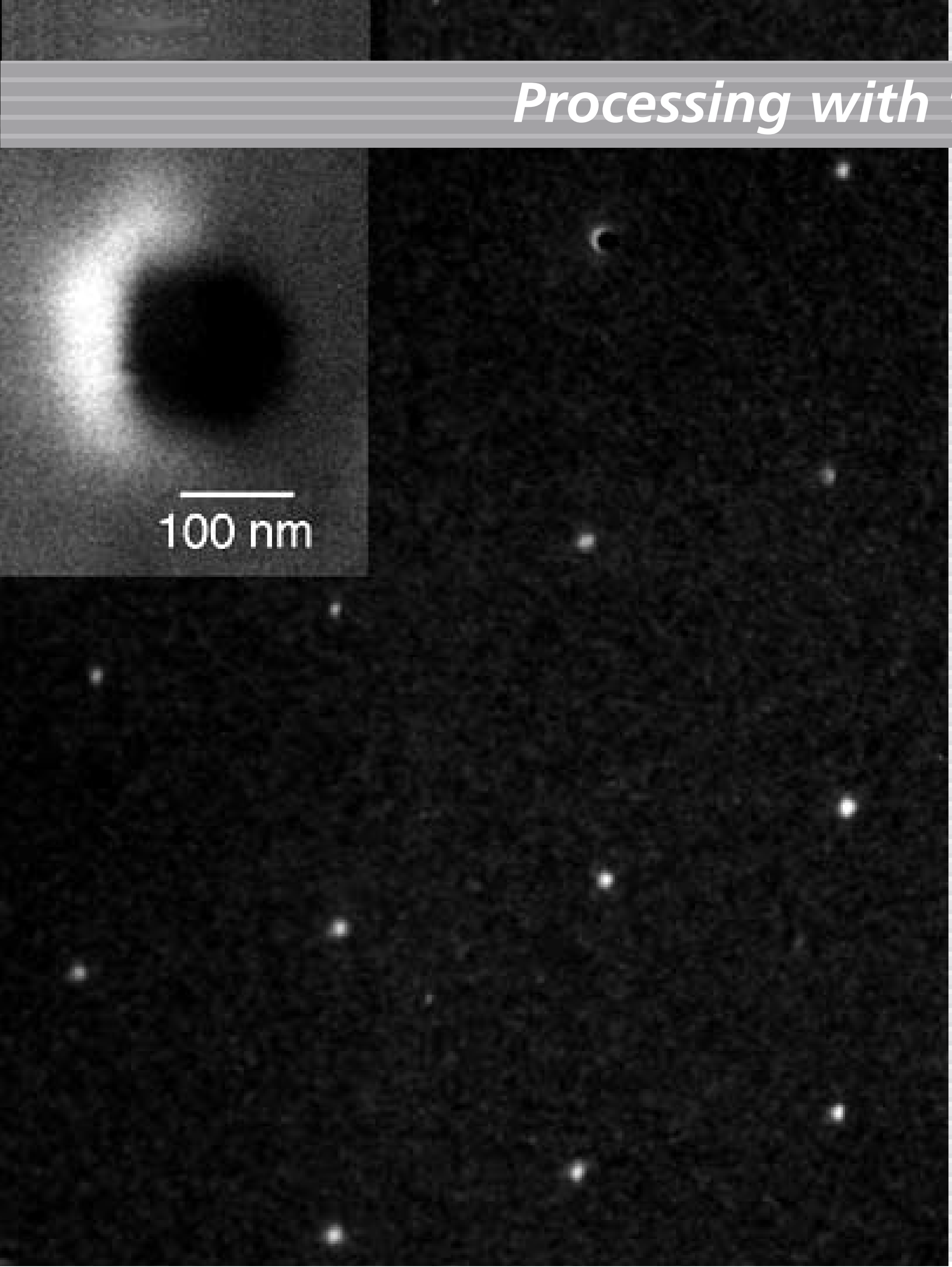


200 ps
9 µJ



100 fs
0.5 µJ

Processing with fs pulses



5 x 5 µm array

fused silica, 0.65 NA

0.5 µJ, 100 fs, 800 nm

***Opt. Lett.* 21, 2023 (1996)**

Processing with fs pulses

Points to keep in mind:

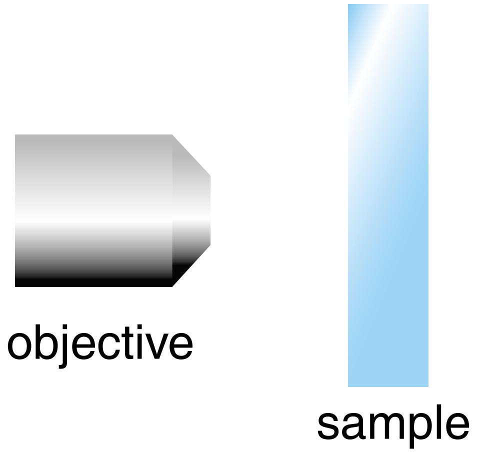
- **fs laser processing works**
- **focusing very important**
- **no collateral damage**

Outline

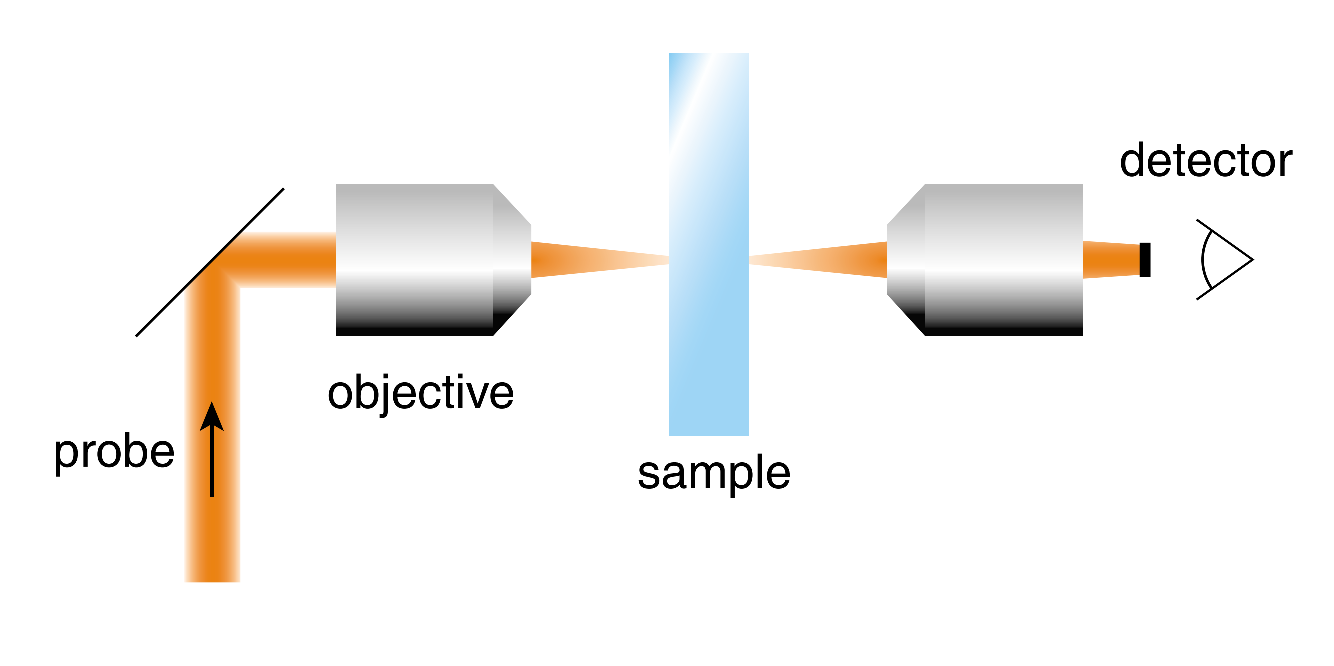
- Processing with fs pulses
- **Role of focusing**
- Low-energy processing

Role of focusing

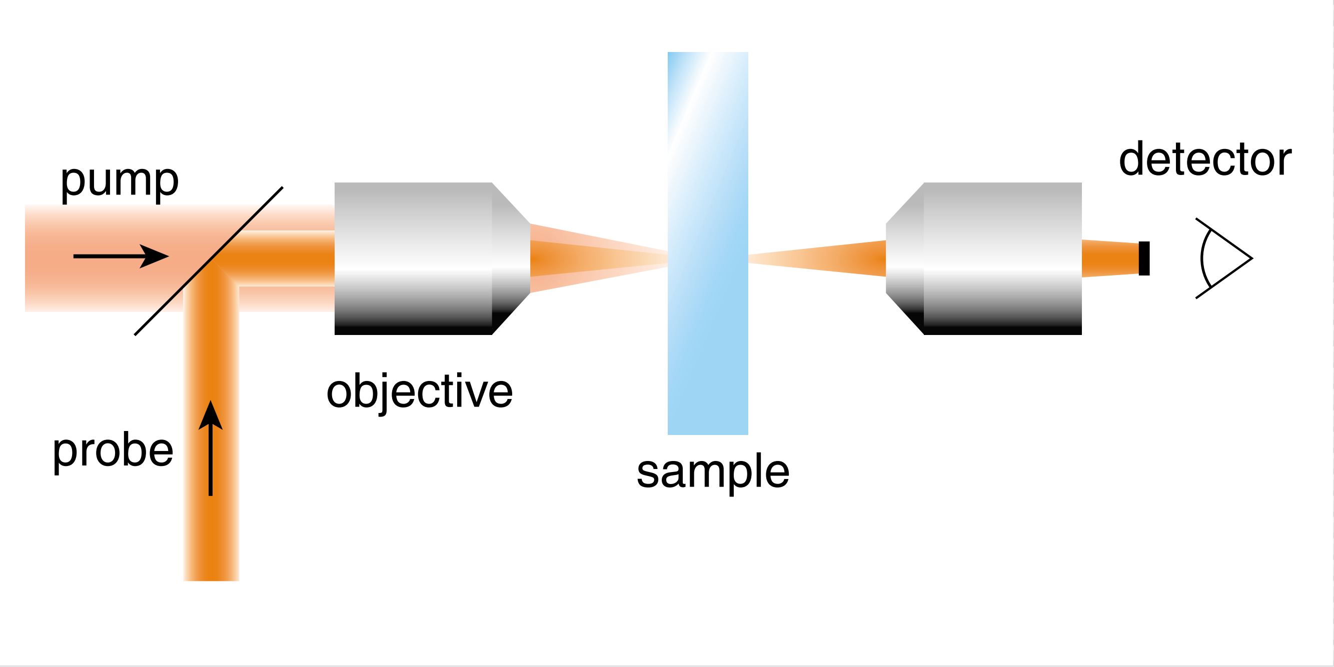
Dark-field scattering



block probe beam…

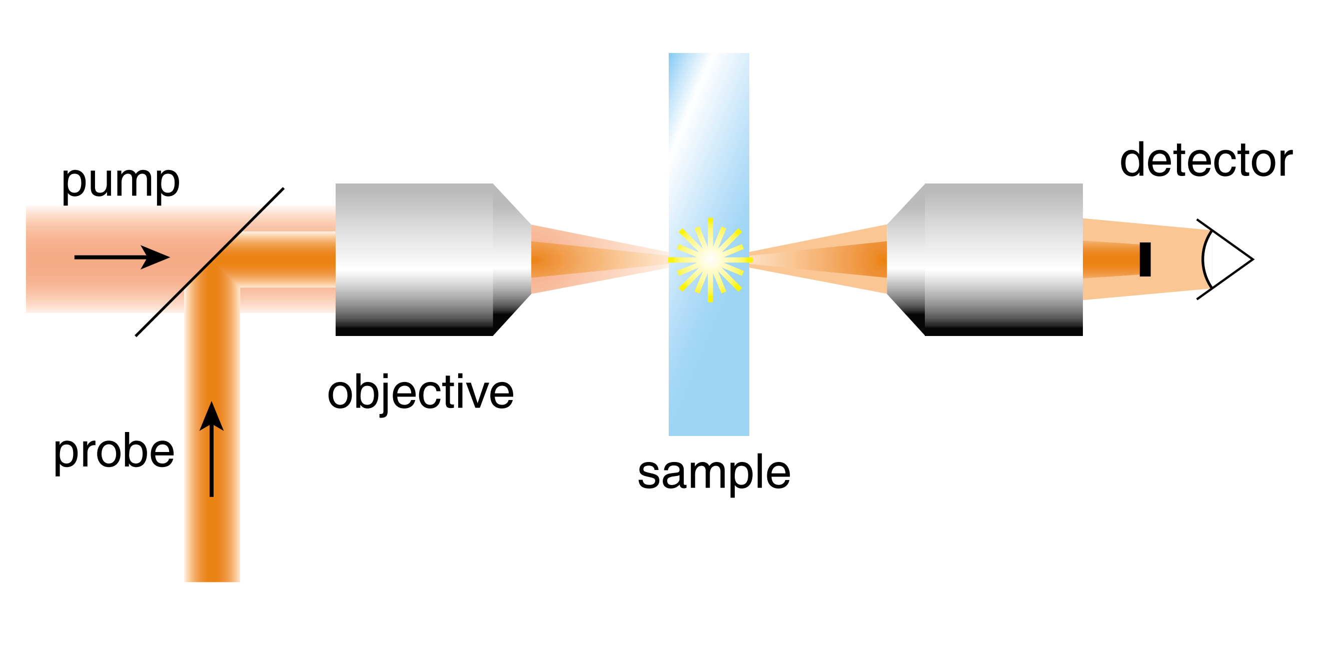


… bring in pump beam…

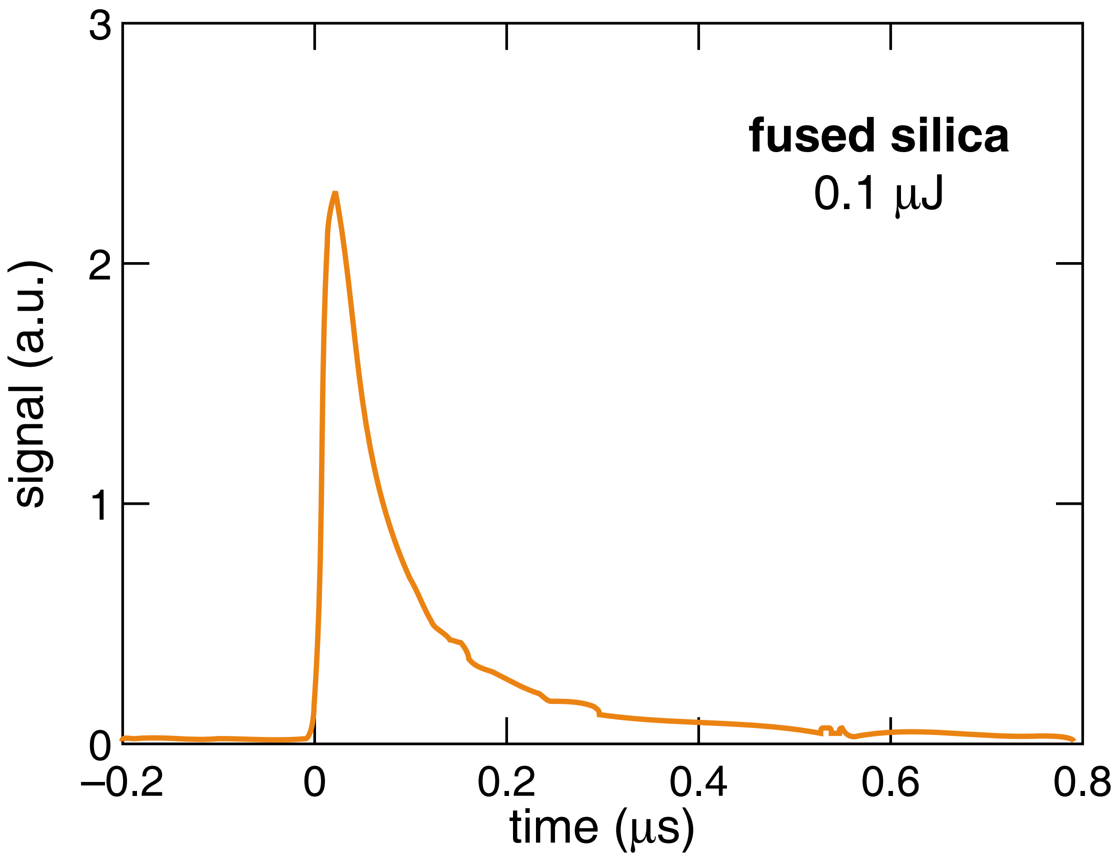


Role of focusing

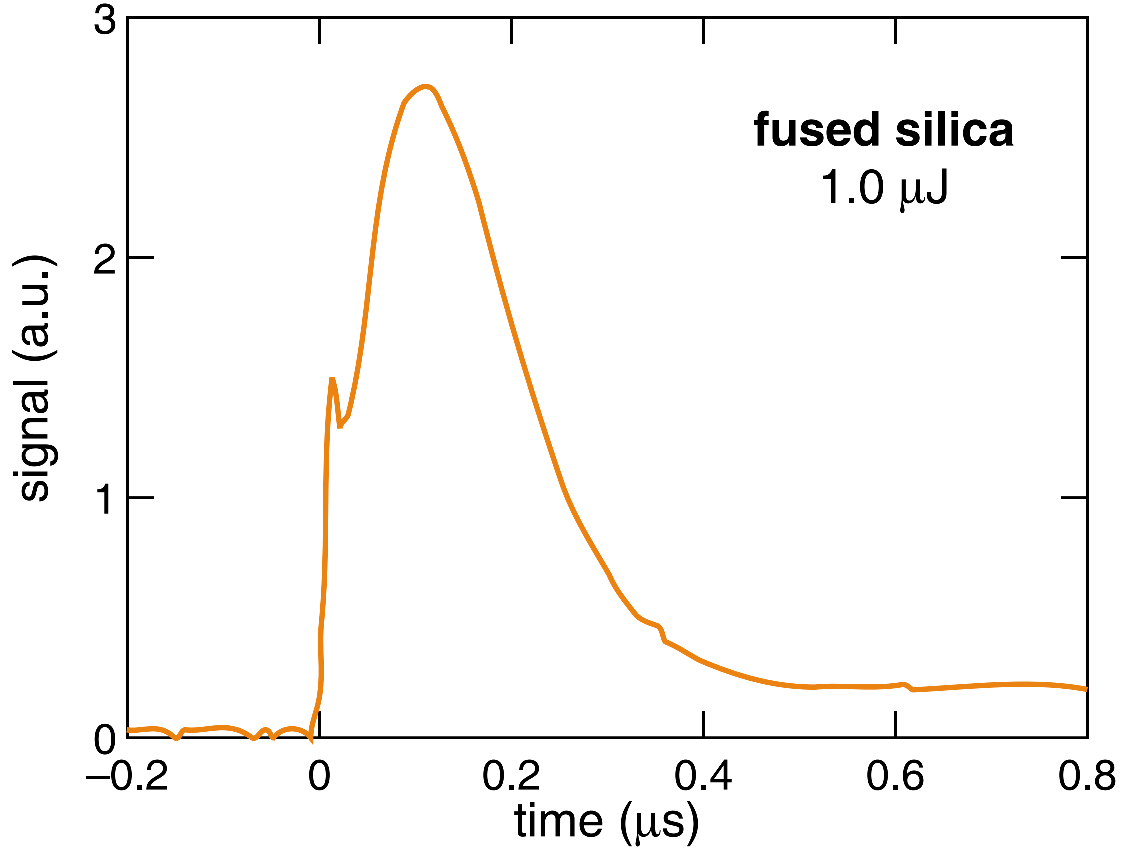
… damage scatters probe beam



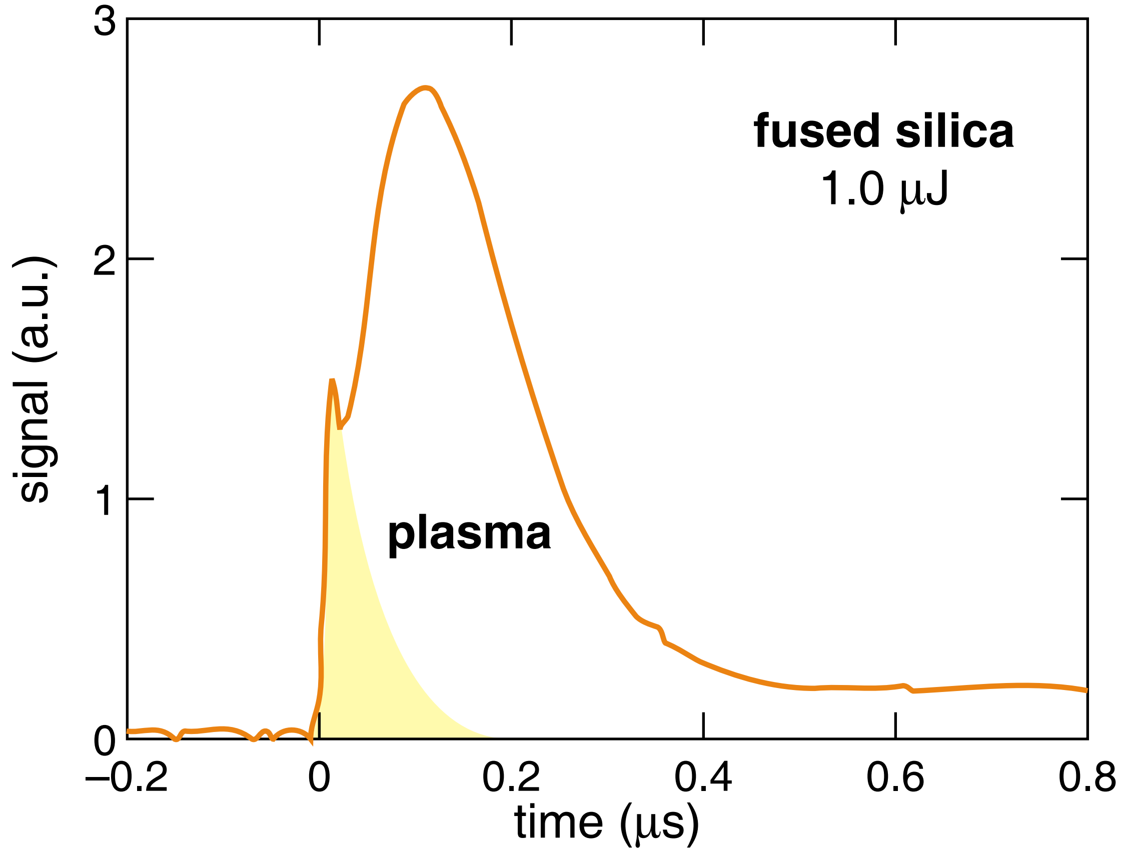
Role of focusing



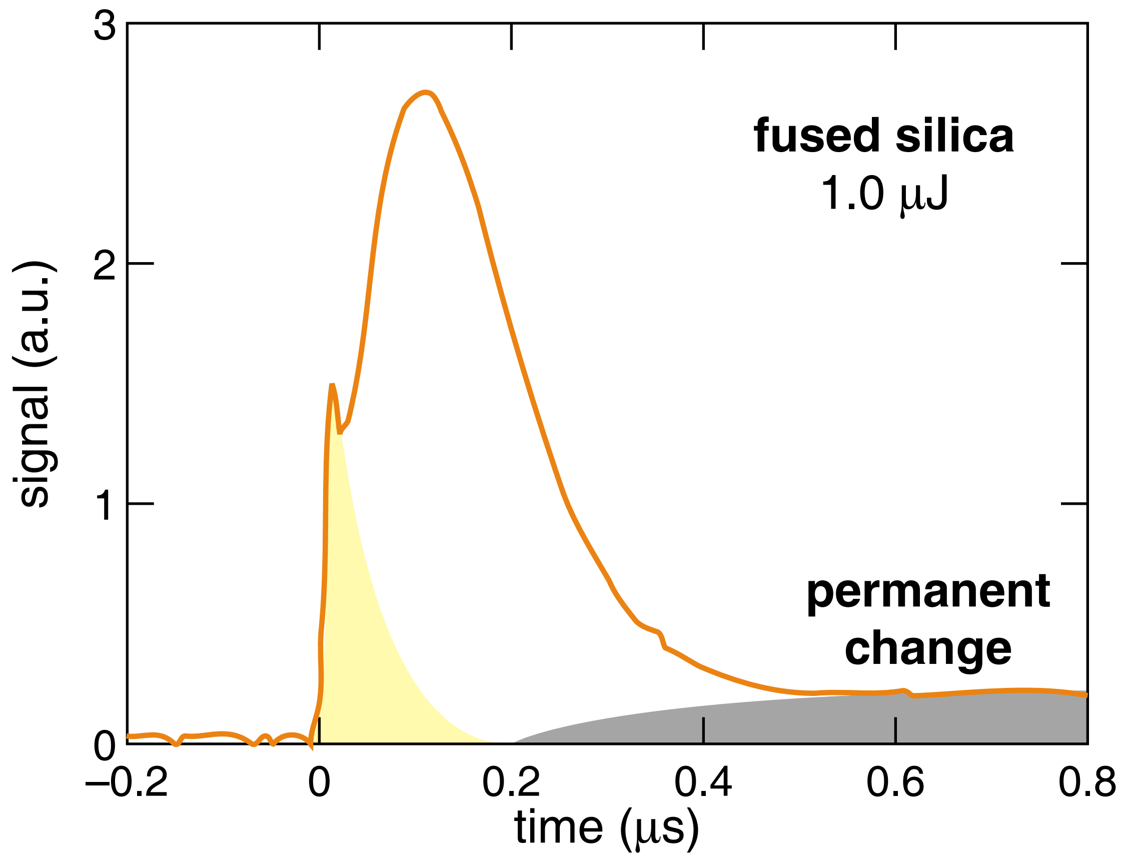
Role of focusing



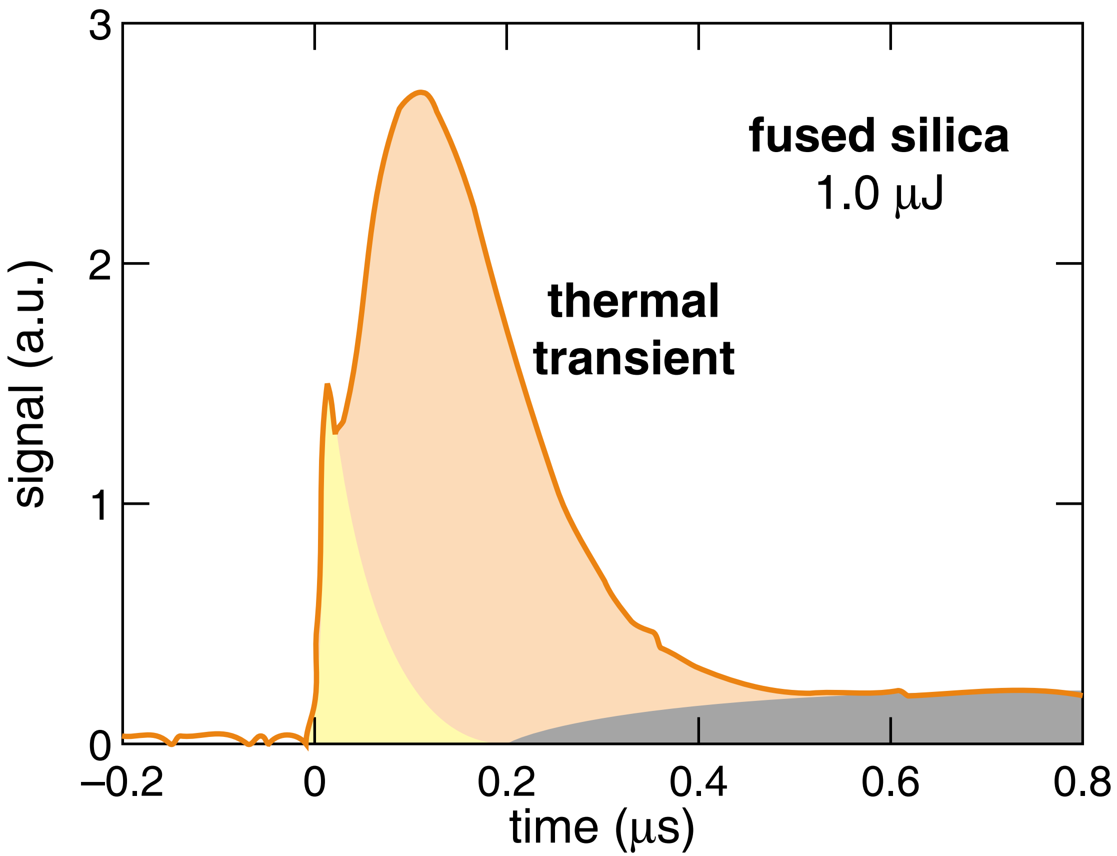
Role of focusing



Role of focusing

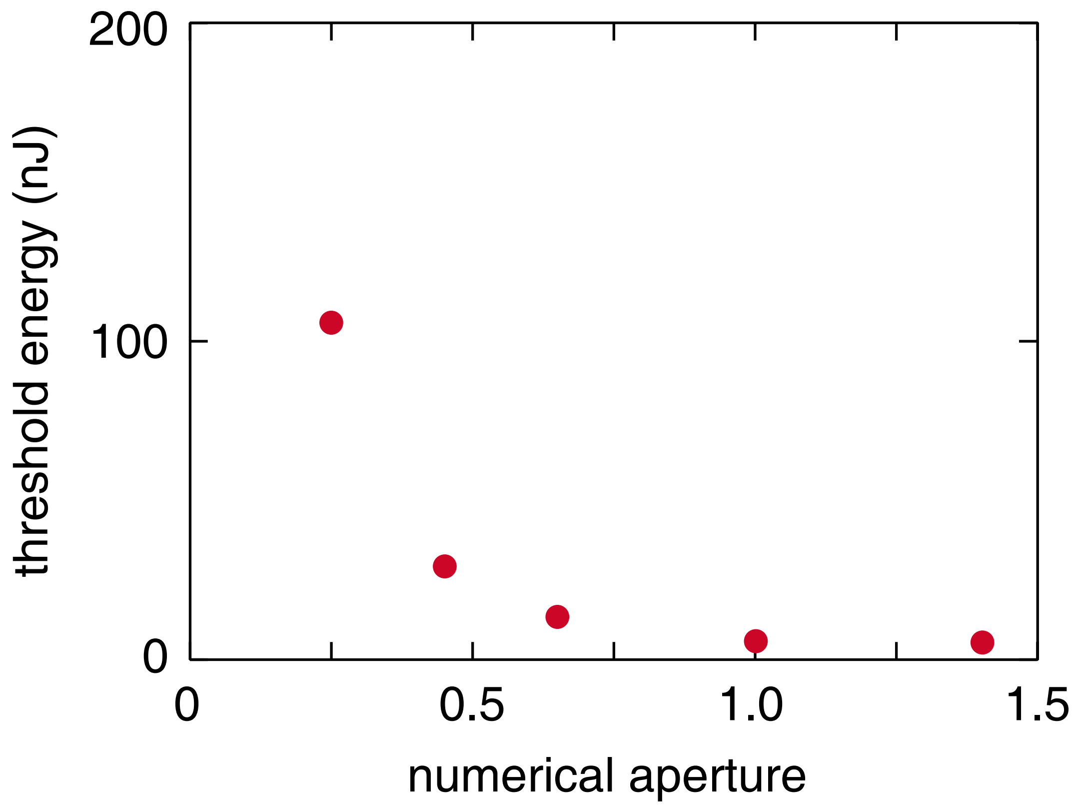


Role of focusing

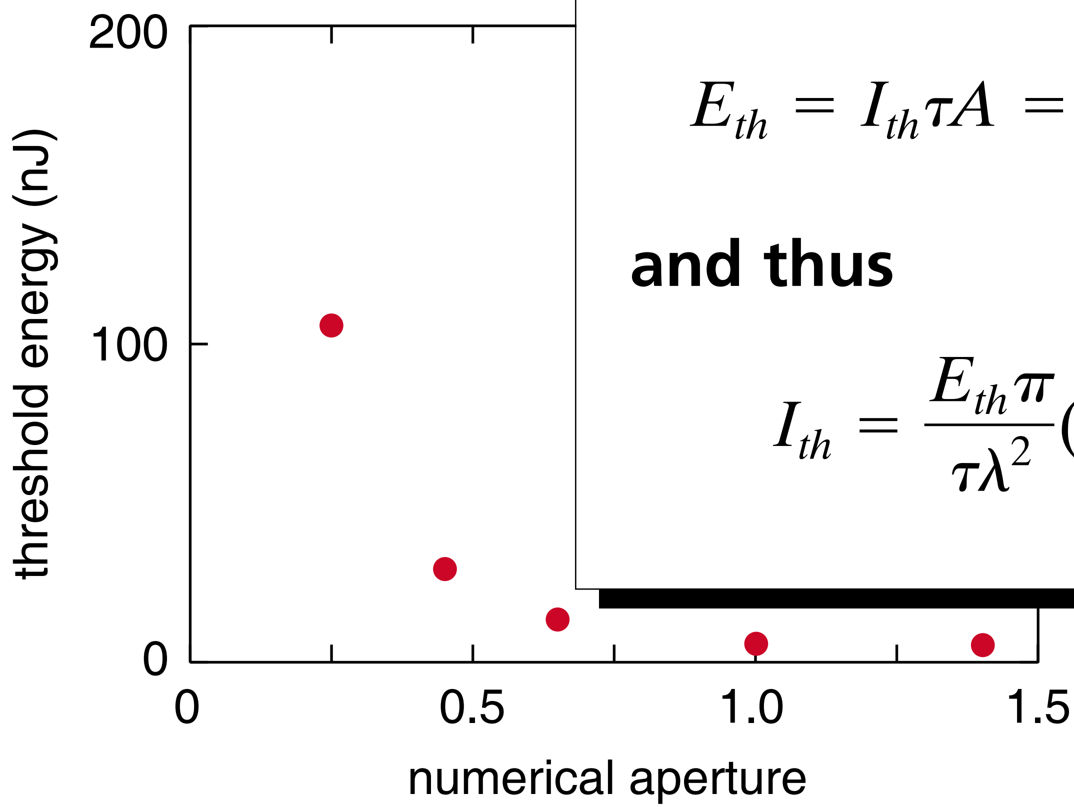


Role of focusing

vary numerical aperture in Corning 0211



Role of focusing



spot size determined by numerical aperture:

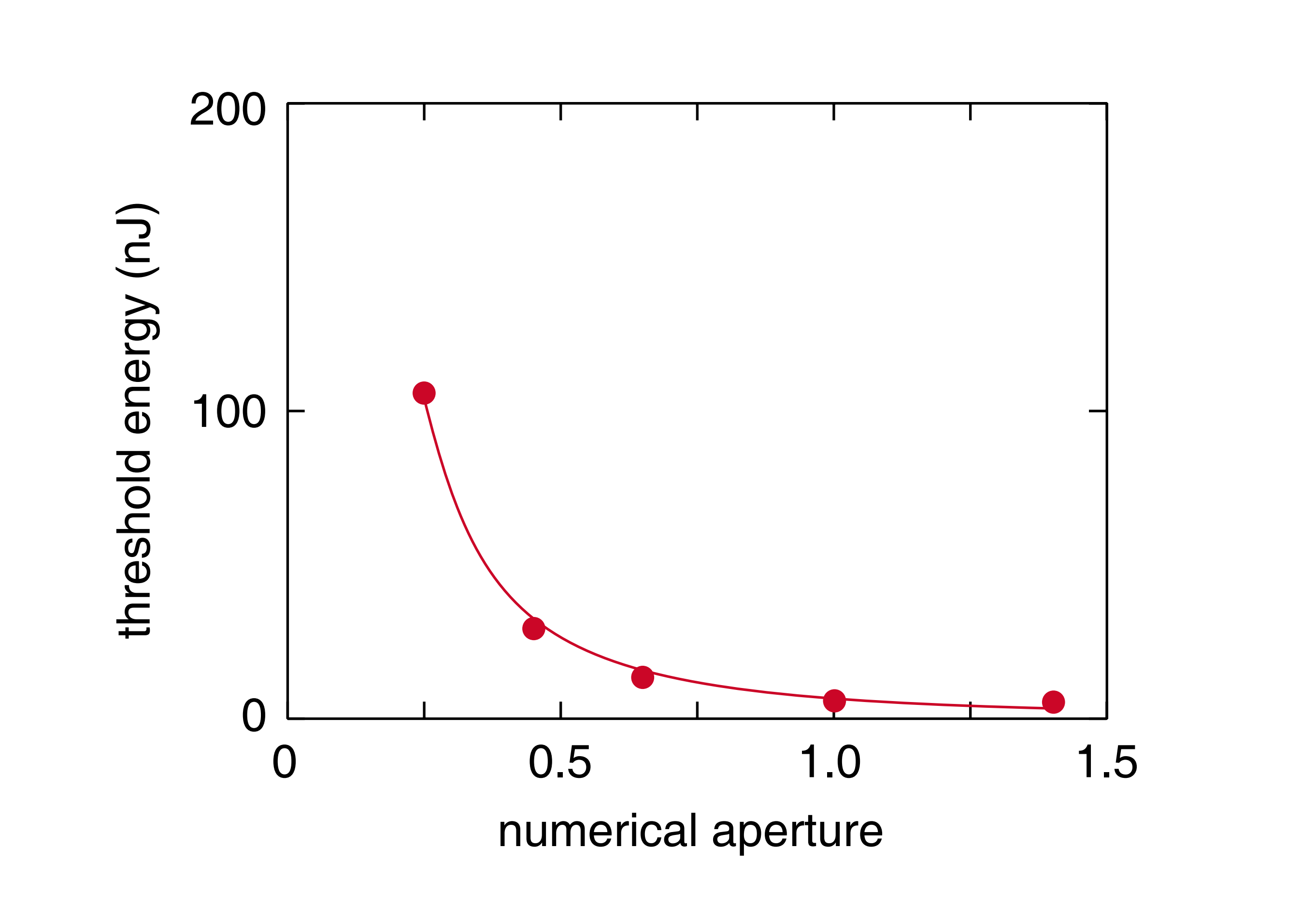
$$E_{th} = I_{th}\tau A = \frac{I_{th}\tau\lambda^2}{\pi(\mathrm{NA})^2}$$

and thus

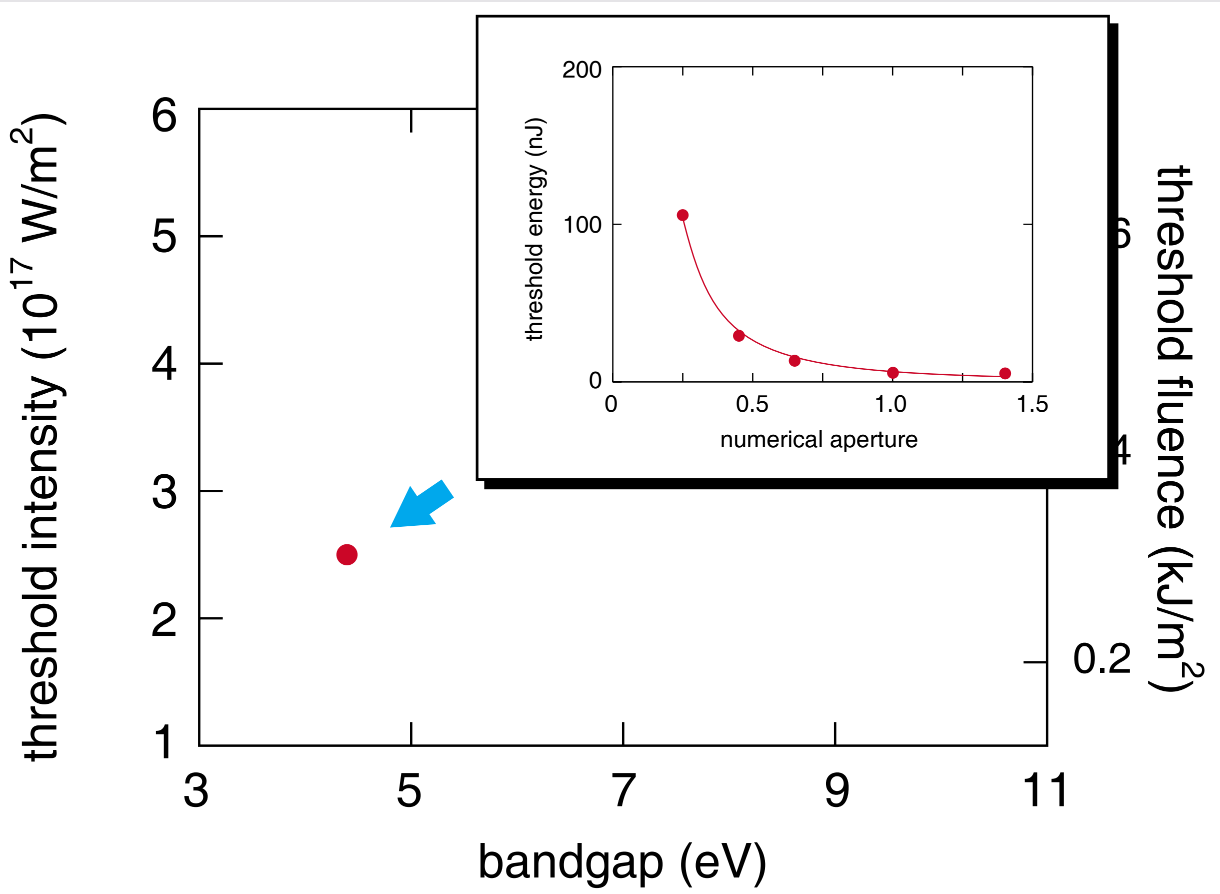
$$I_{th} = \frac{E_{th}\pi}{\tau\lambda^2}(\mathrm{NA})^2$$

Role of focusing

fit gives threshold intensity: I_{th} = 2.5 x 10^{17} W/m^2

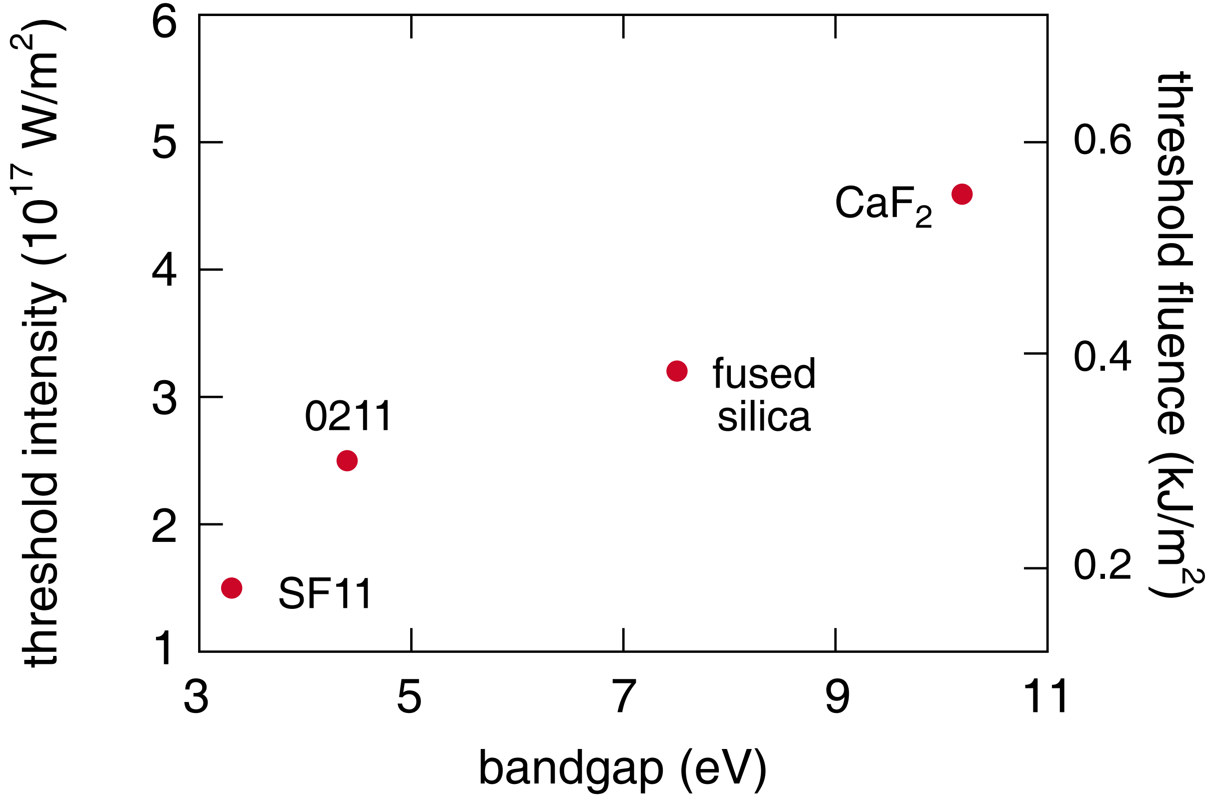


Role of focusing



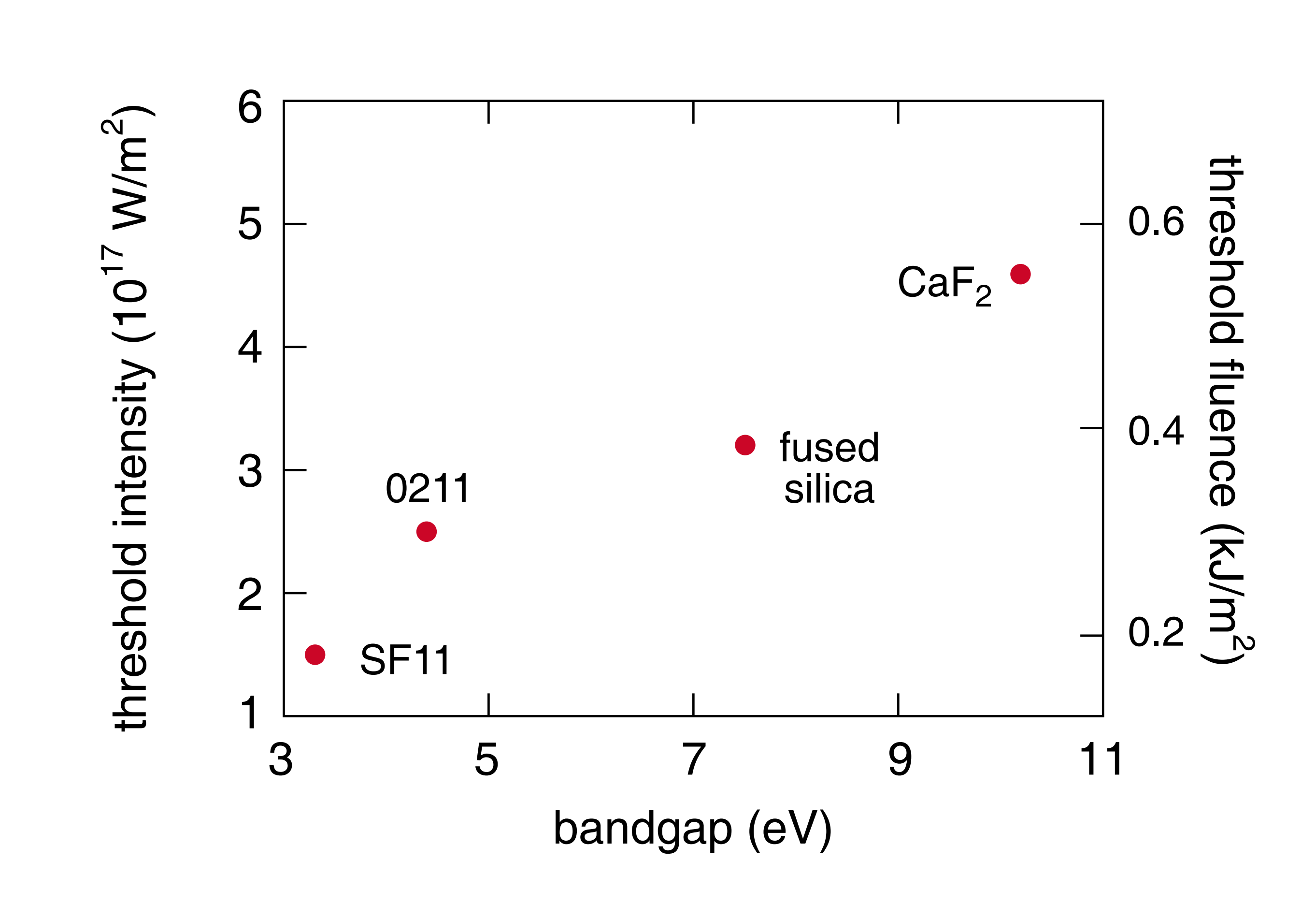
Role of focusing

vary material...



Role of focusing

threshold varies with bandgap



Role of focusing

Points to keep in mind:

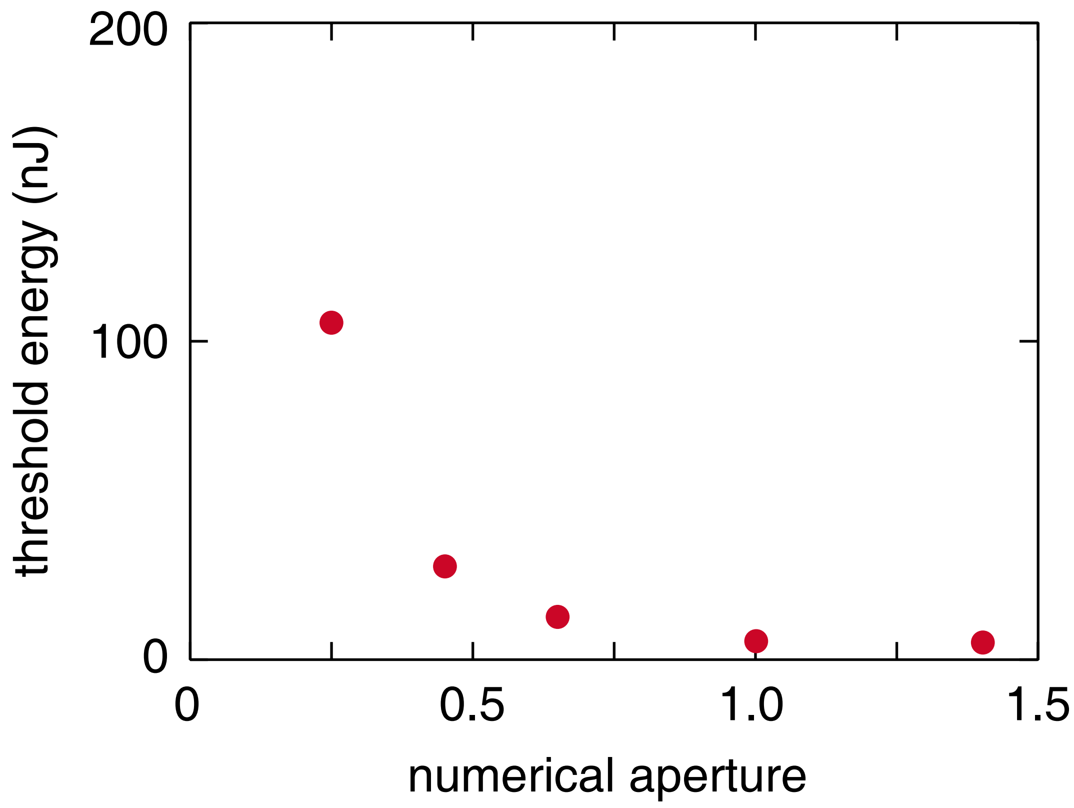
- **threshold critically dependent on NA**
- **surprisingly little material dependence**
- **avalanche ionization important**

Outline

- Processing with fs pulses
- Role of focusing
- **Low-energy processing**

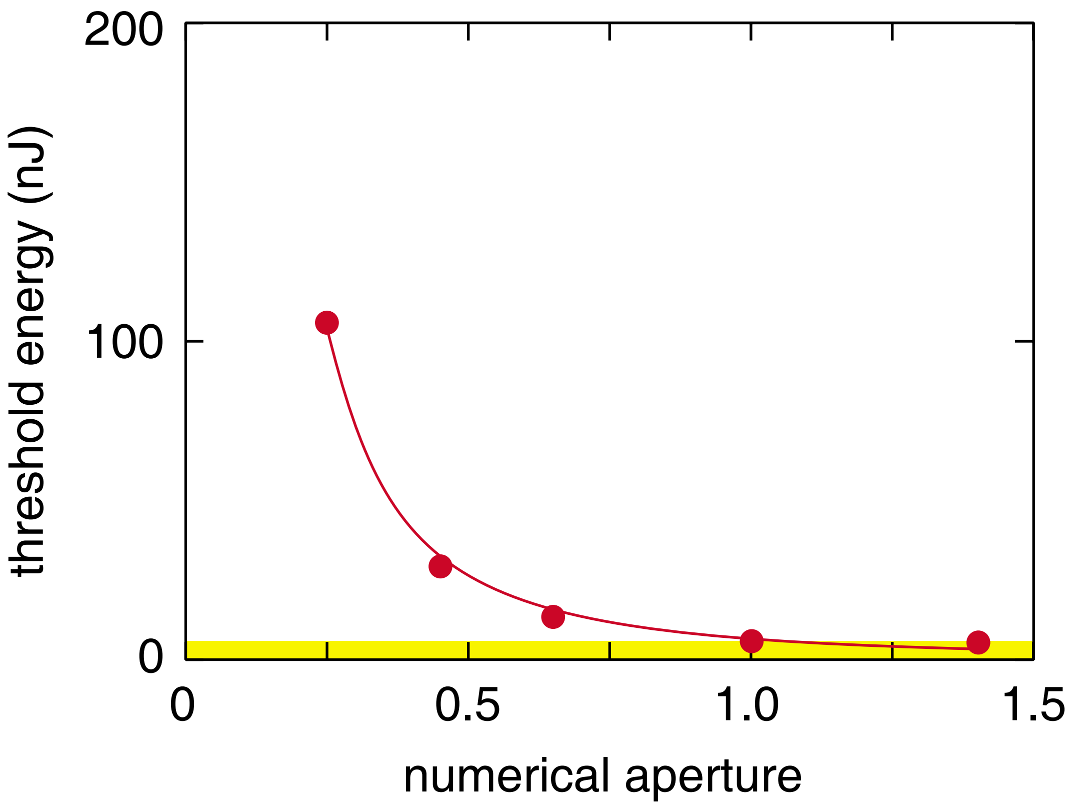
Low-energy processing

threshold decreases with increasing numerical aperture



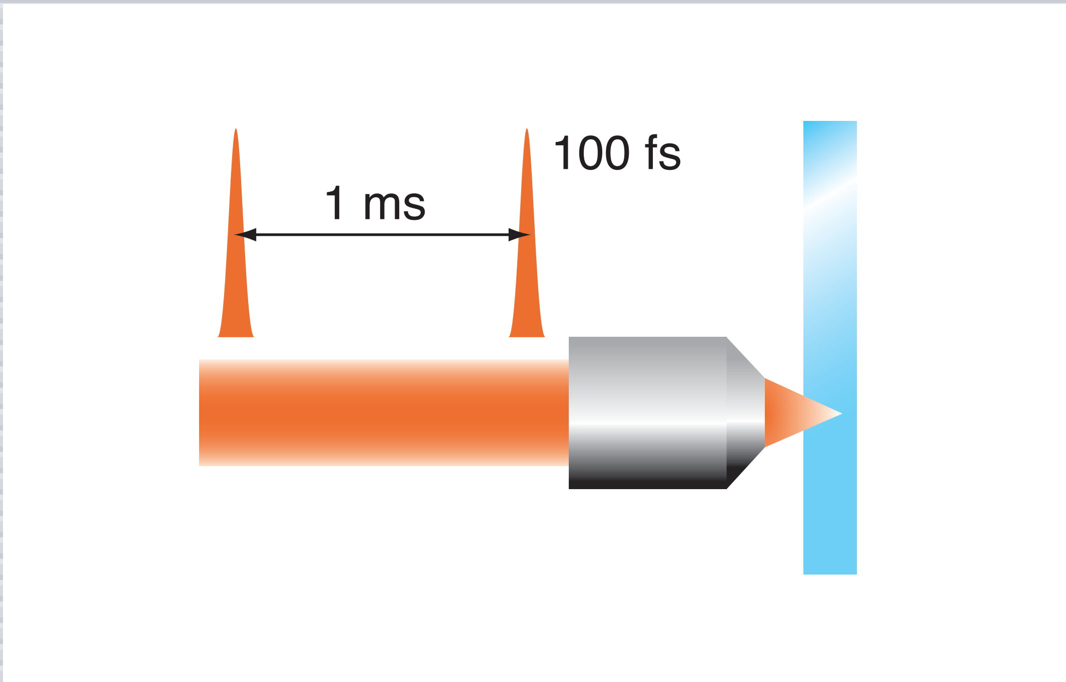
Low-energy processing

less than 10 nJ at high numerical aperture!



Low-energy processing

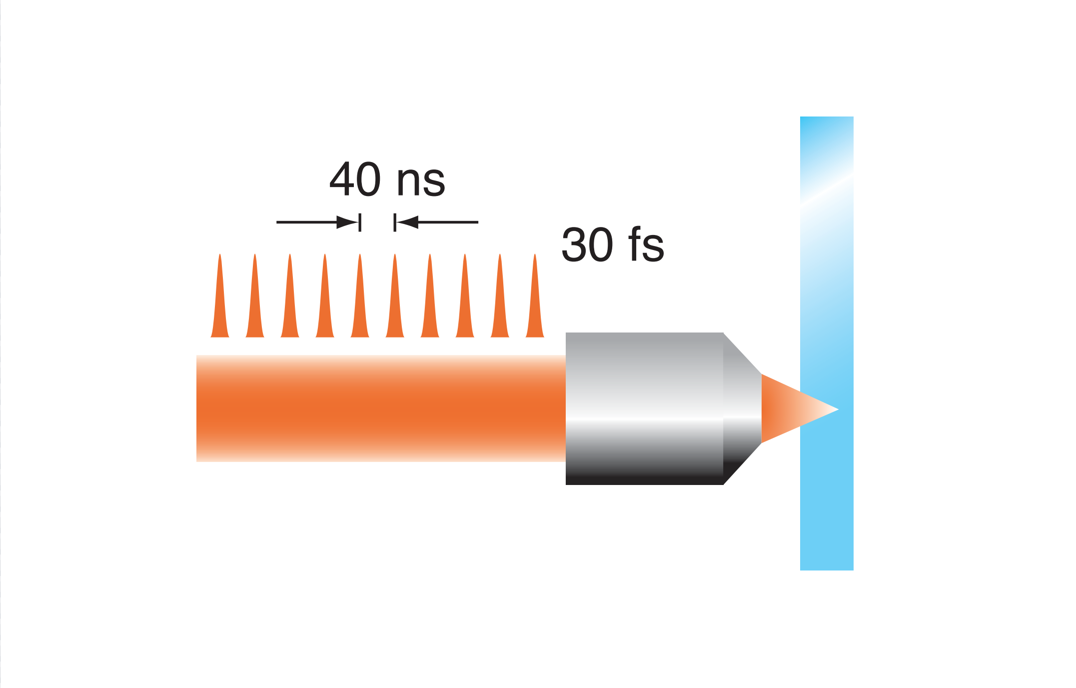
amplified laser: 1 kHz, 1 mJ



heat diffusion time: $\tau_{diff} \approx 1\ \mu s$

Low-energy processing

long cavity oscillator: 25 MHz, 25 nJ



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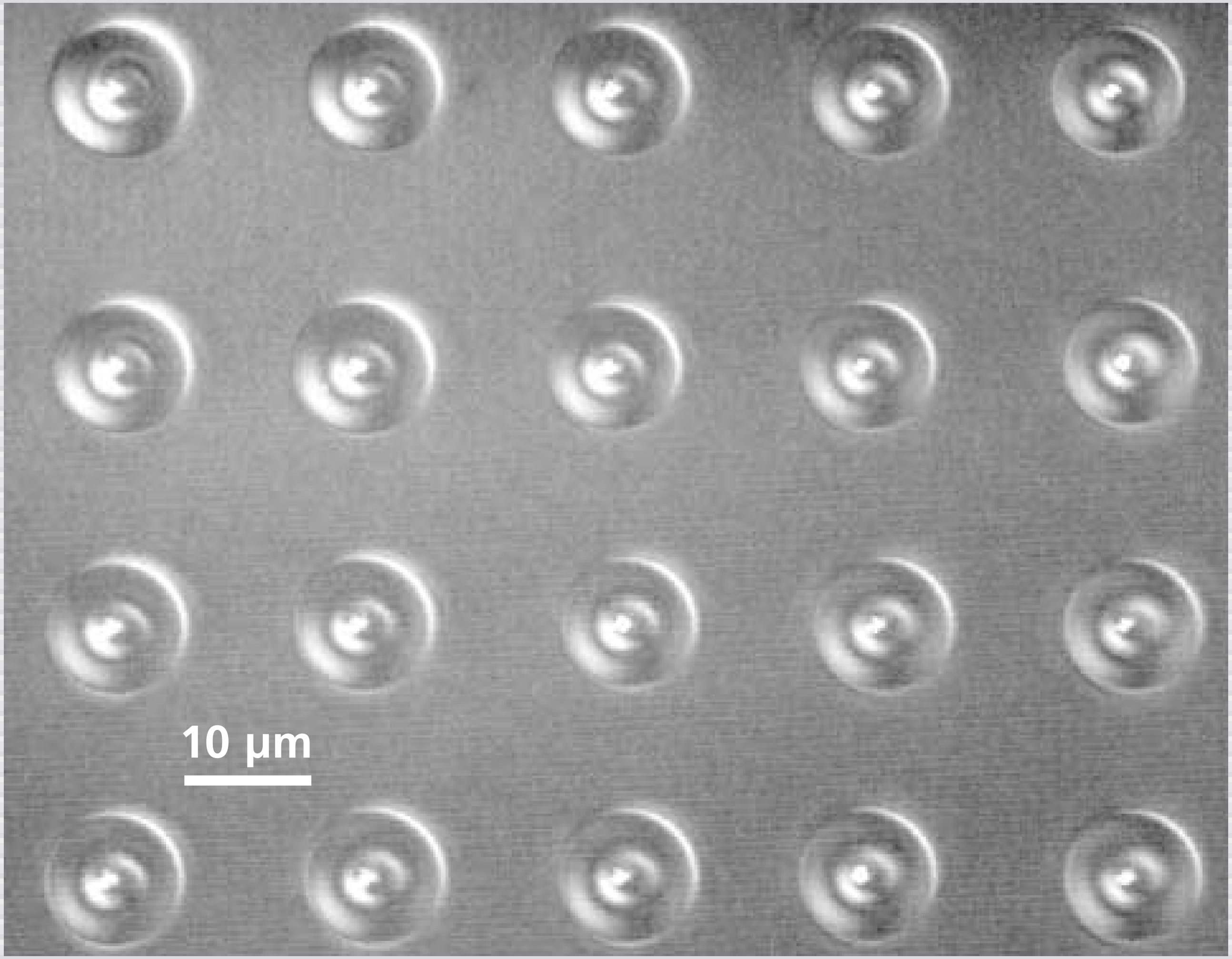
Low-energy processing

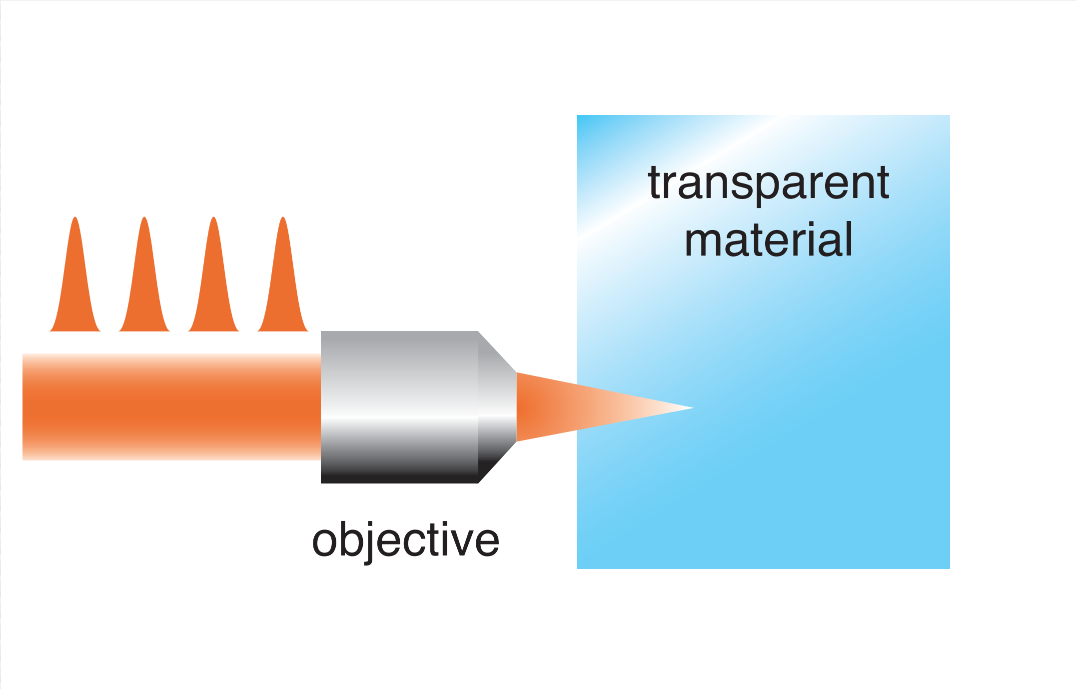


Low-energy processing

high repetition-rate micromachining:

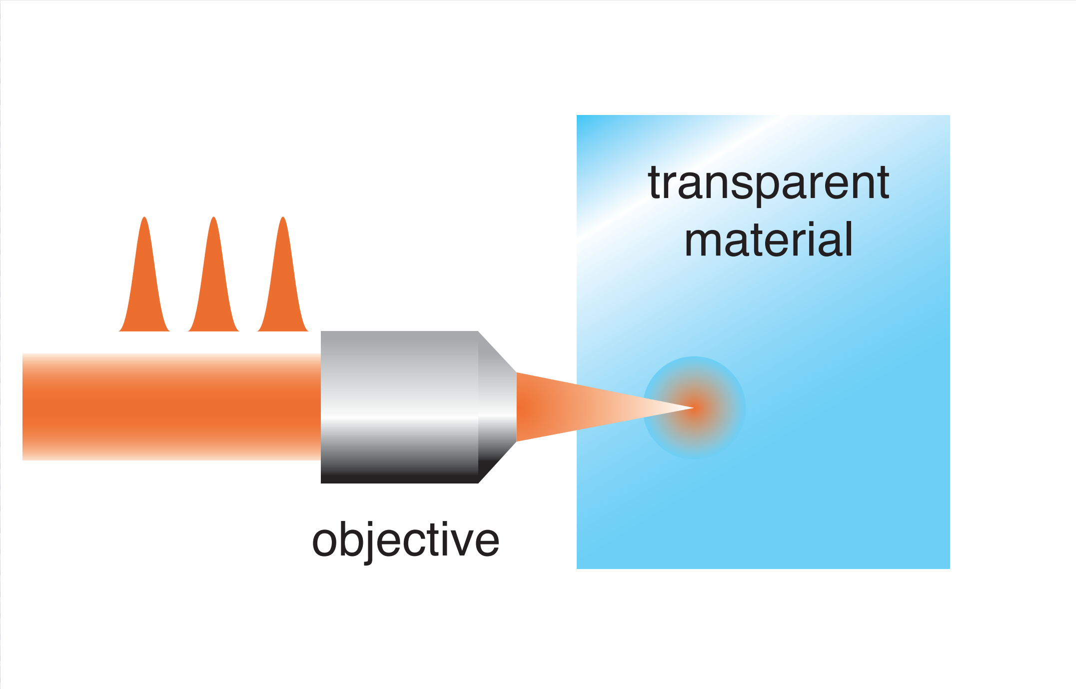
- **structural changes exceed focal volume**
- **spherical structures**
- **density change caused by melting**

Low-energy processing



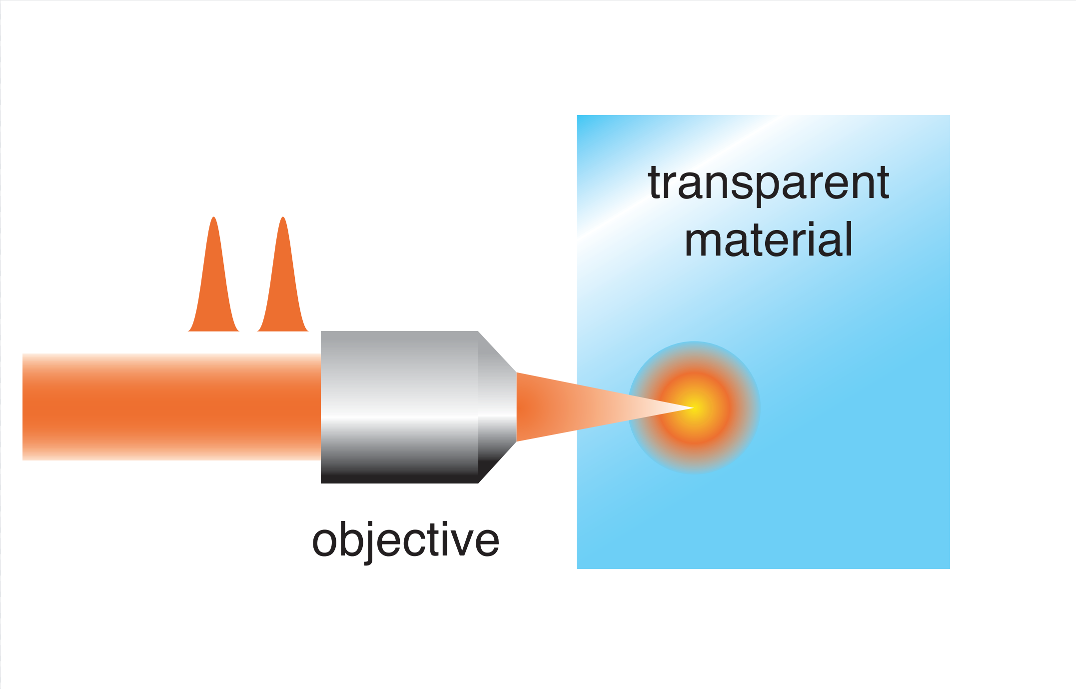
cumulative energy deposition

Low-energy processing



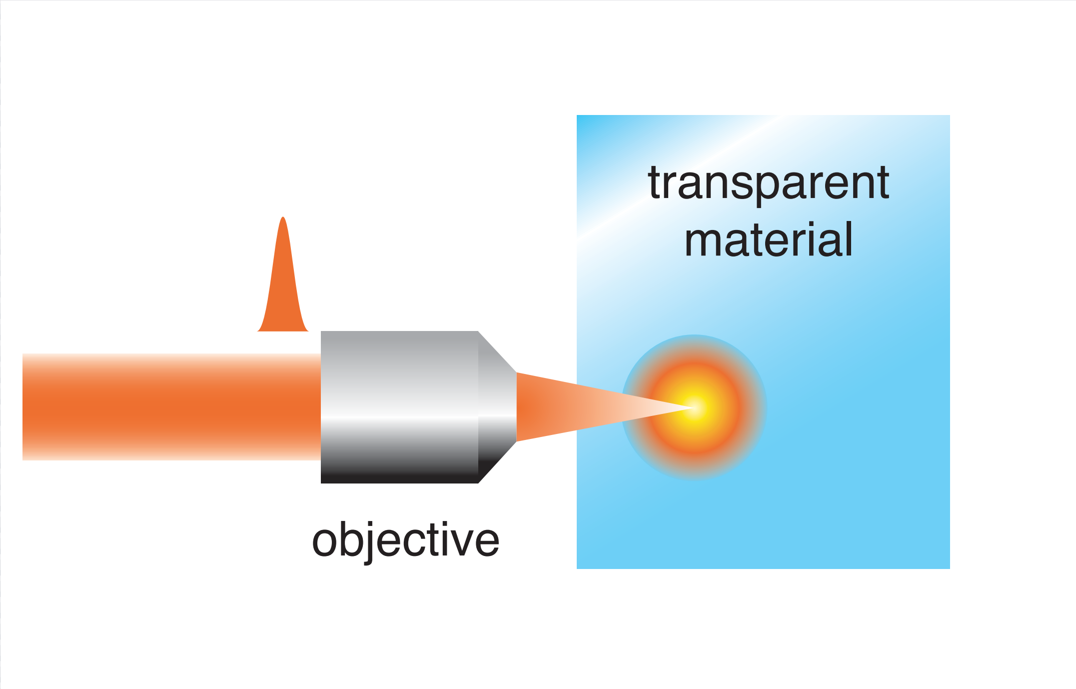
cumulative energy deposition

Low-energy processing



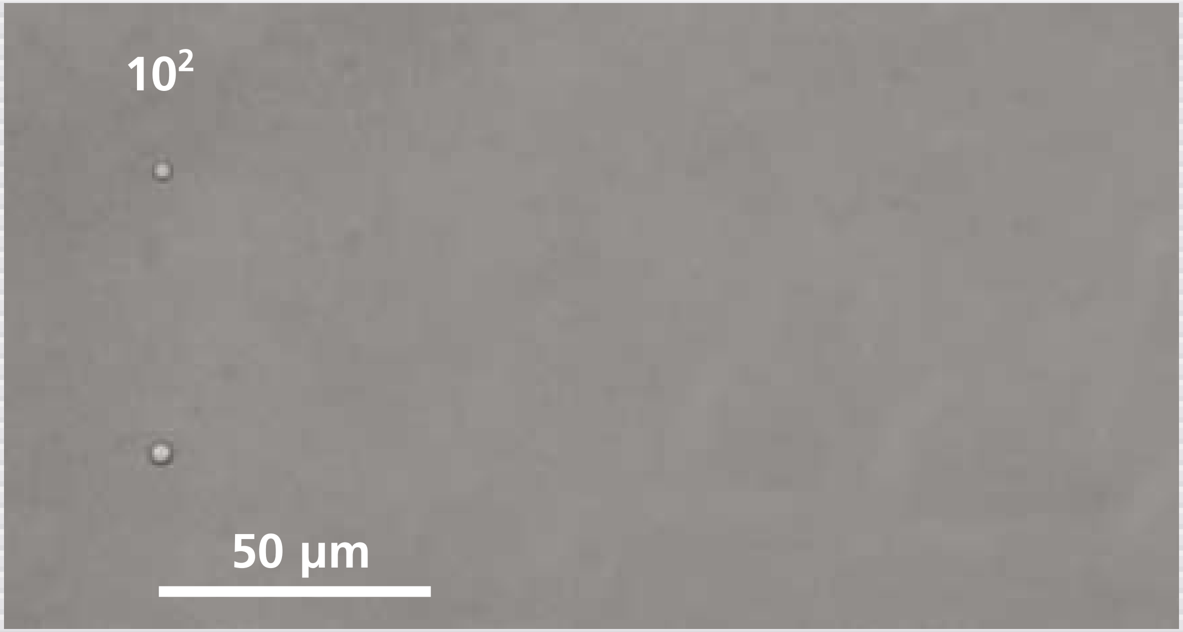
cumulative energy deposition

Low-energy processing

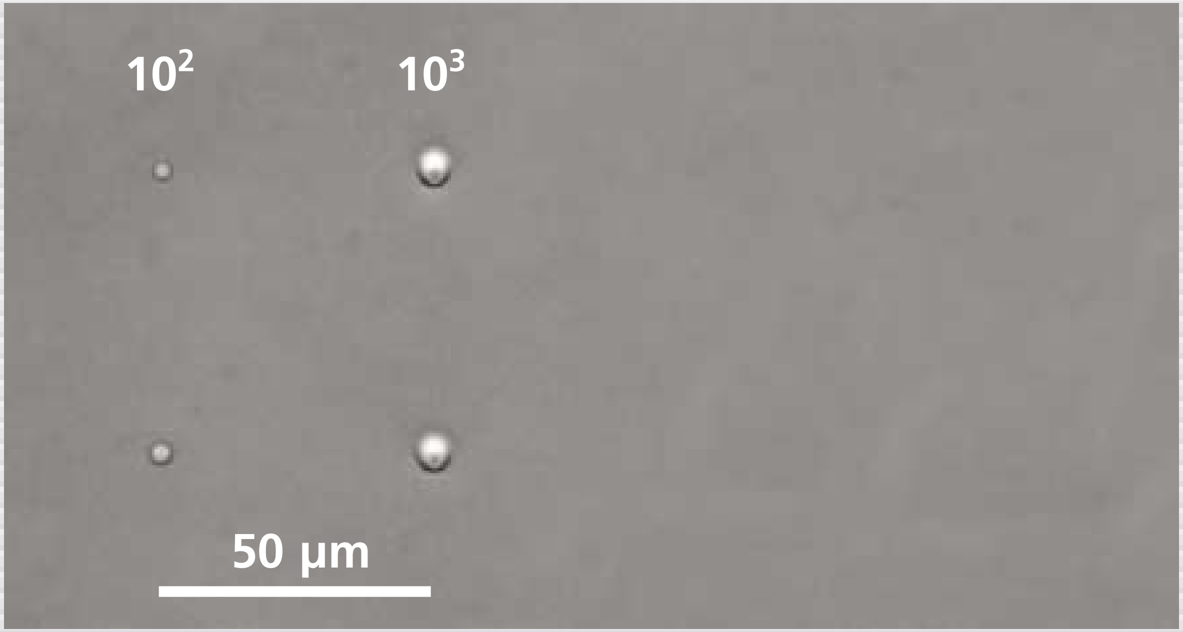


cumulative energy deposition

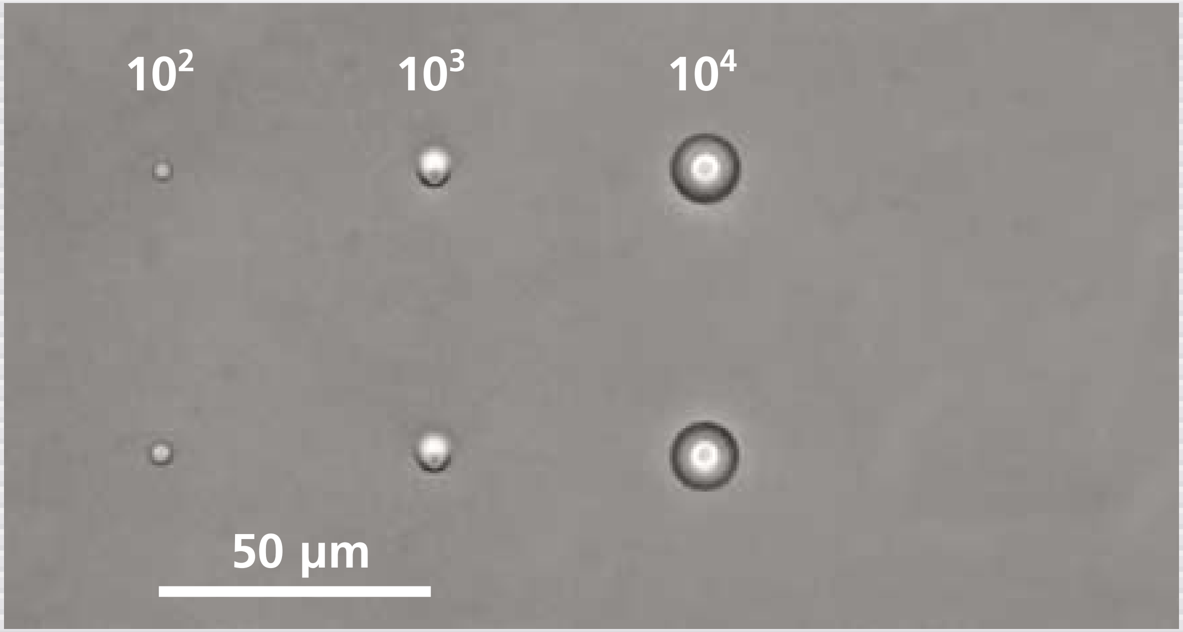
Low-energy processing



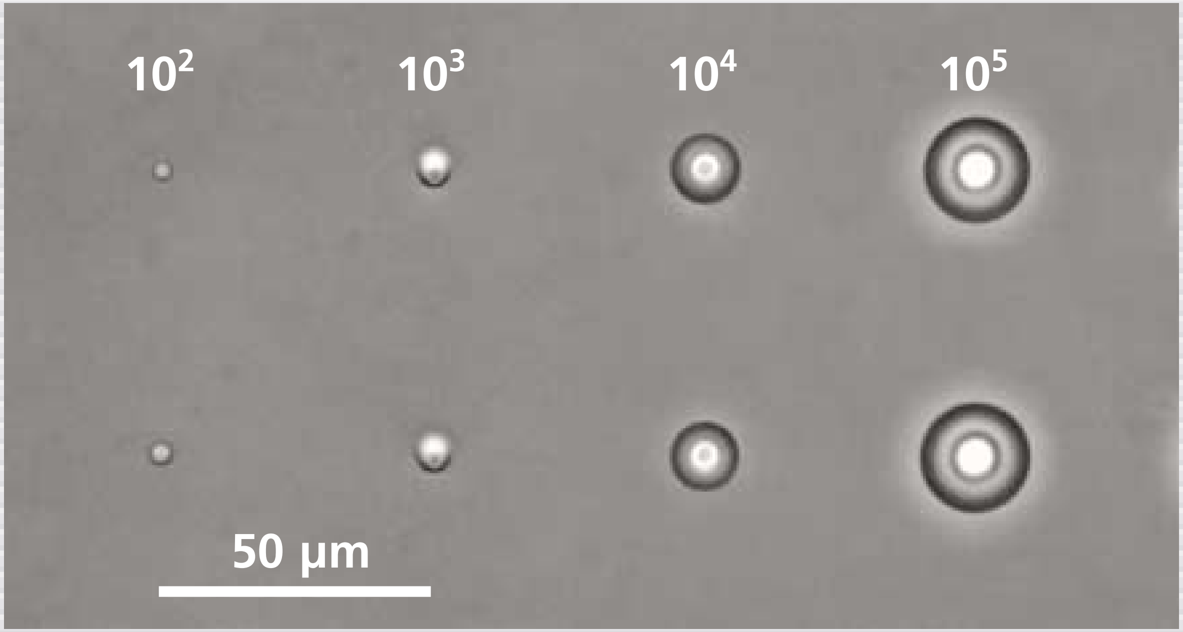
Low-energy processing



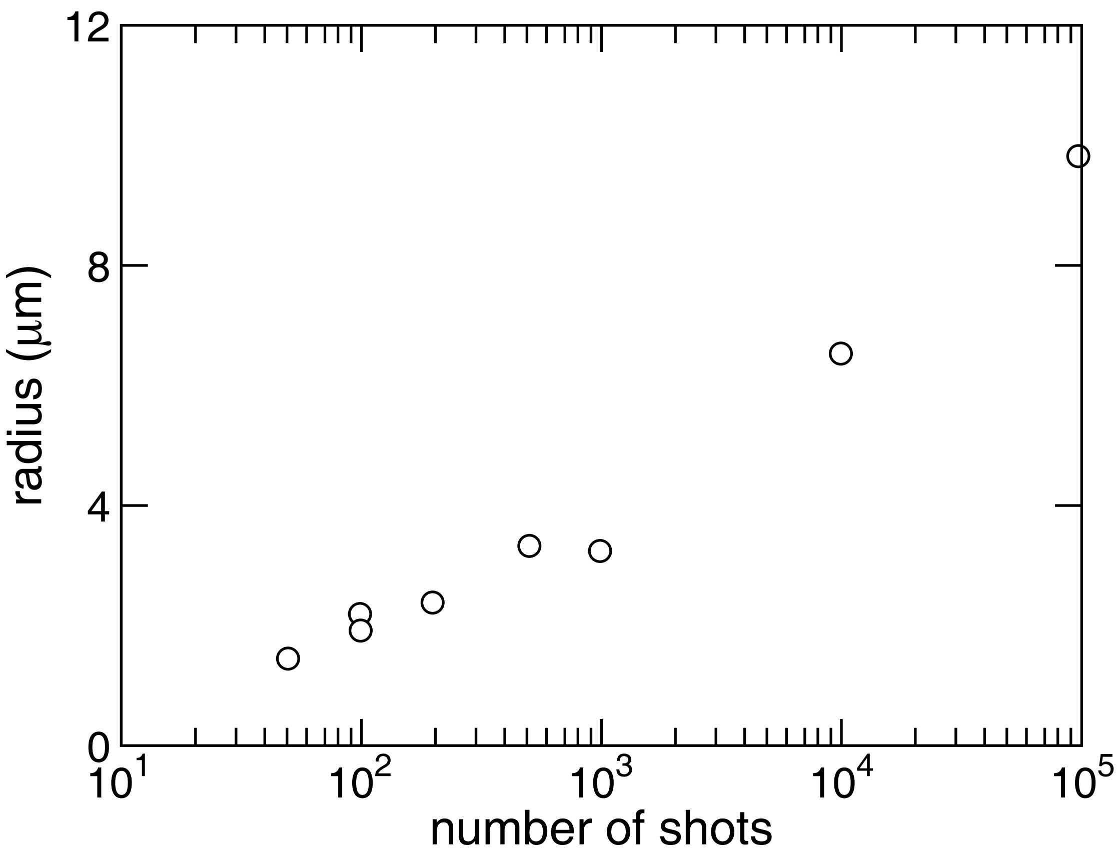
Low-energy processing



Low-energy processing

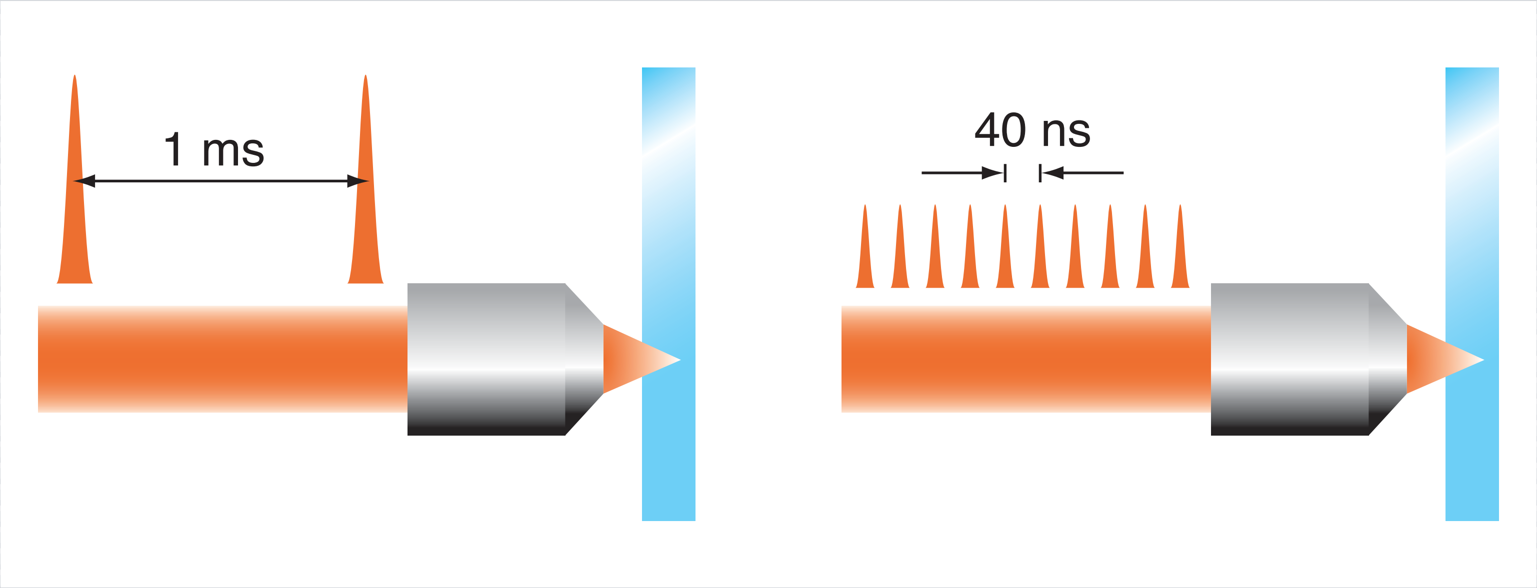


Low-energy processing



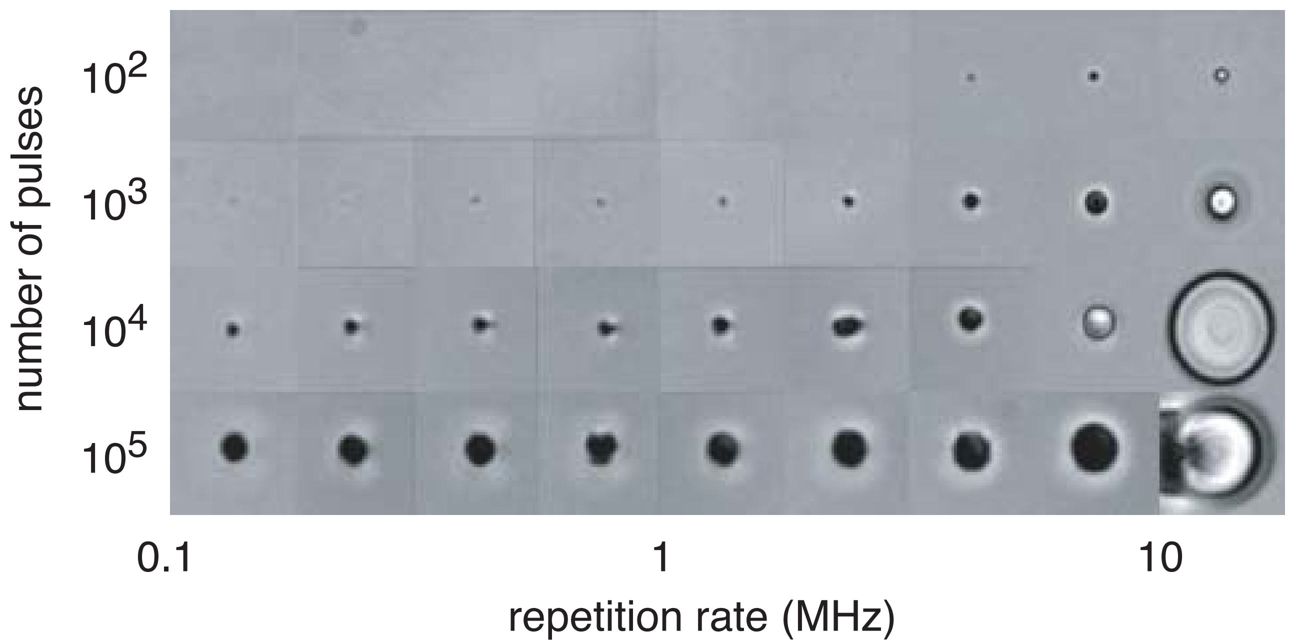
Low-energy processing

amplified laser **oscillator**



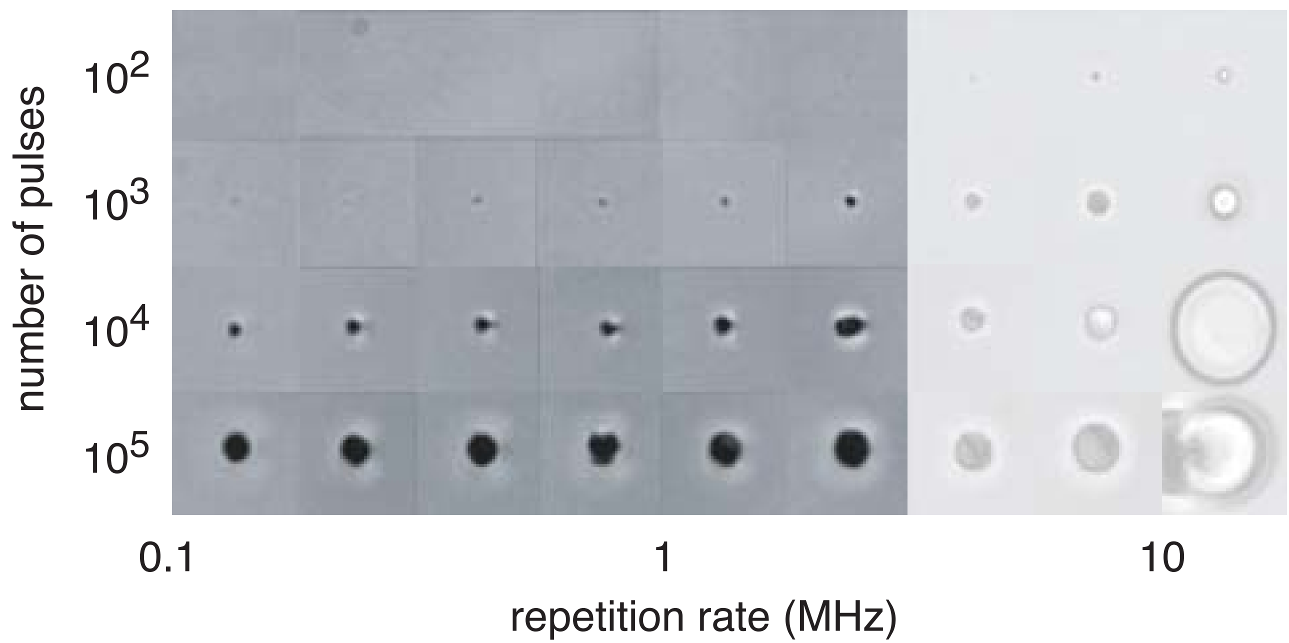
repetitive **cumulative**

repetition-rate dependence



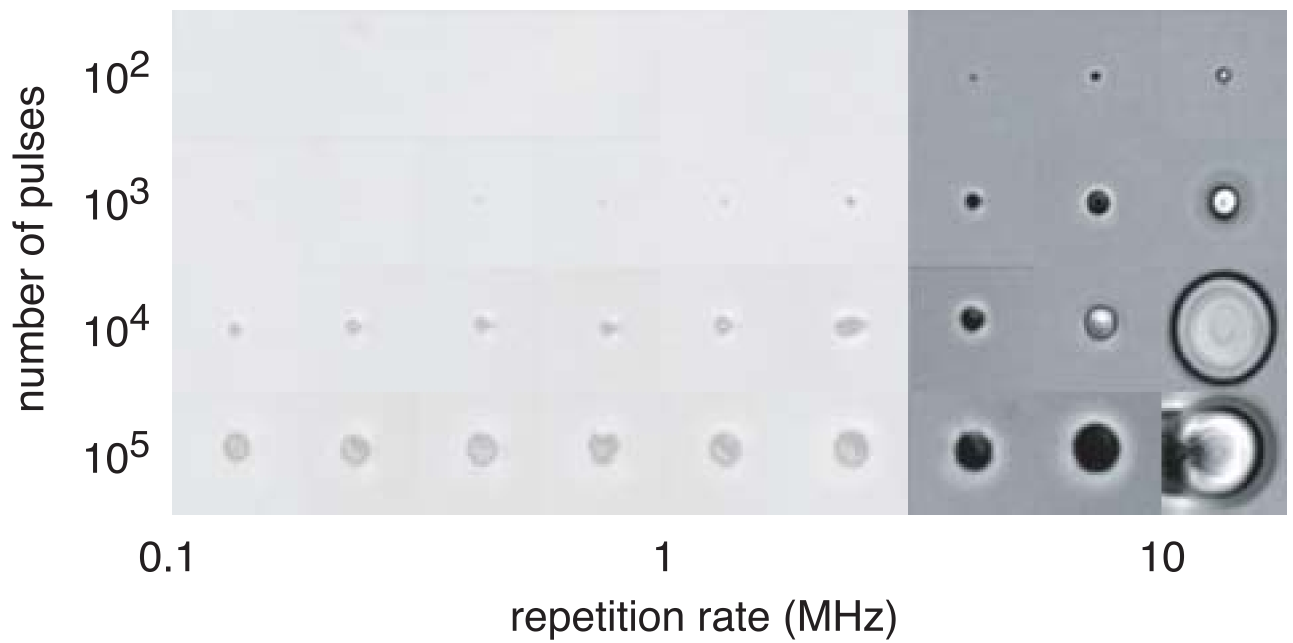
As_2S_3, 100 fs, 7 nJ

repetition-rate dependence



As_2S_3, 100 fs, 7 nJ

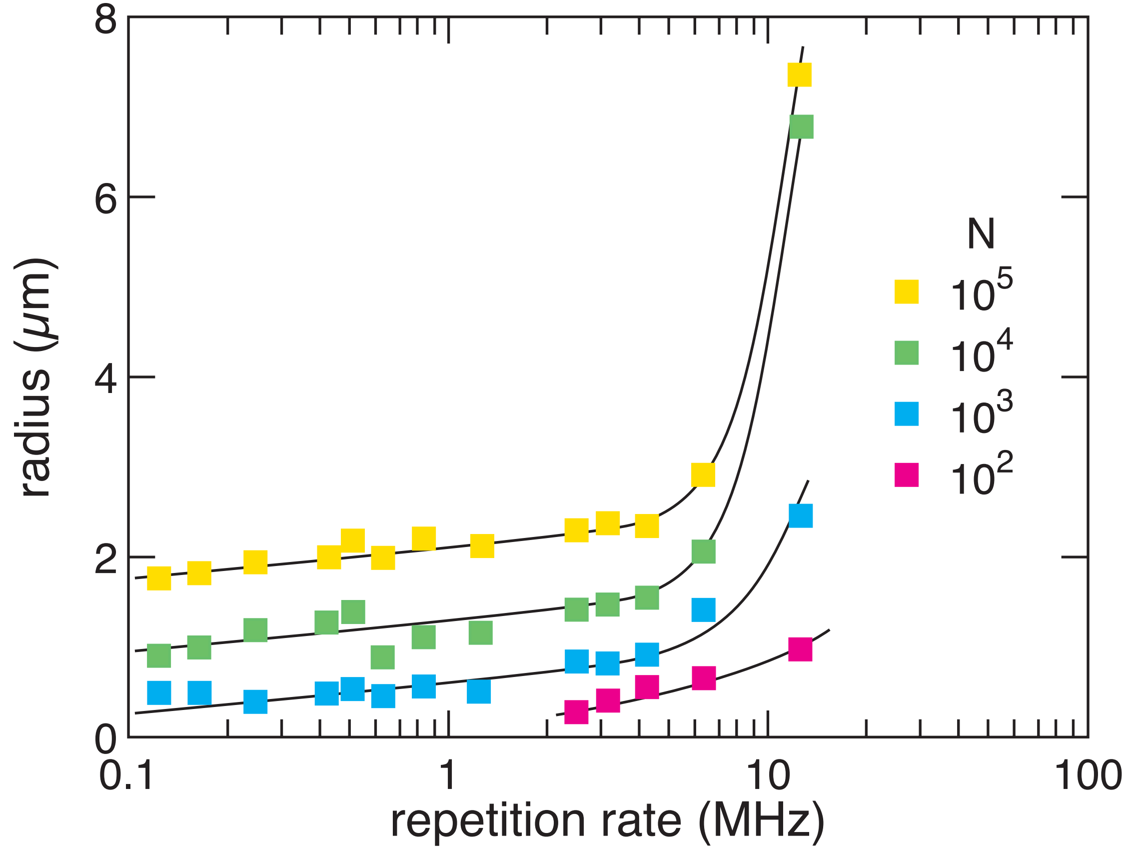
repetition-rate dependence



As_2S_3, 100 fs, 7 nJ

Low-energy processing

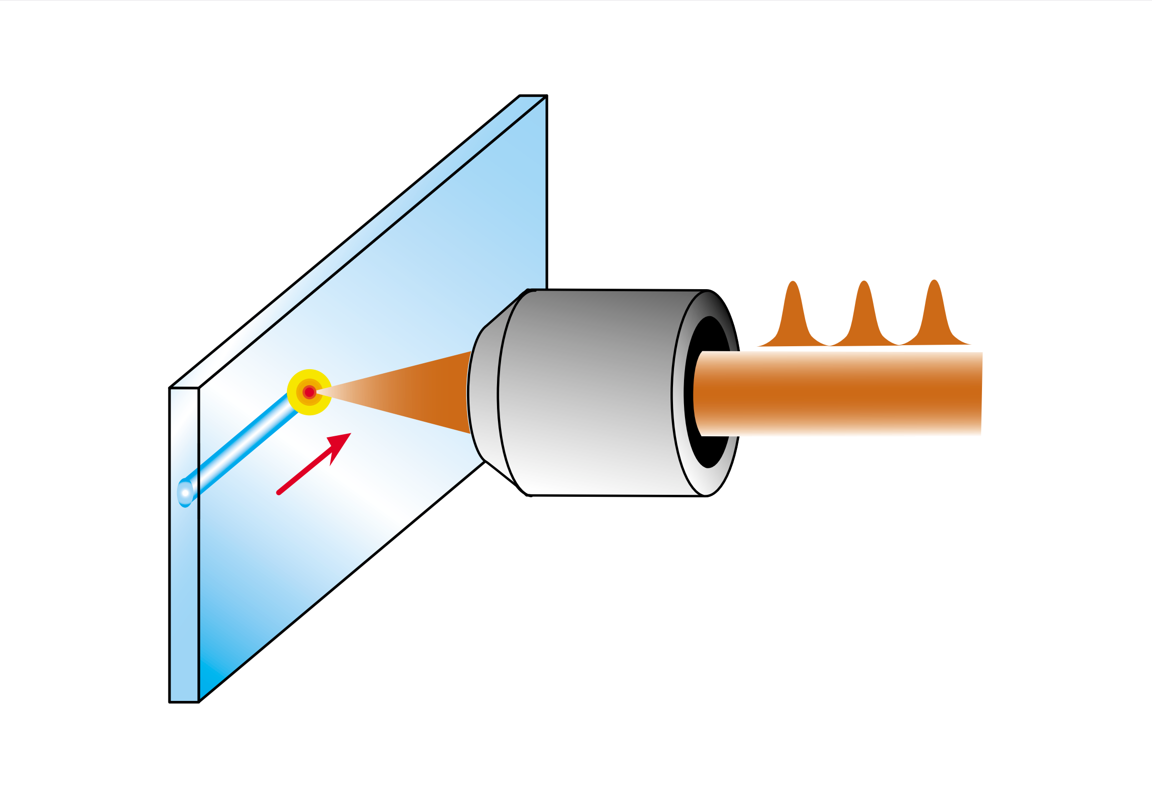
repetition-rate dependence



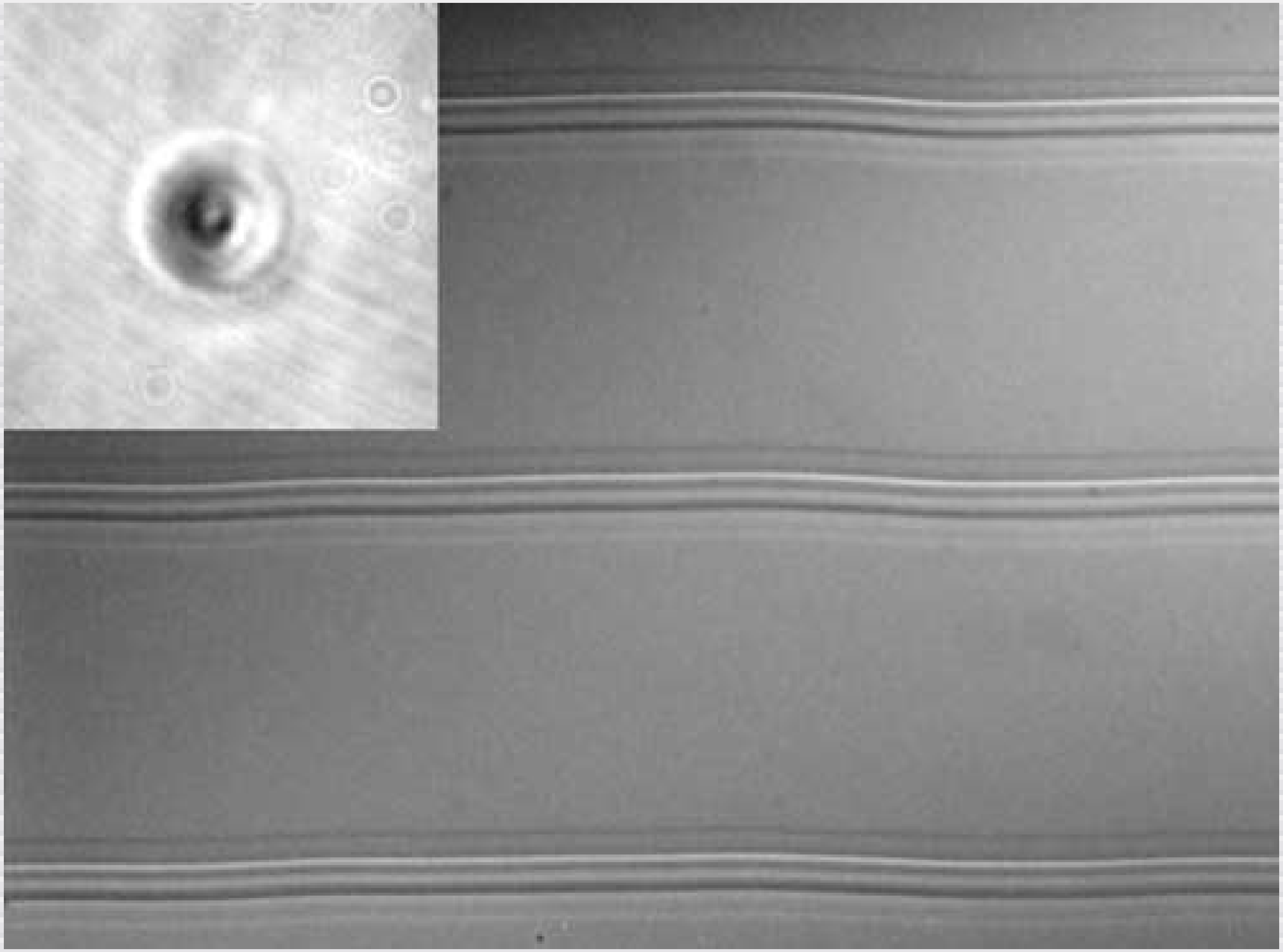
As_2S_3, 100 fs, 7 nJ

Low-energy processing

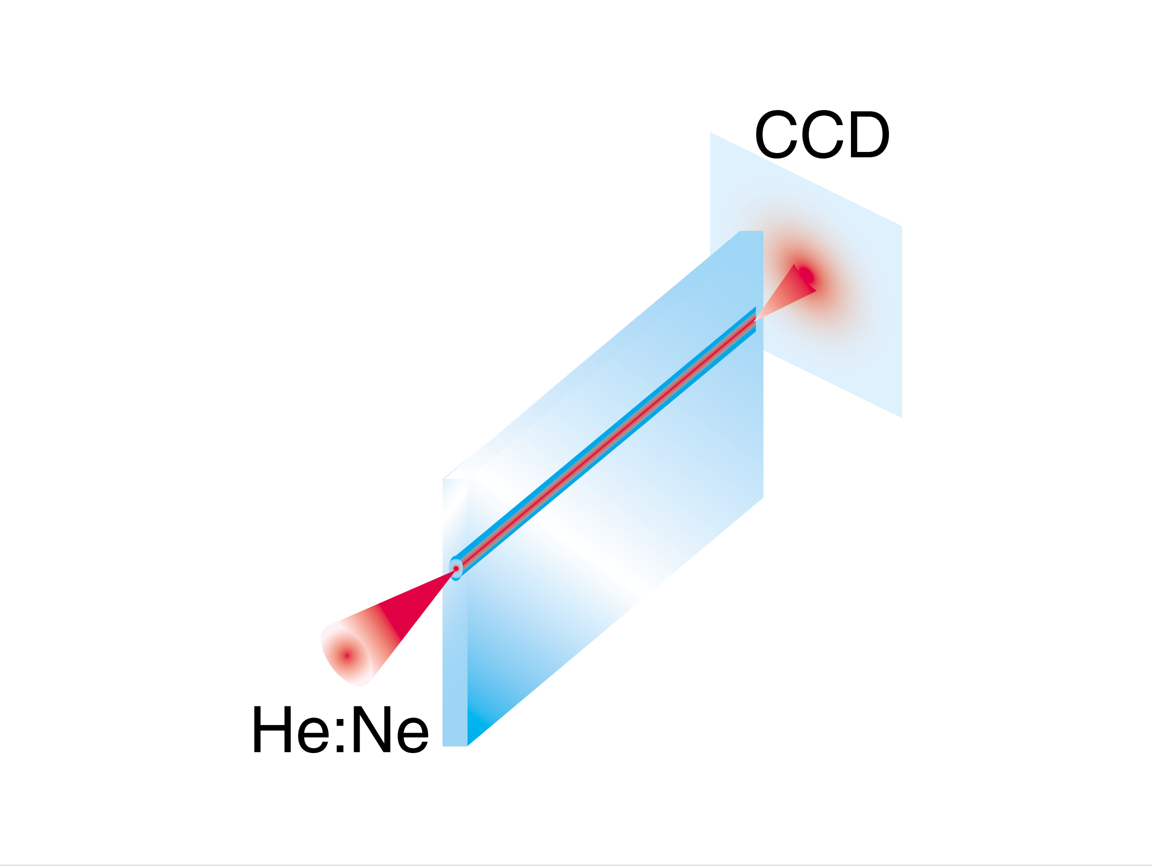
waveguide machining



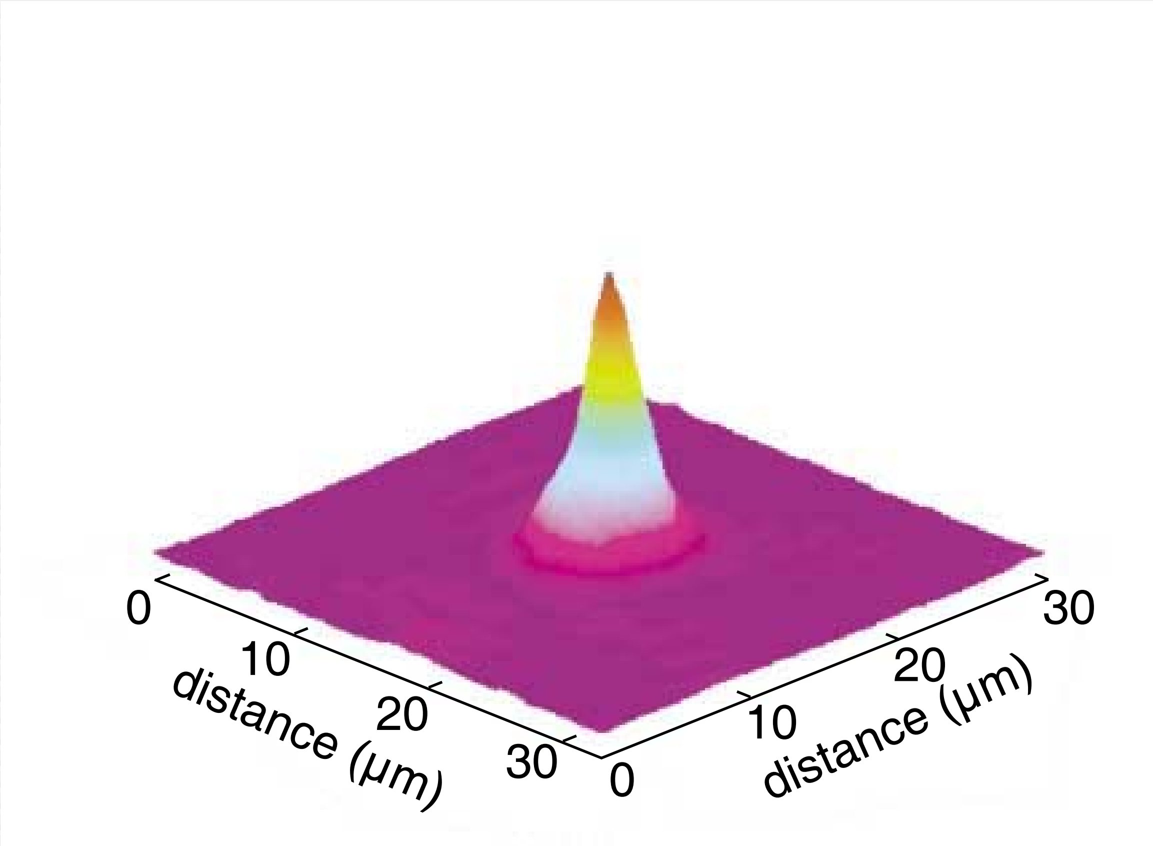
waveguide machining



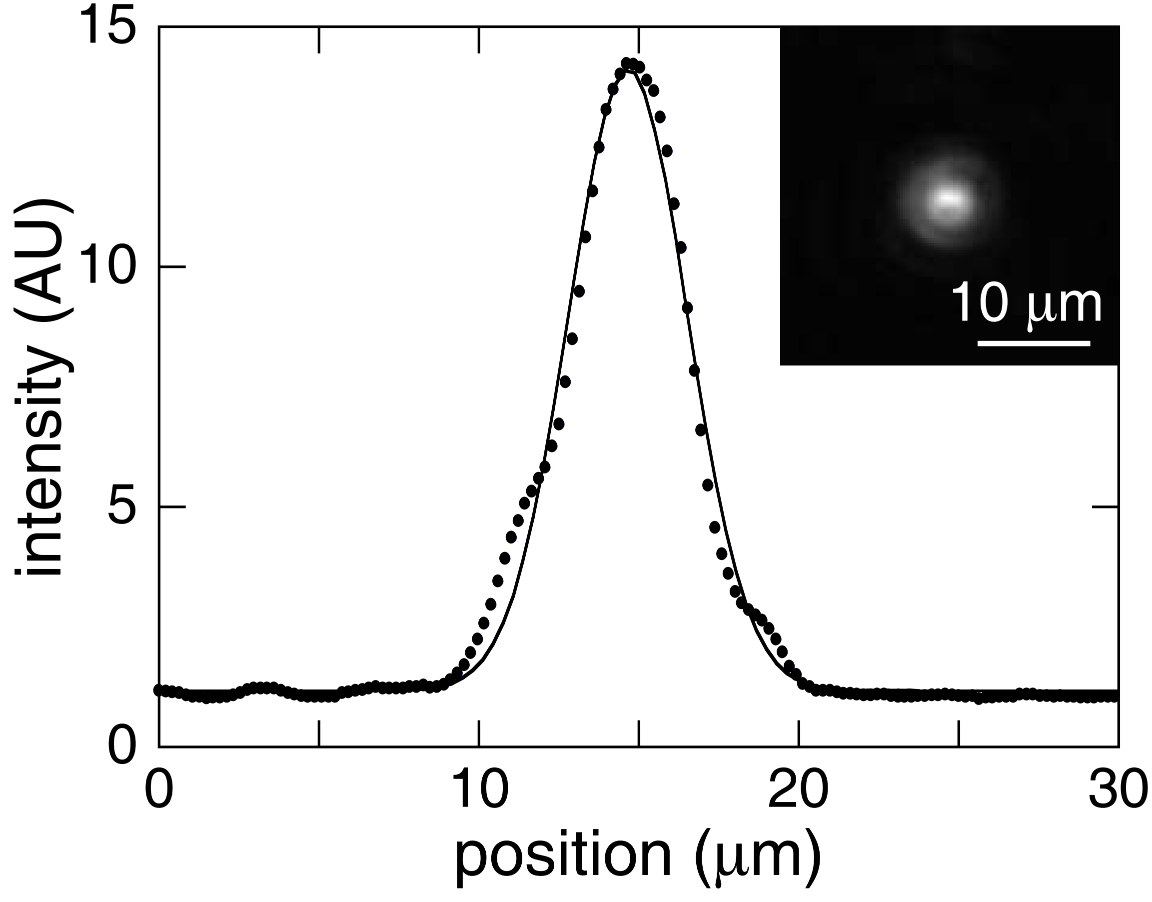
waveguide mode analysis



near field mode

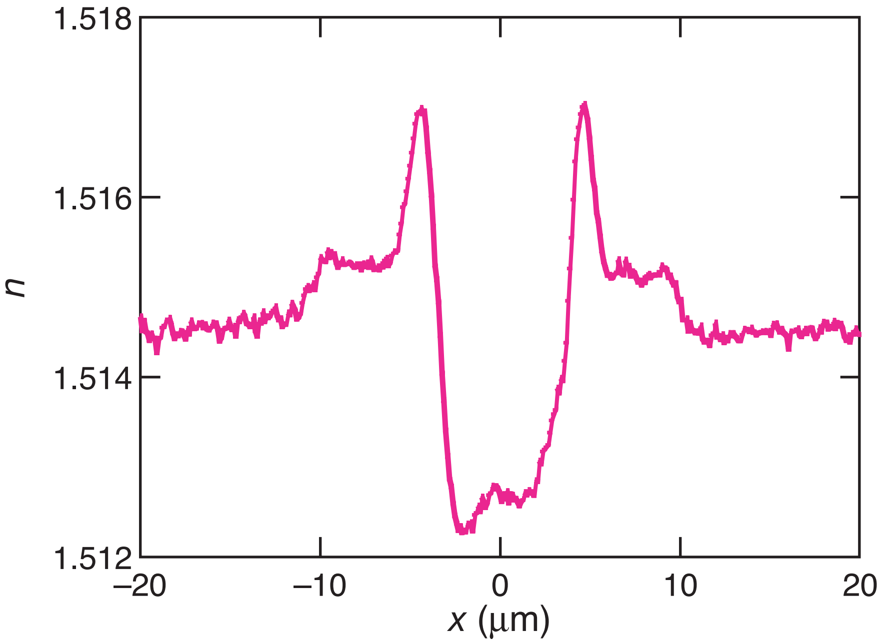


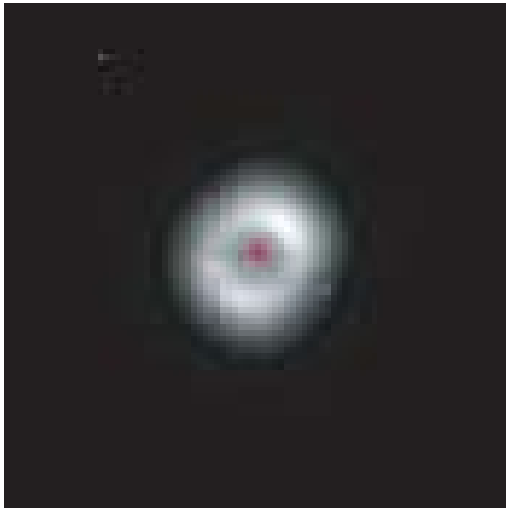
near field mode



refractive index profiles and near field mode at 633 nm

5 mm/s





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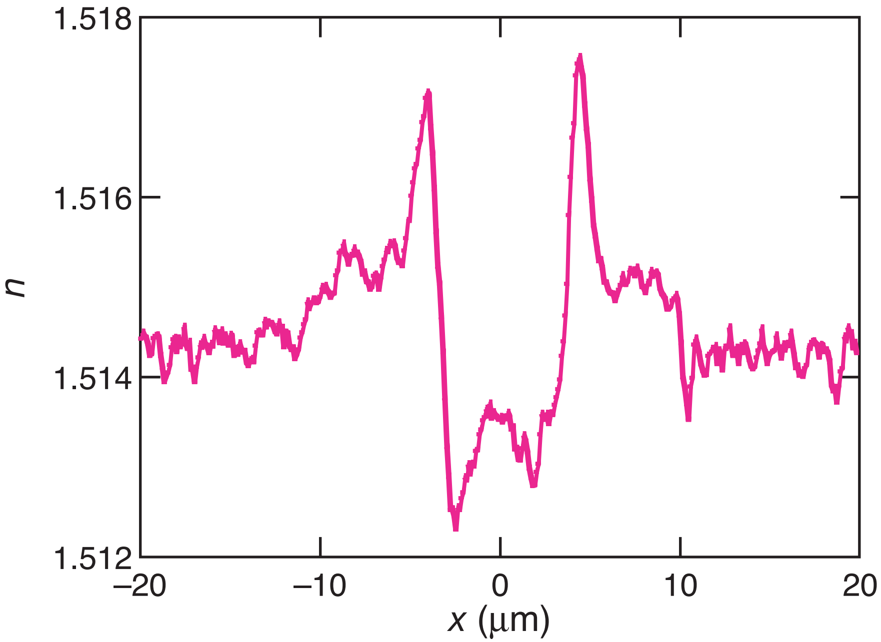
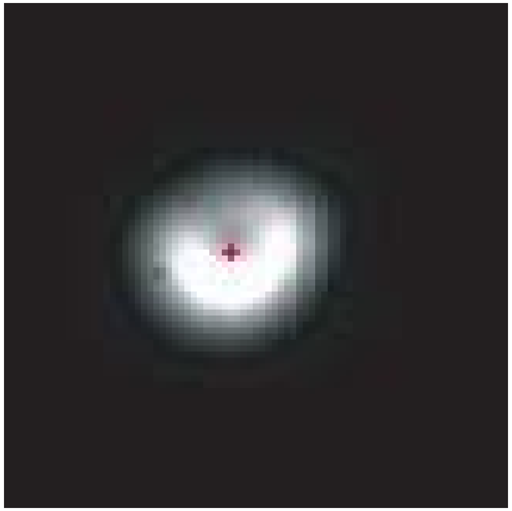
Low-energy processing

refractive index profiles and near field mode at 633 nm

10 mm/s





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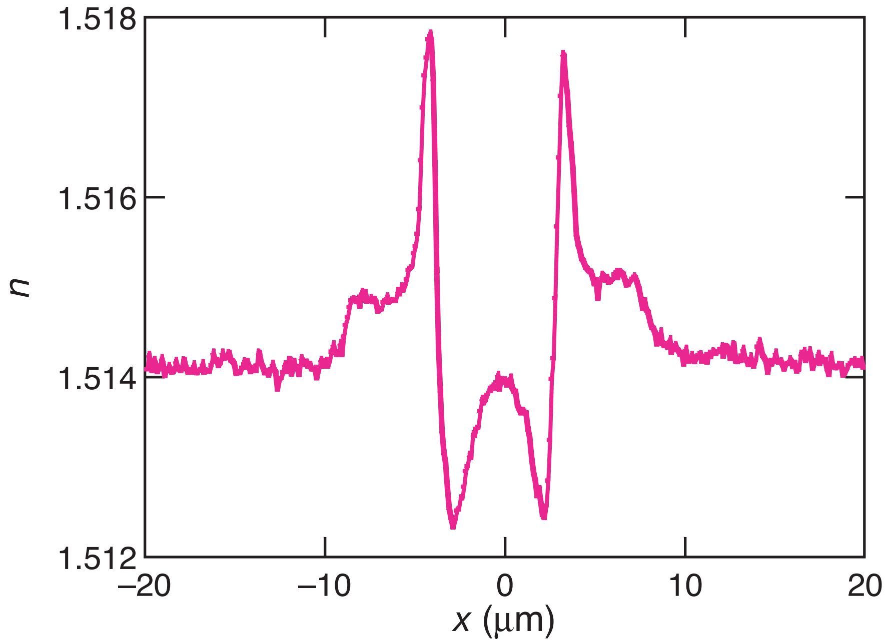
refractive index profiles and near field mode at 633 nm

20 mm/s



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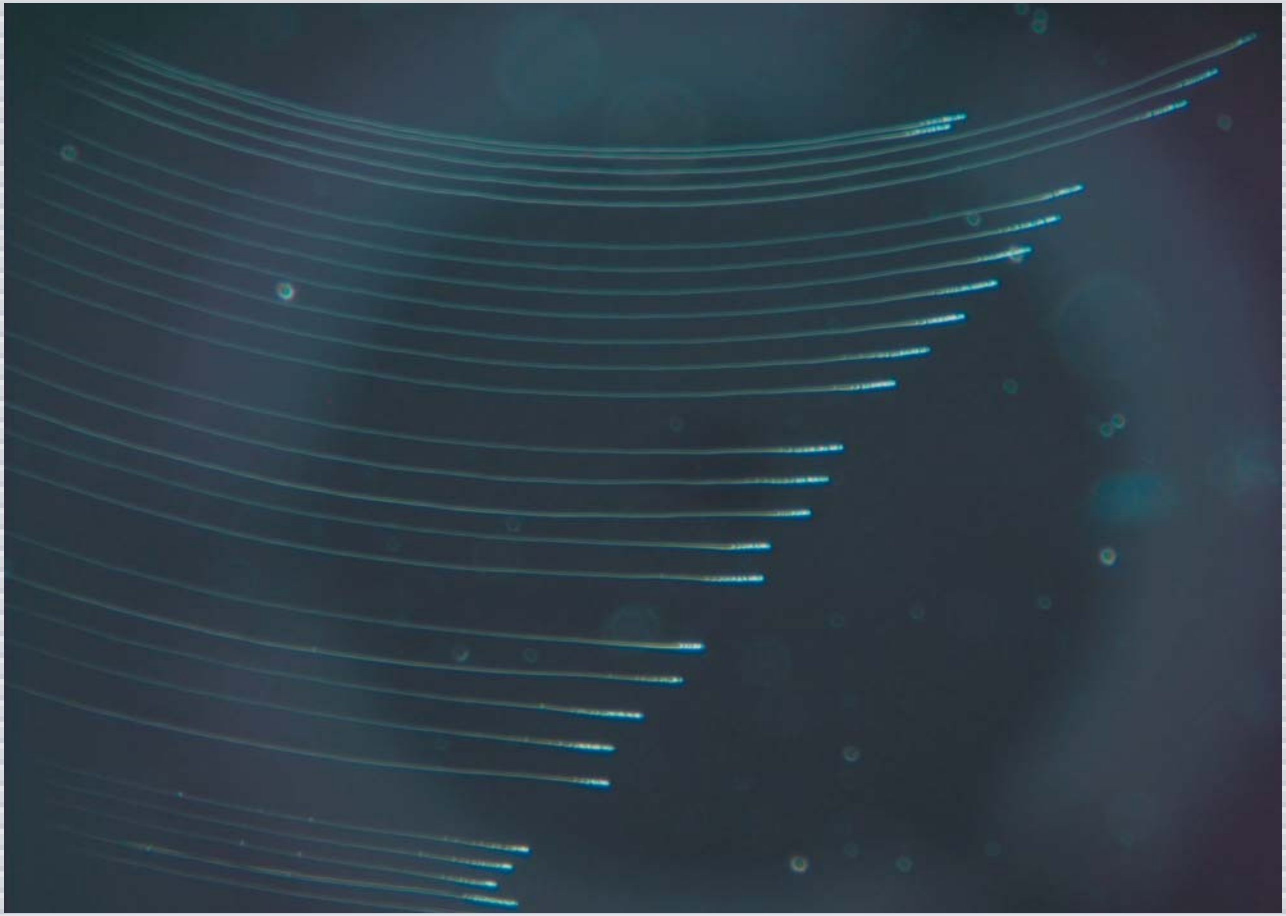
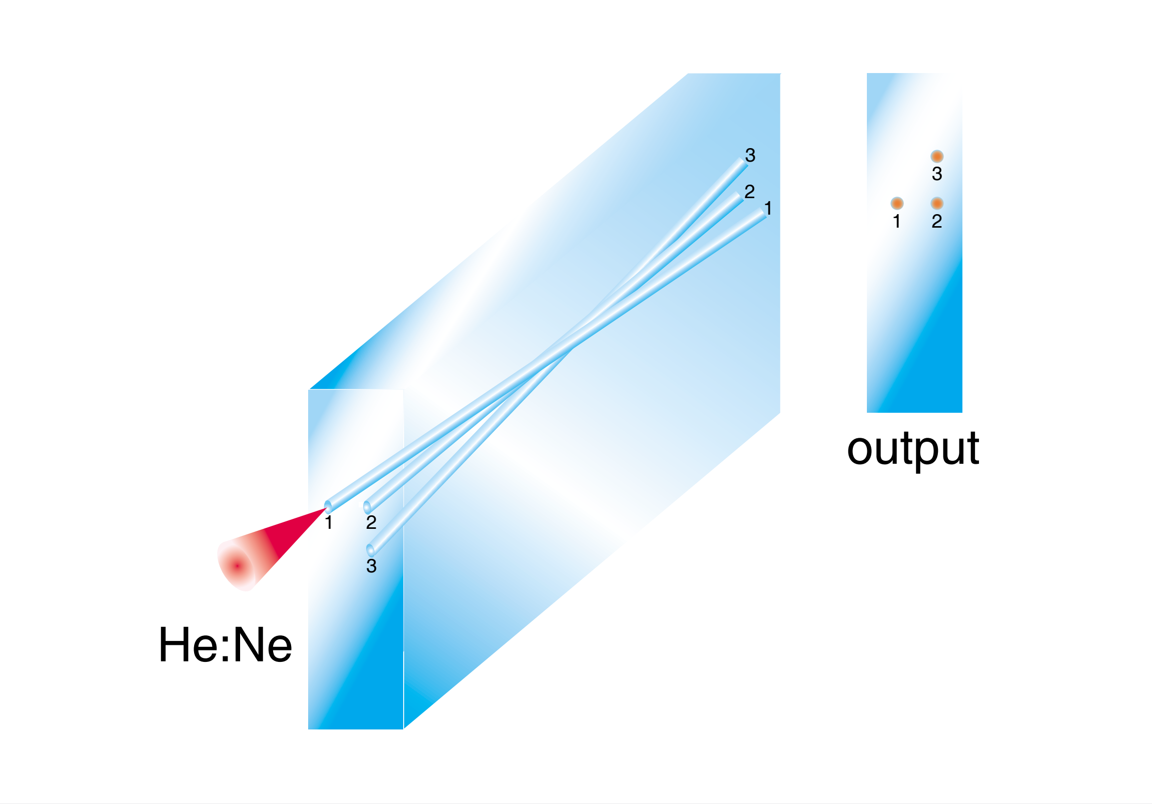
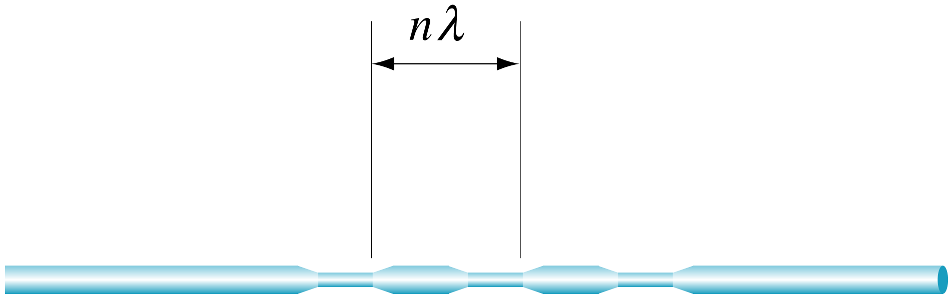
curved waveguides



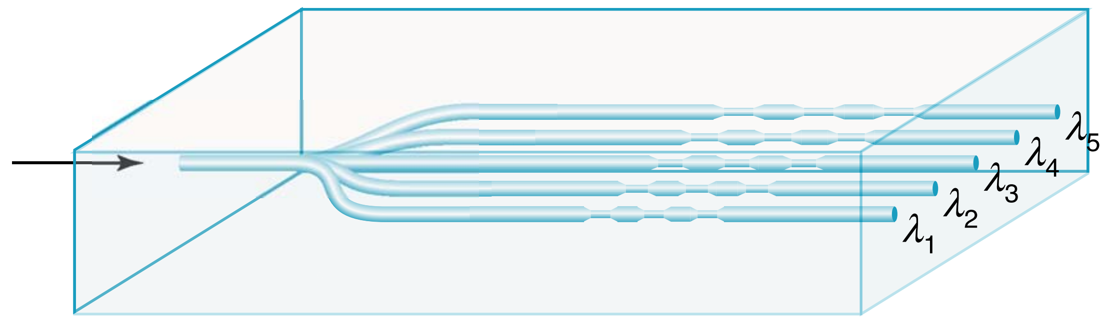
3D wave splitter



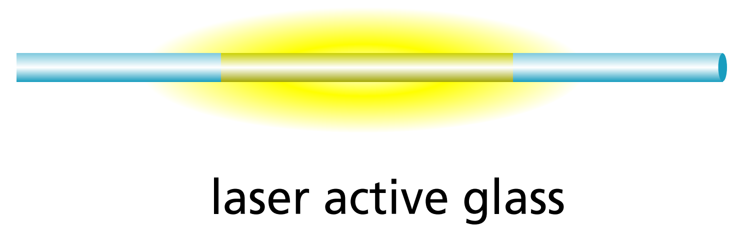
Bragg grating



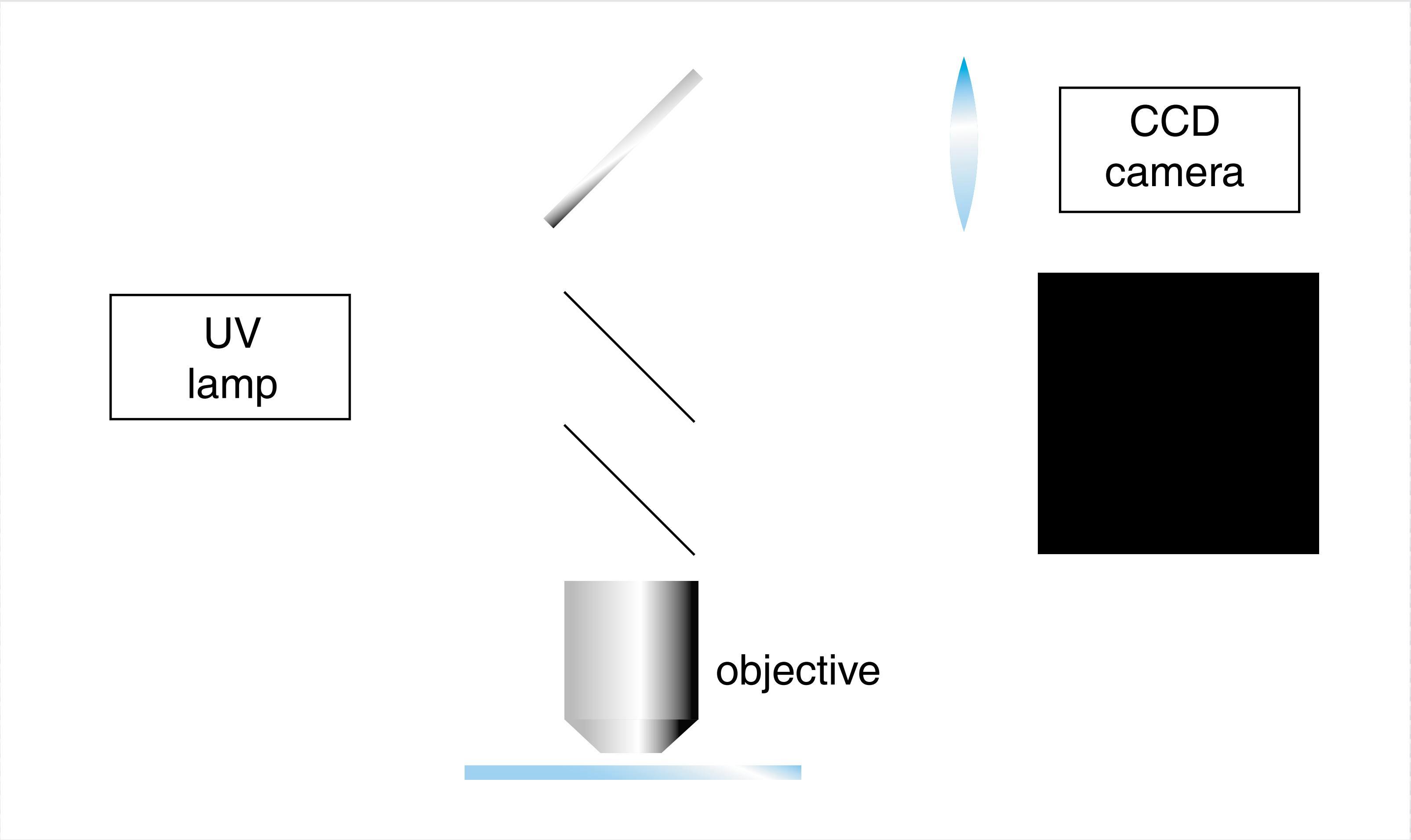
Bragg grating



monolithic amplifier

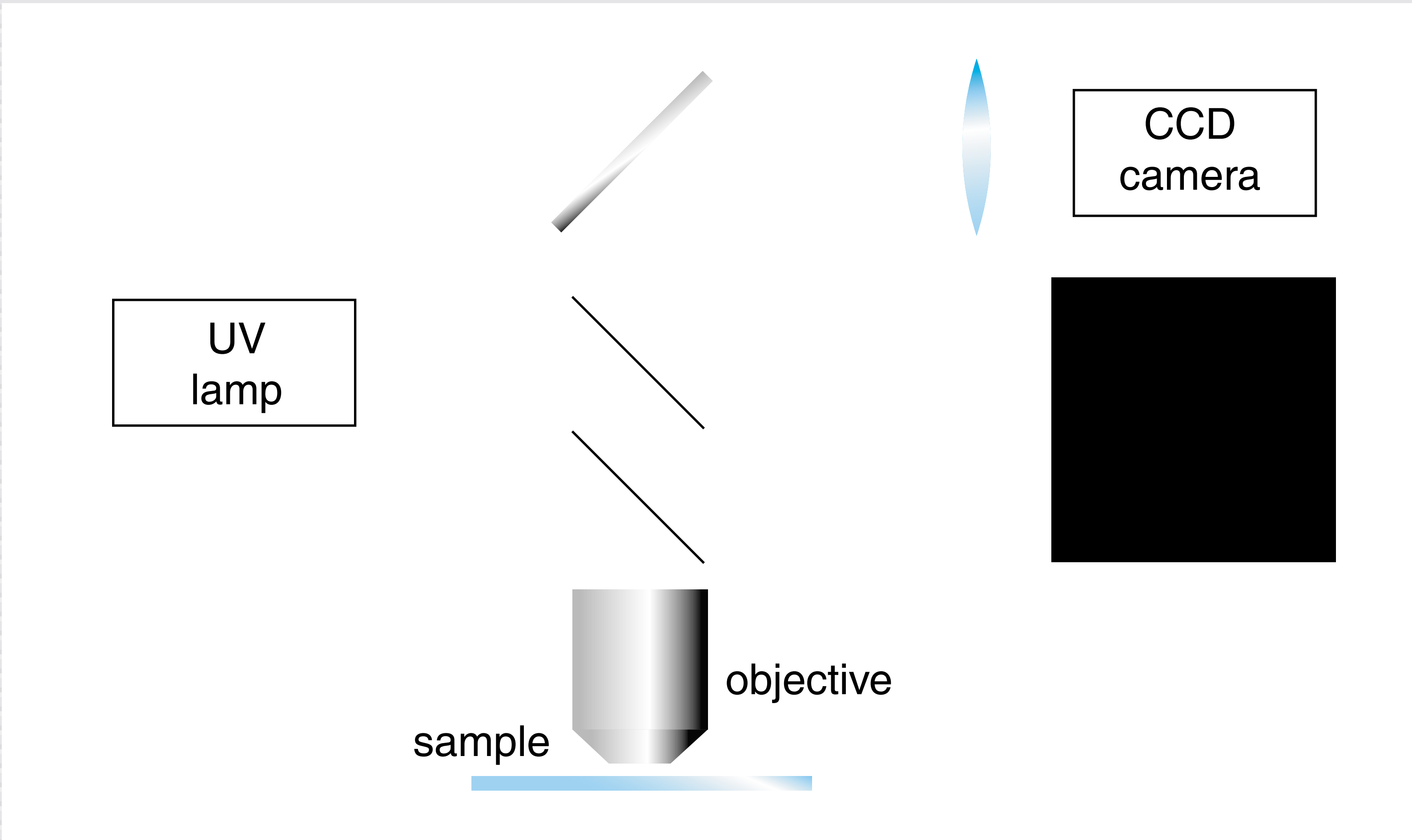


epi-fluorescence microscope

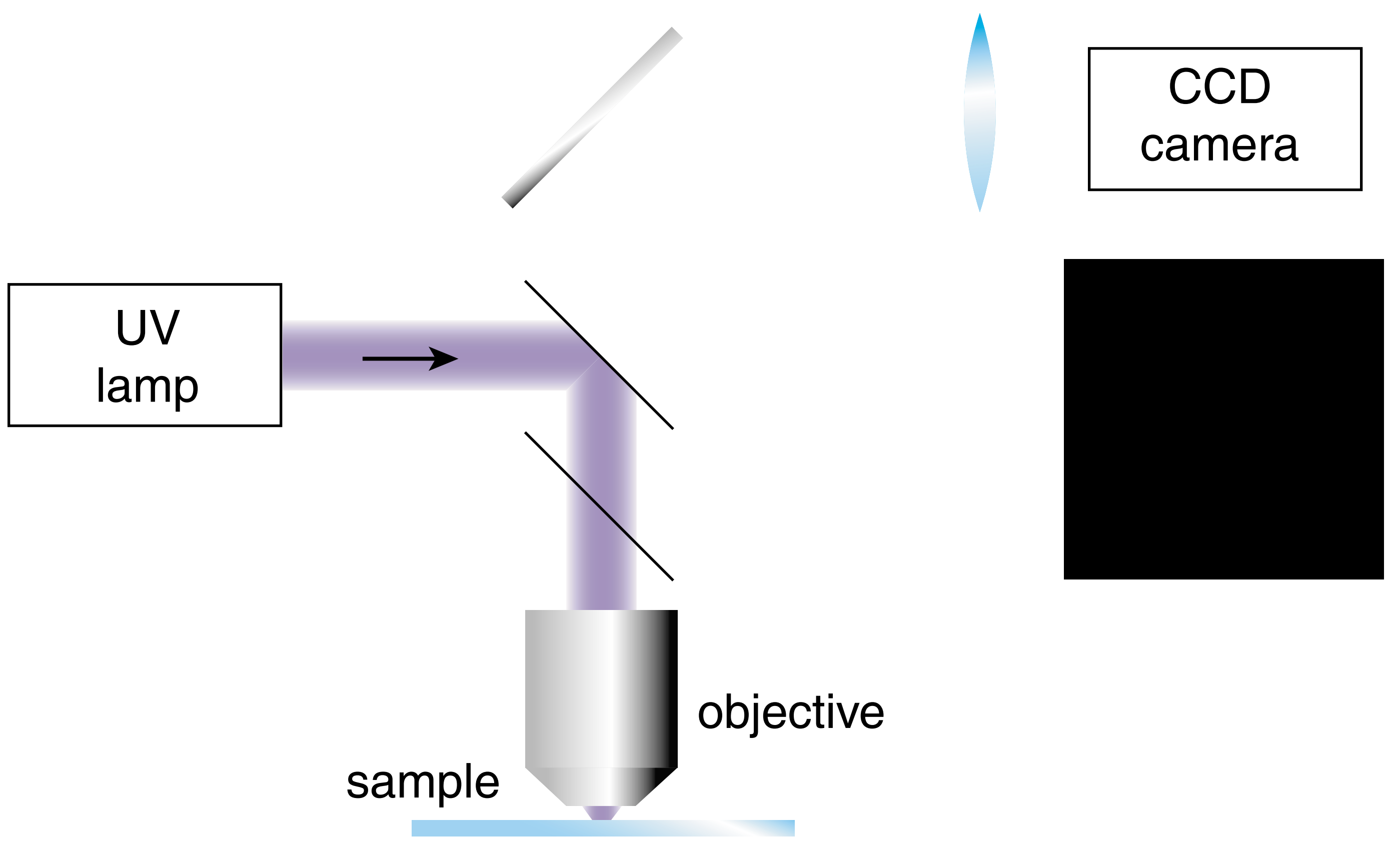


Low-energy processing

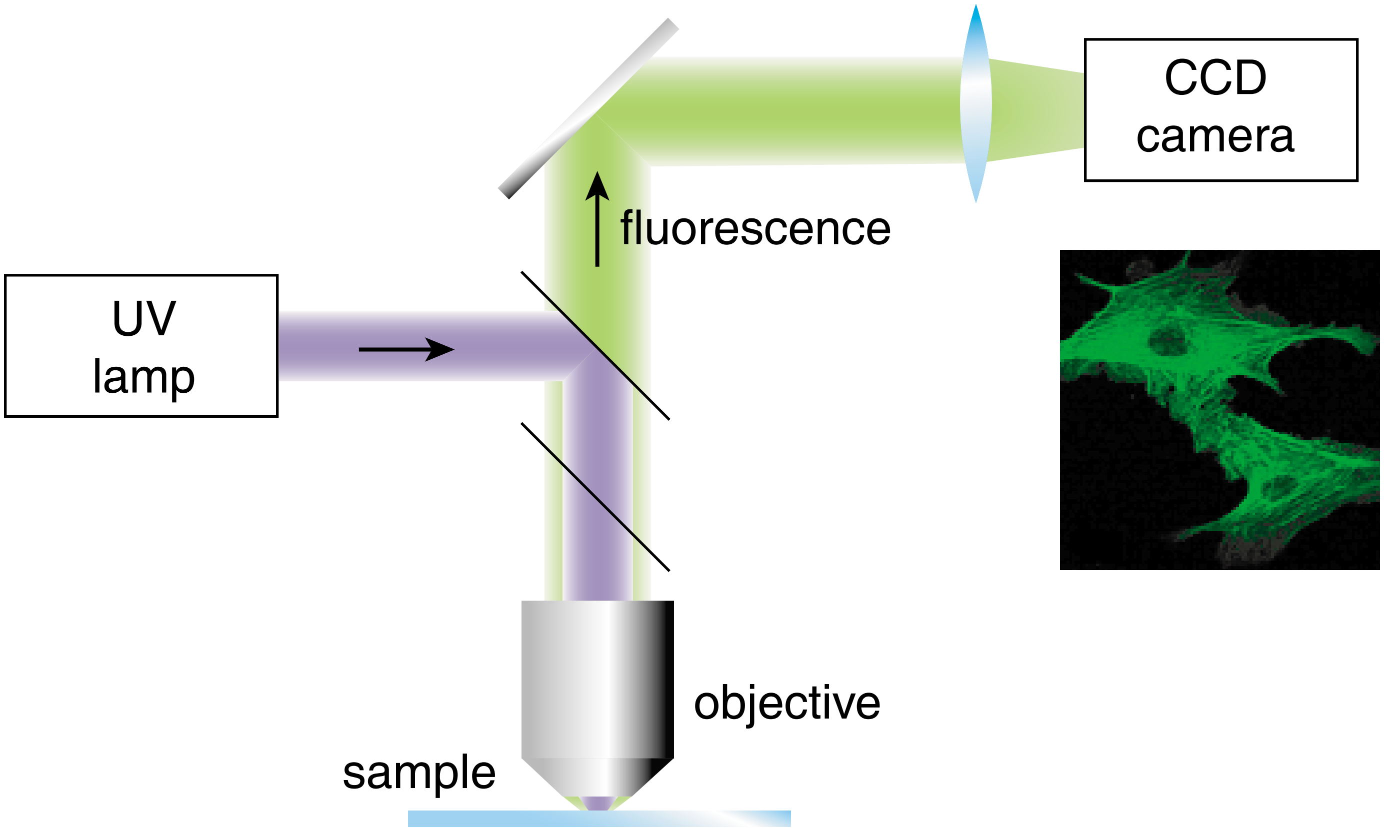
mount fluorescently tagged sample



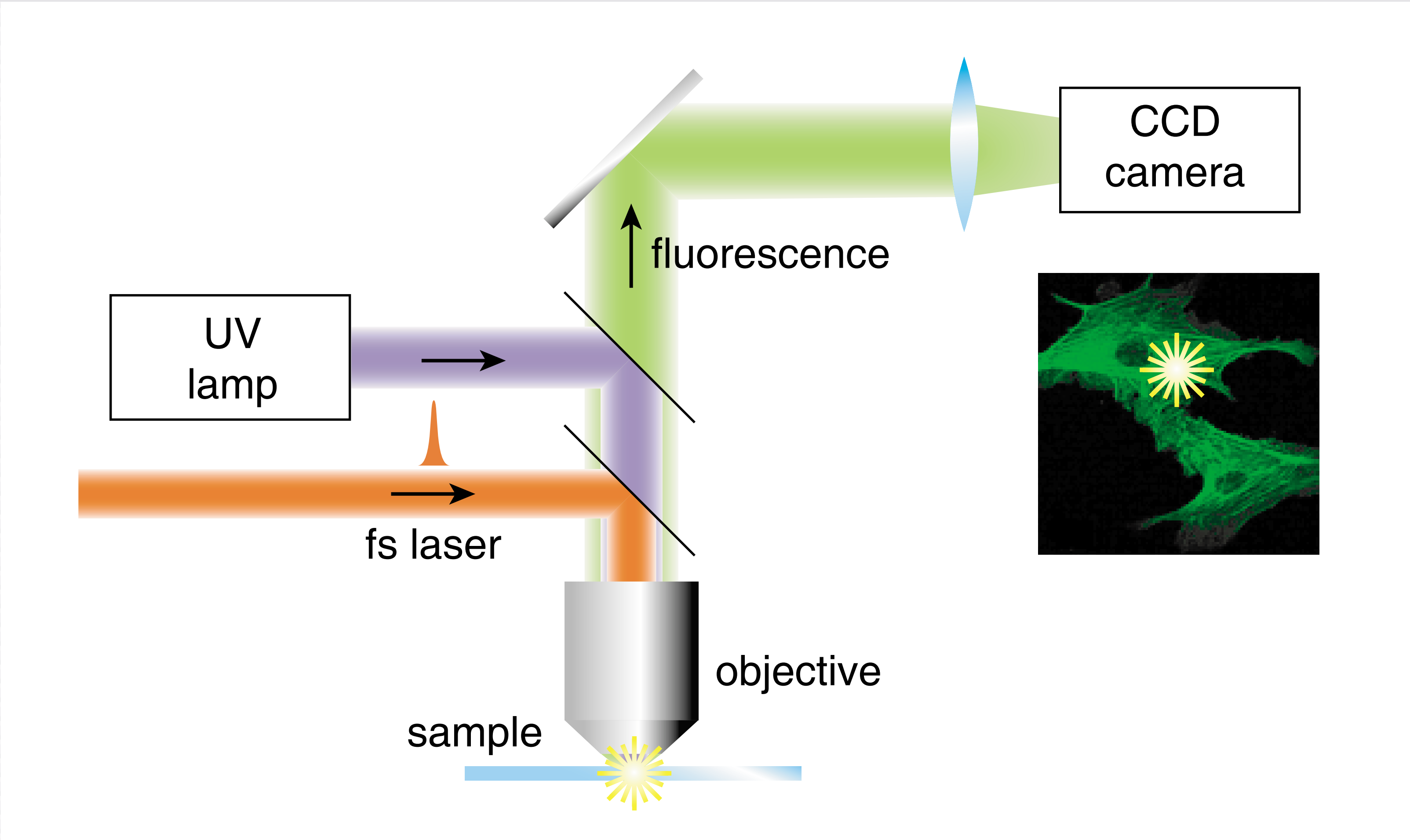
UV illumination…



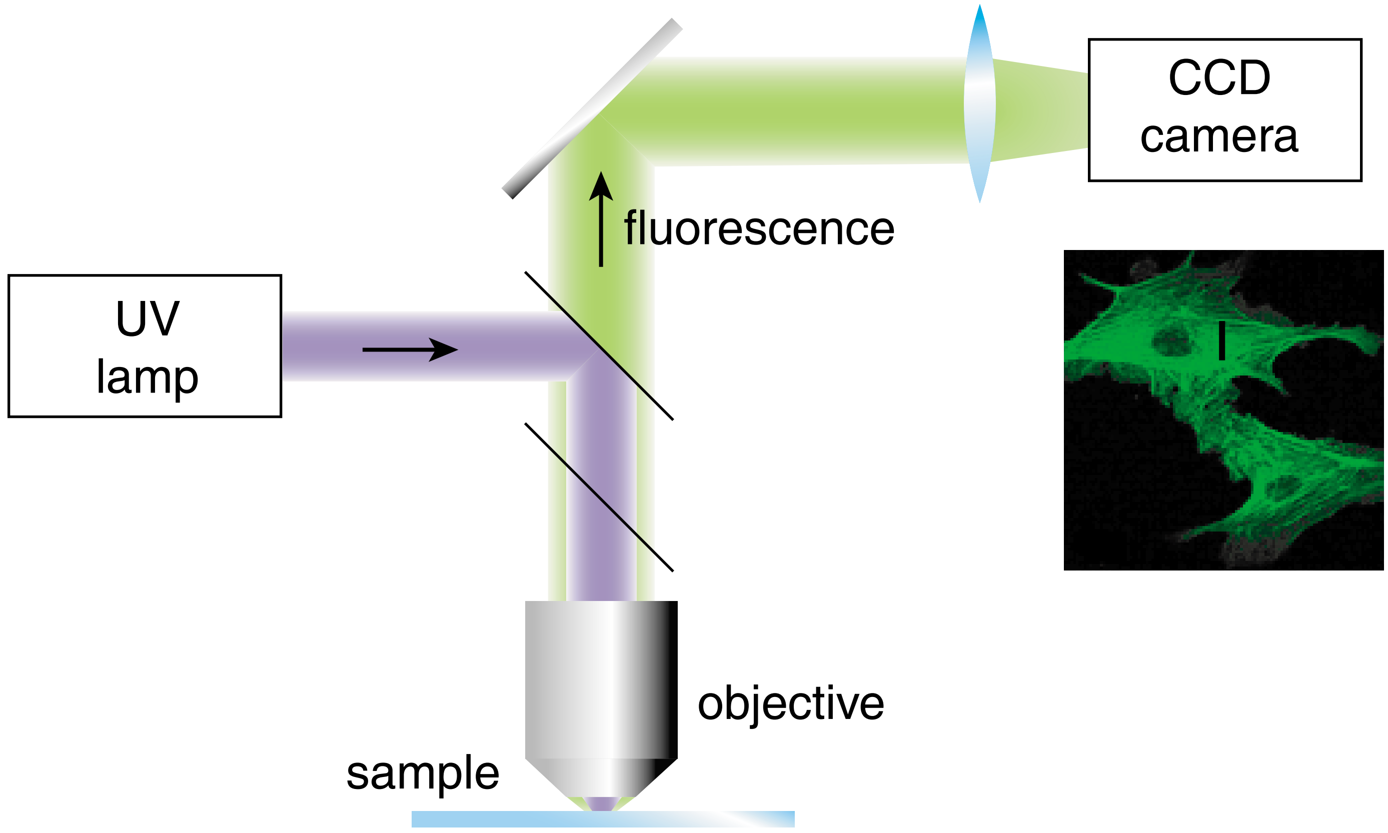
… causes fluorescence



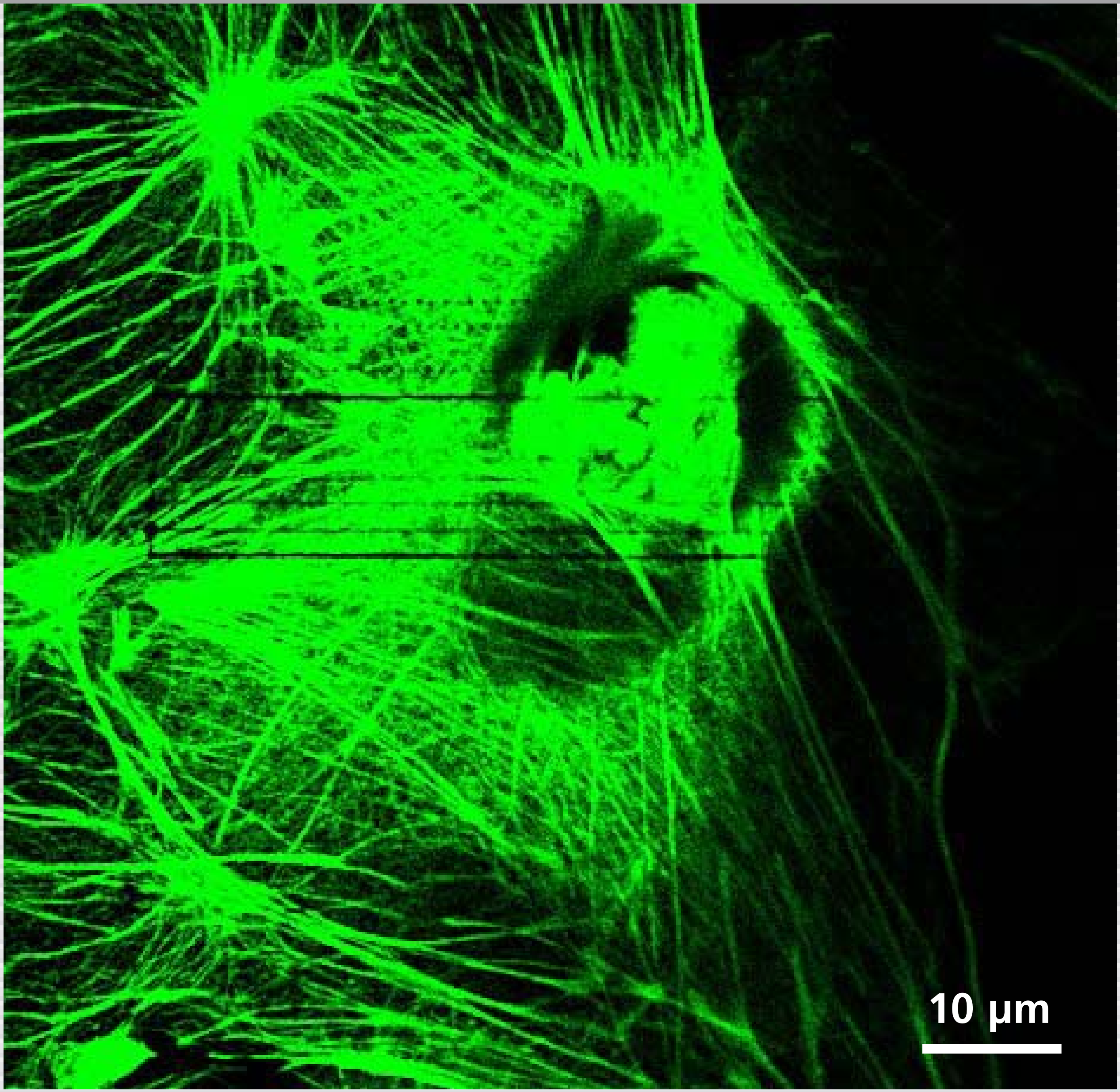
process with fs laser beam



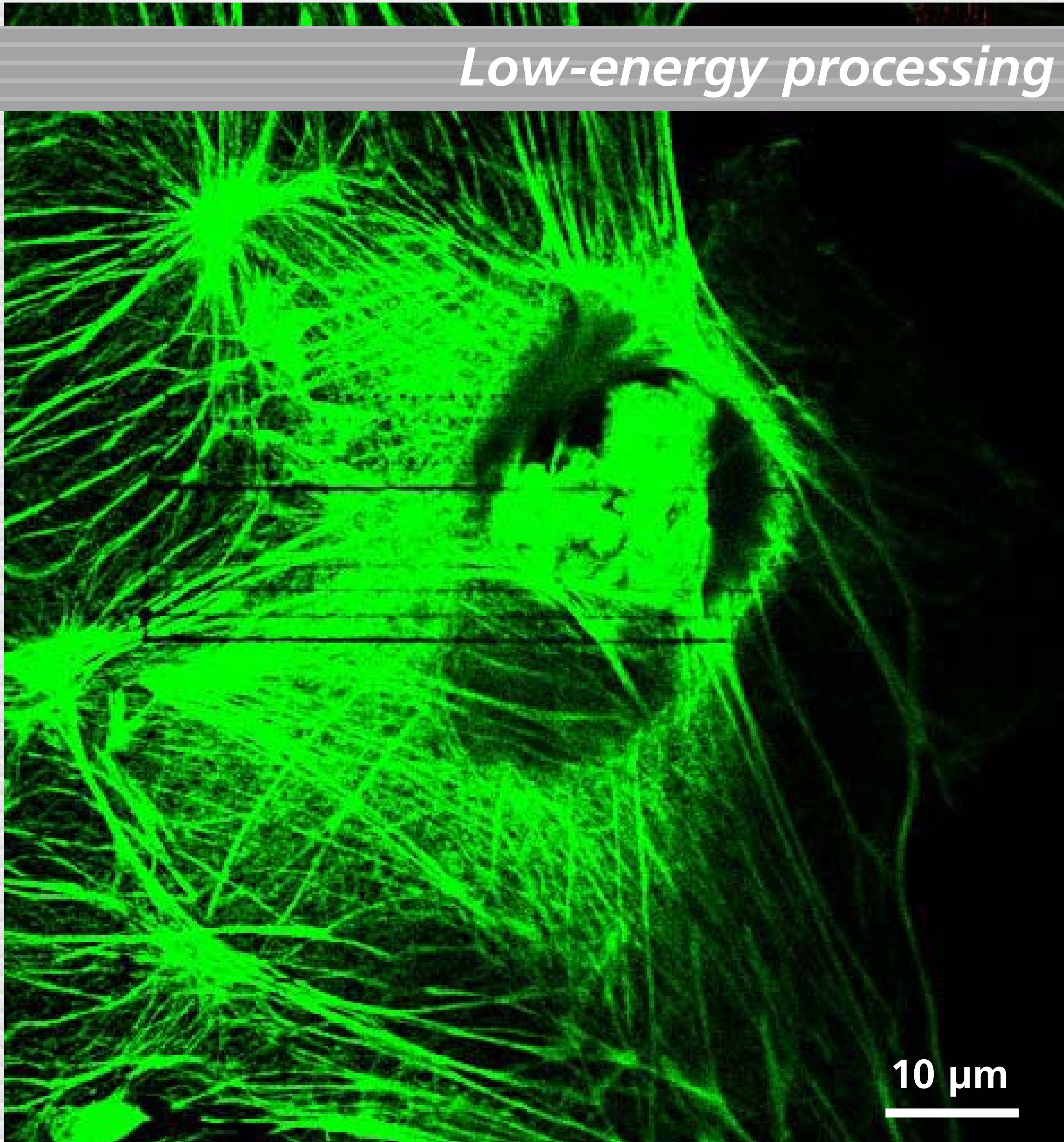
Low-energy processing



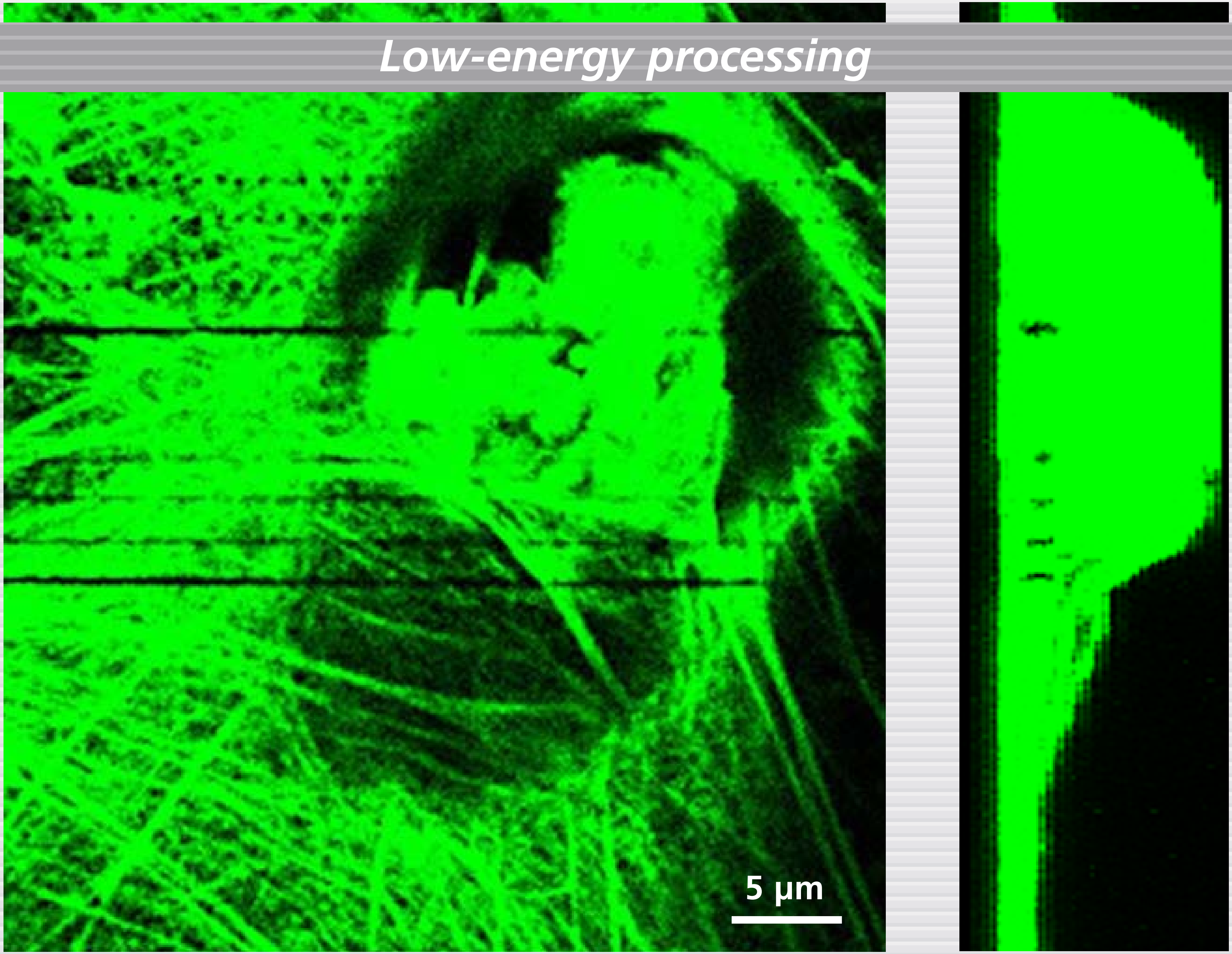
Low-energy processing



Low-energy processing



Low-energy processing



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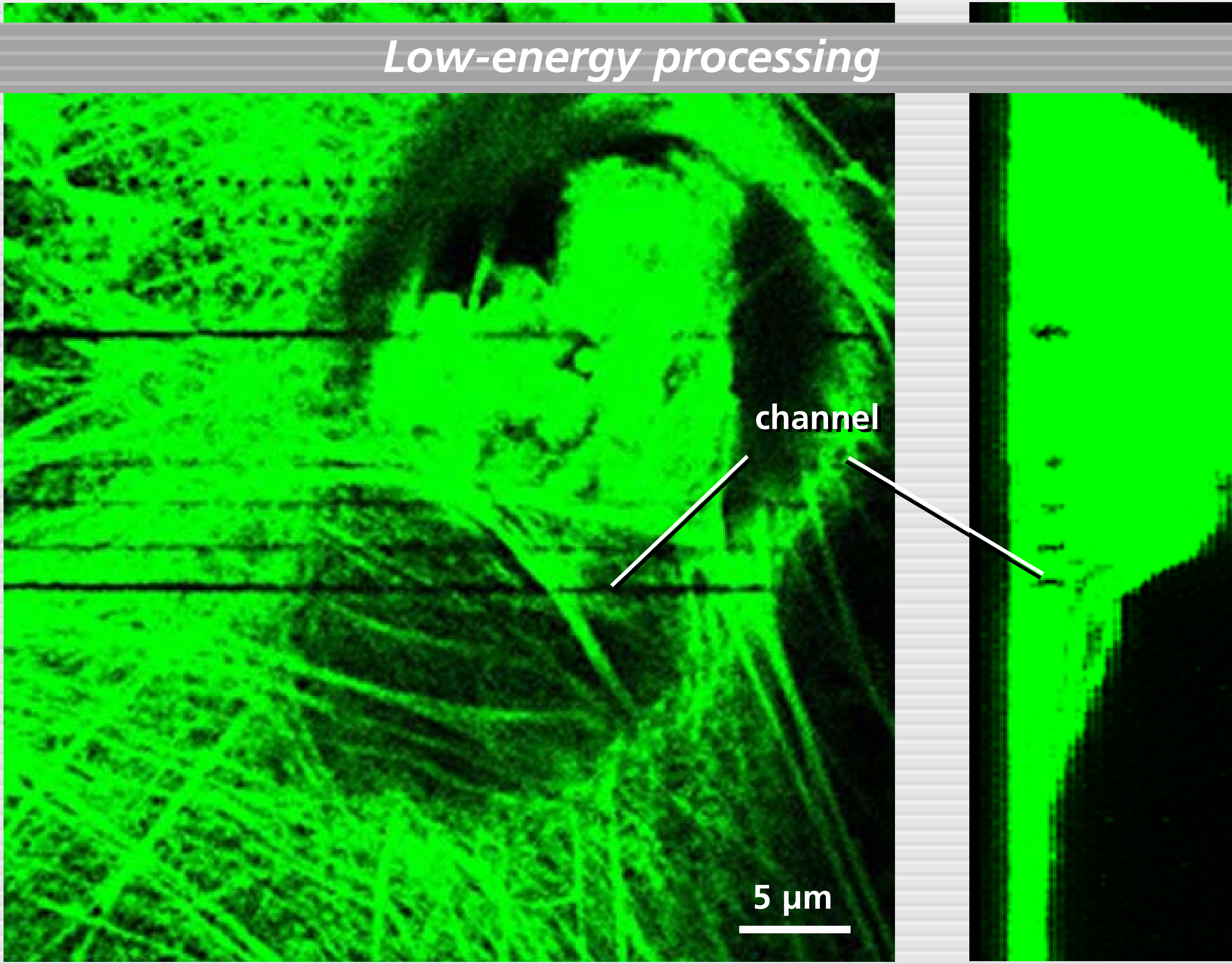

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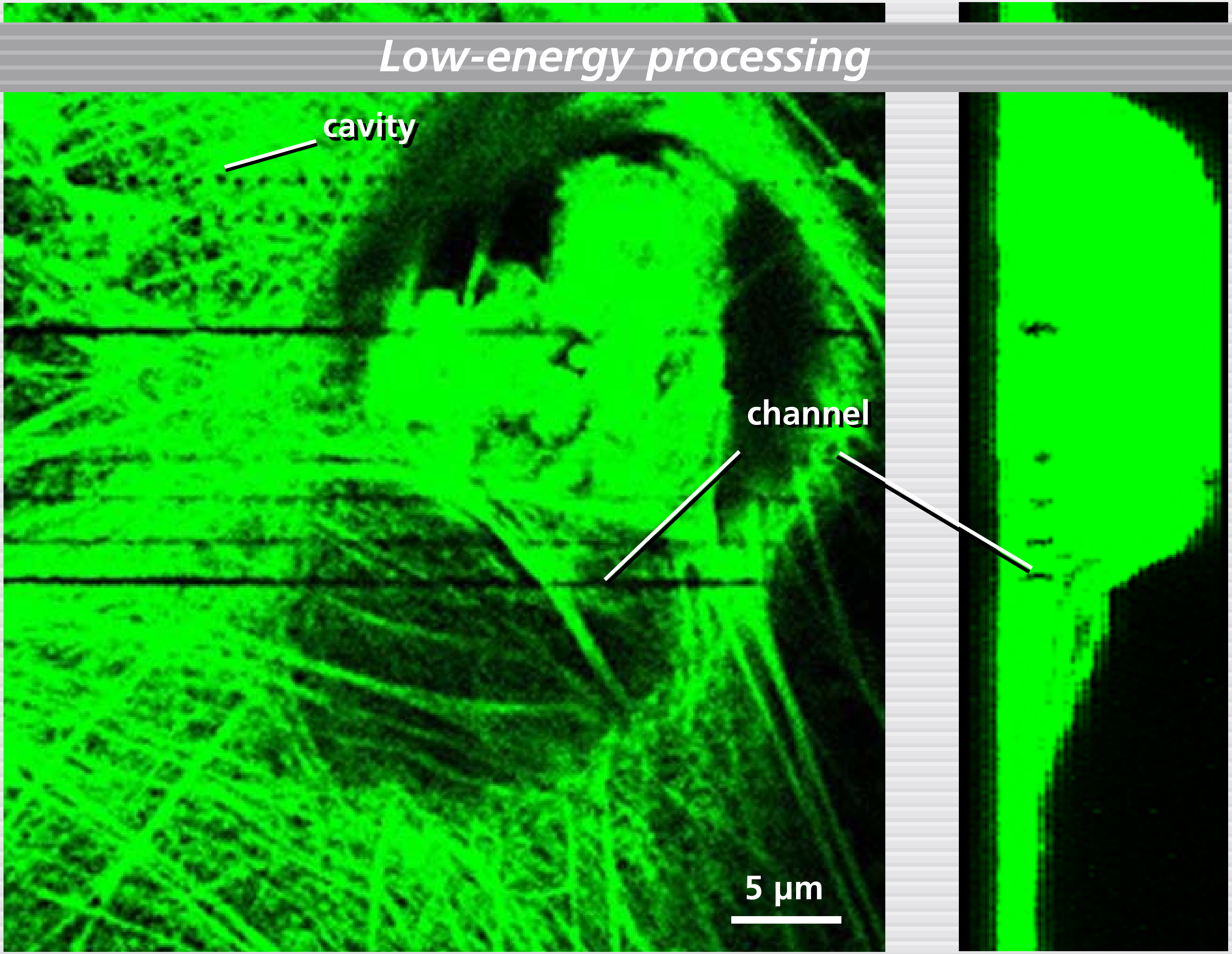
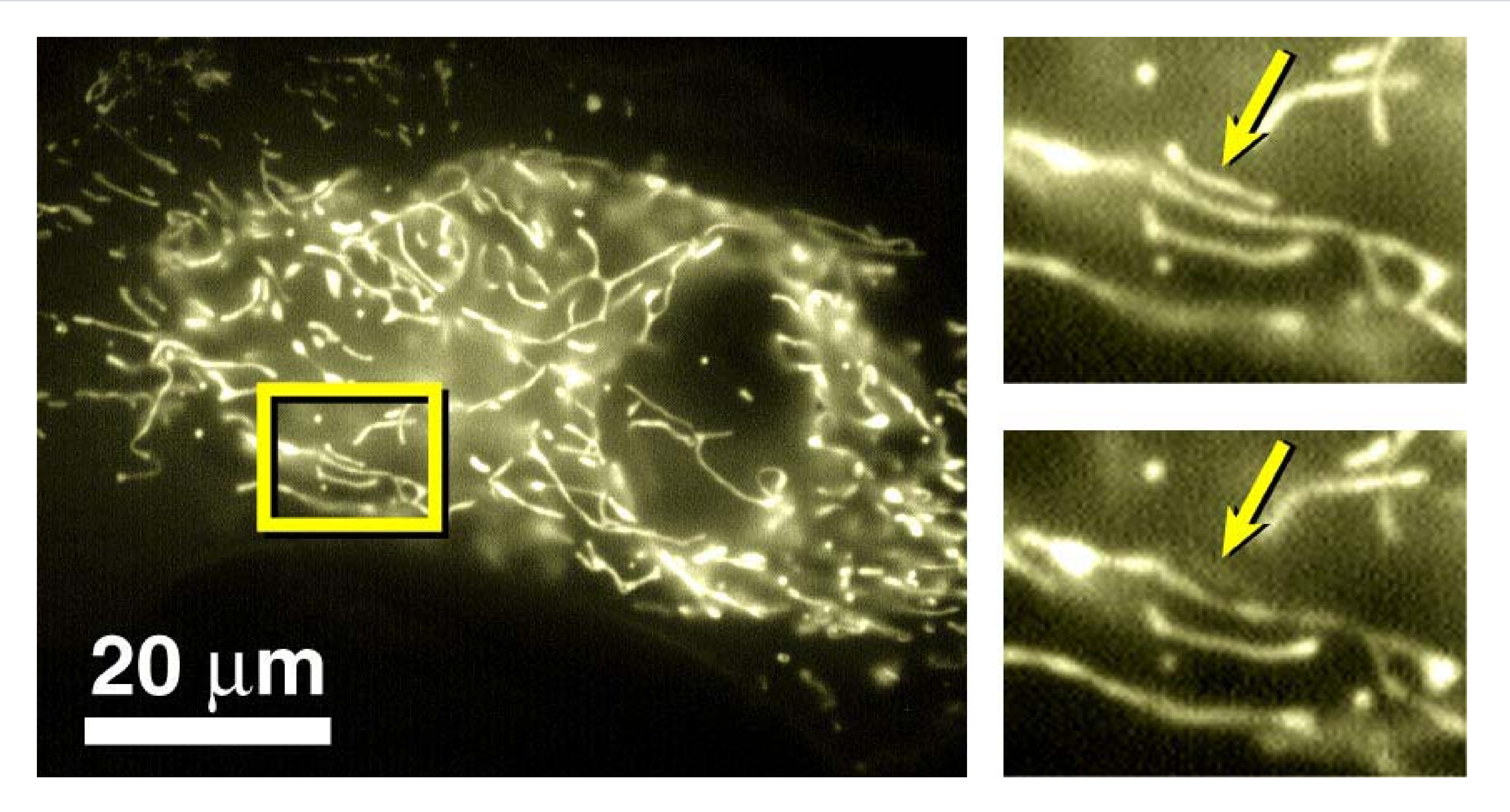
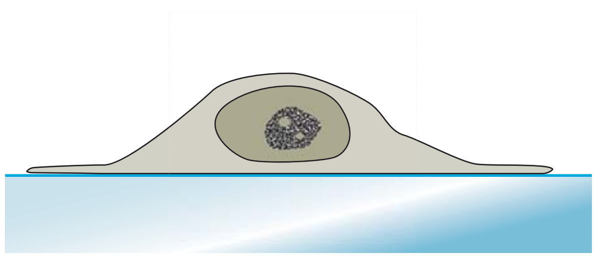
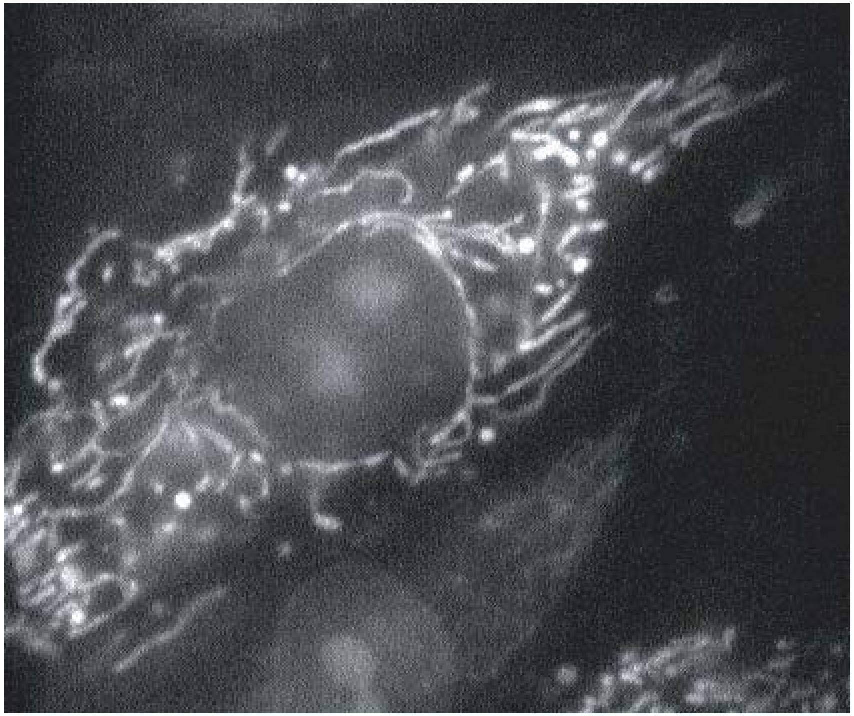


Low-energy processing

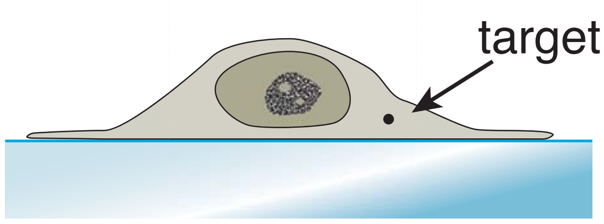


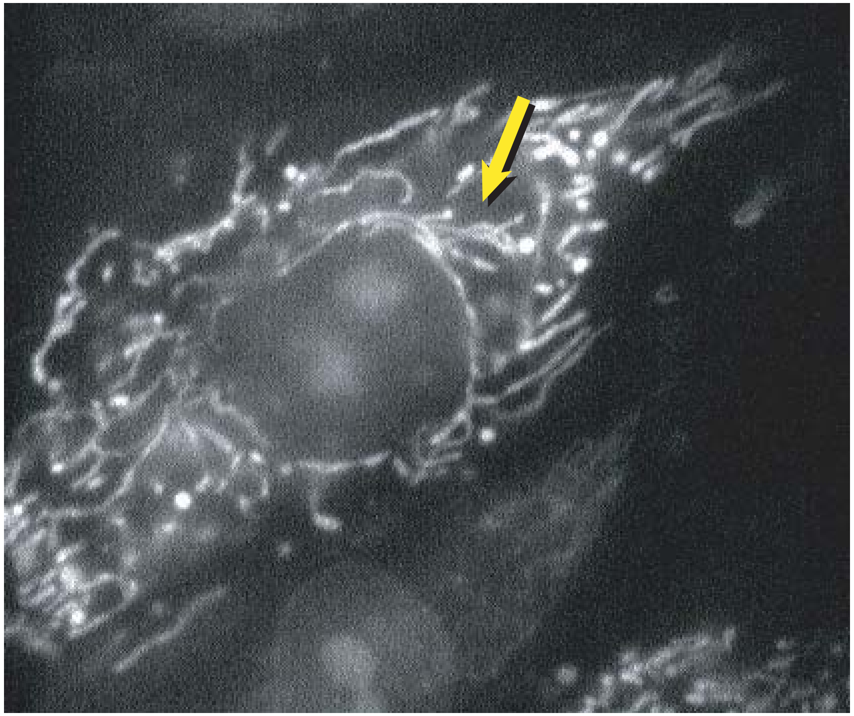
Ethydium bromide test



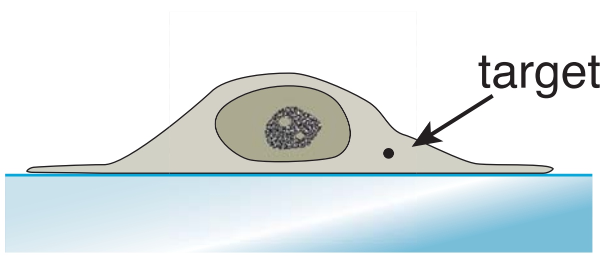


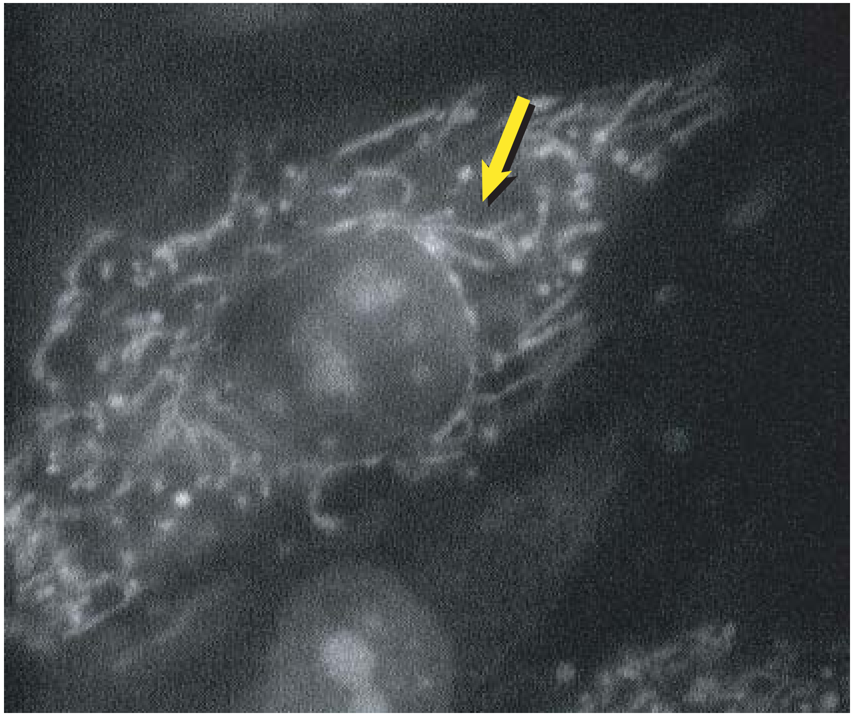
Ethydium bromide test



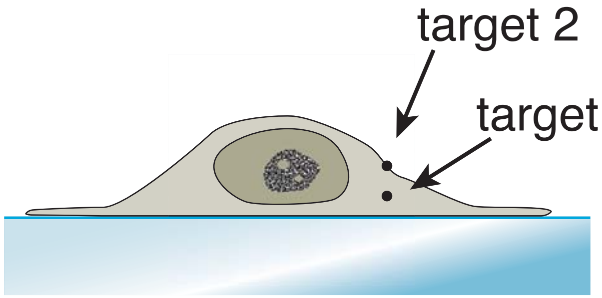


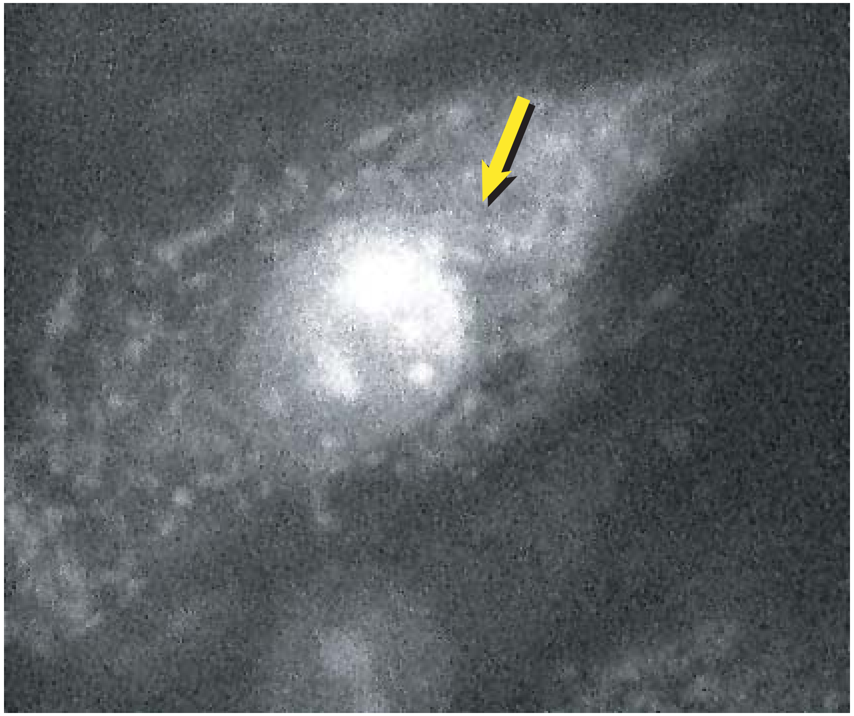
Ethydium bromide test





Ethydium bromide test





Nanoneurosurgery

Caenorhabditis Elegans

Juergen Berger & Ralph Sommer
Max-Planck Institute for Developmental Biology

Caenorhabditis Elegans

- **simple model organism**

Caenorhabditis Elegans

- **simple model organism**
- **similarities to higher organism**

Caenorhabditis Elegans

- simple model organism
- similarities to higher organism
- genome fully sequenced

Caenorhabditis Elegans

- simple model organism
- similarities to higher organism
- genome fully sequenced
- easy to handle

Nanoneurosurgery

- **80 µm x 1 mm**

Caenorhabditis Elegans

- 80 µm x 1 mm
- about 1300 cells

Caenorhabditis Elegans

- **80 µm x 1 mm**
- **about 1300 cells**
- **302 neurons**

Caenorhabditis Elegans

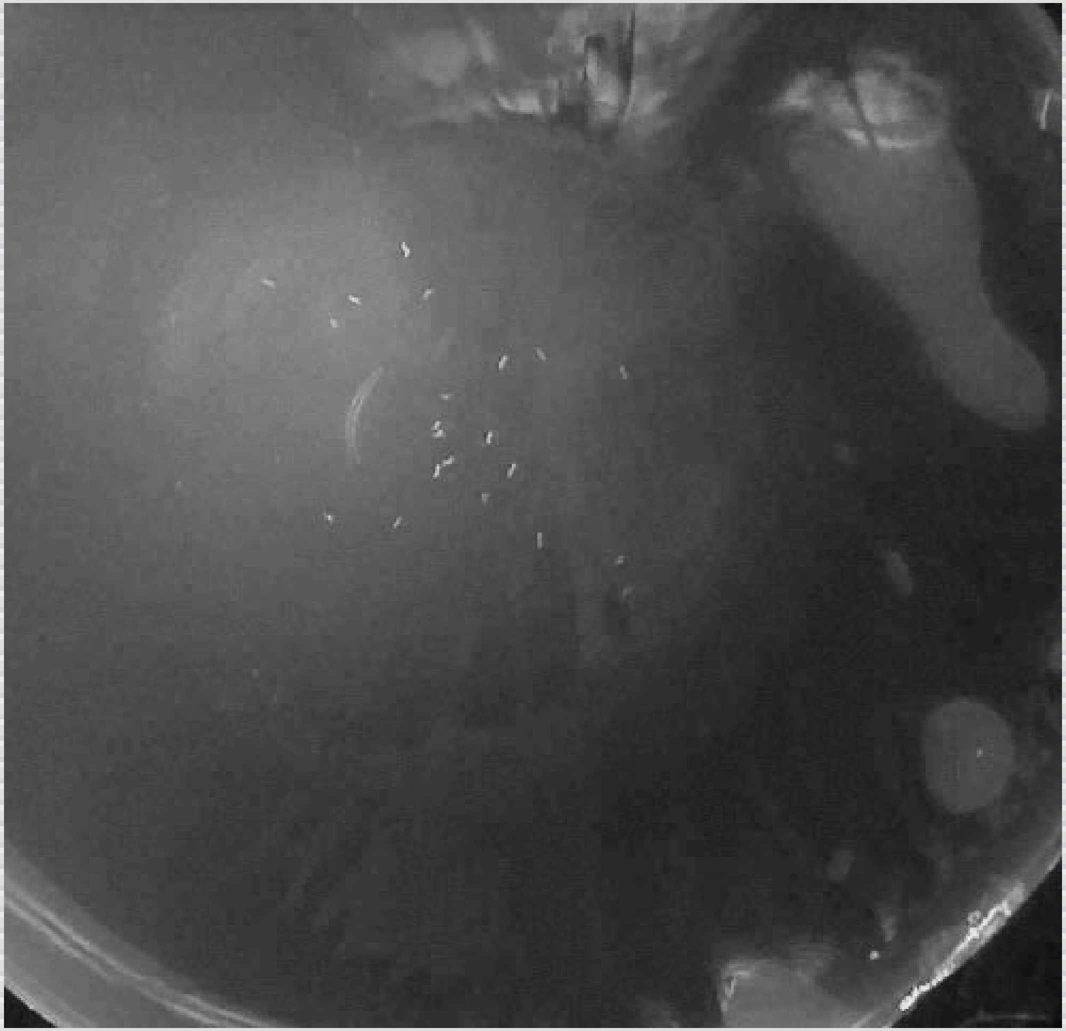
- **80 µm x 1 mm**
- **about 1300 cells**
- **302 neurons**
- **invariant wiring diagram**

Caenorhabditis Elegans

- **80 µm x 1 mm**
- **about 1300 cells**
- **302 neurons**
- **invariant wiring diagram**
- **neuronal system completely encodes behavior**

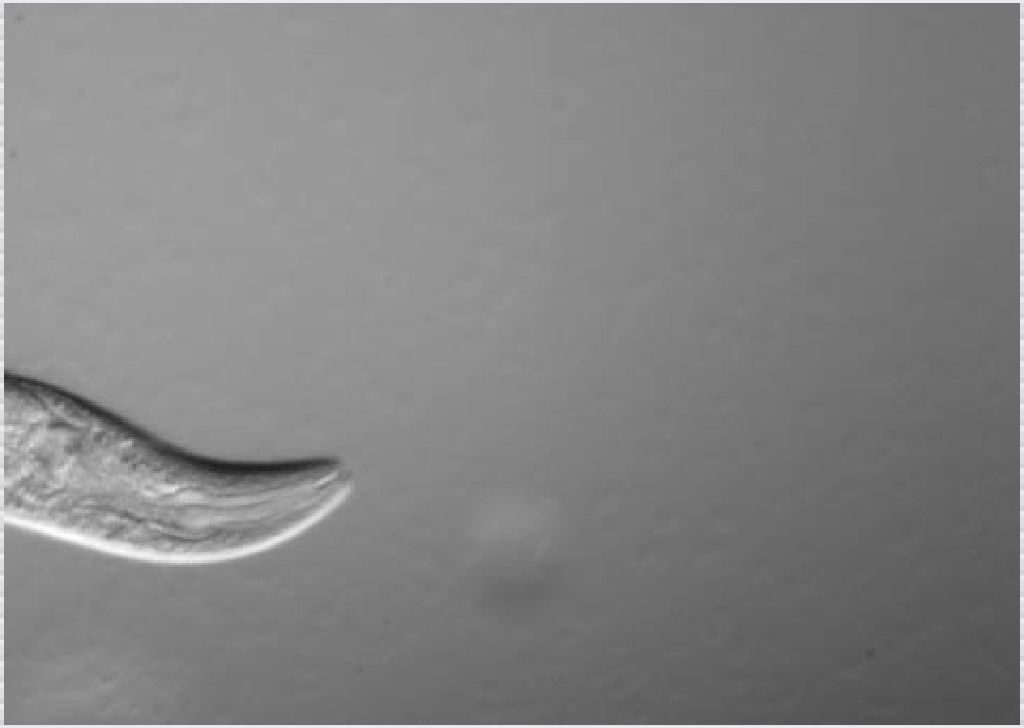
Nanoneurosurgery

Caenorhabditis Elegans



Nanoneurosurgery

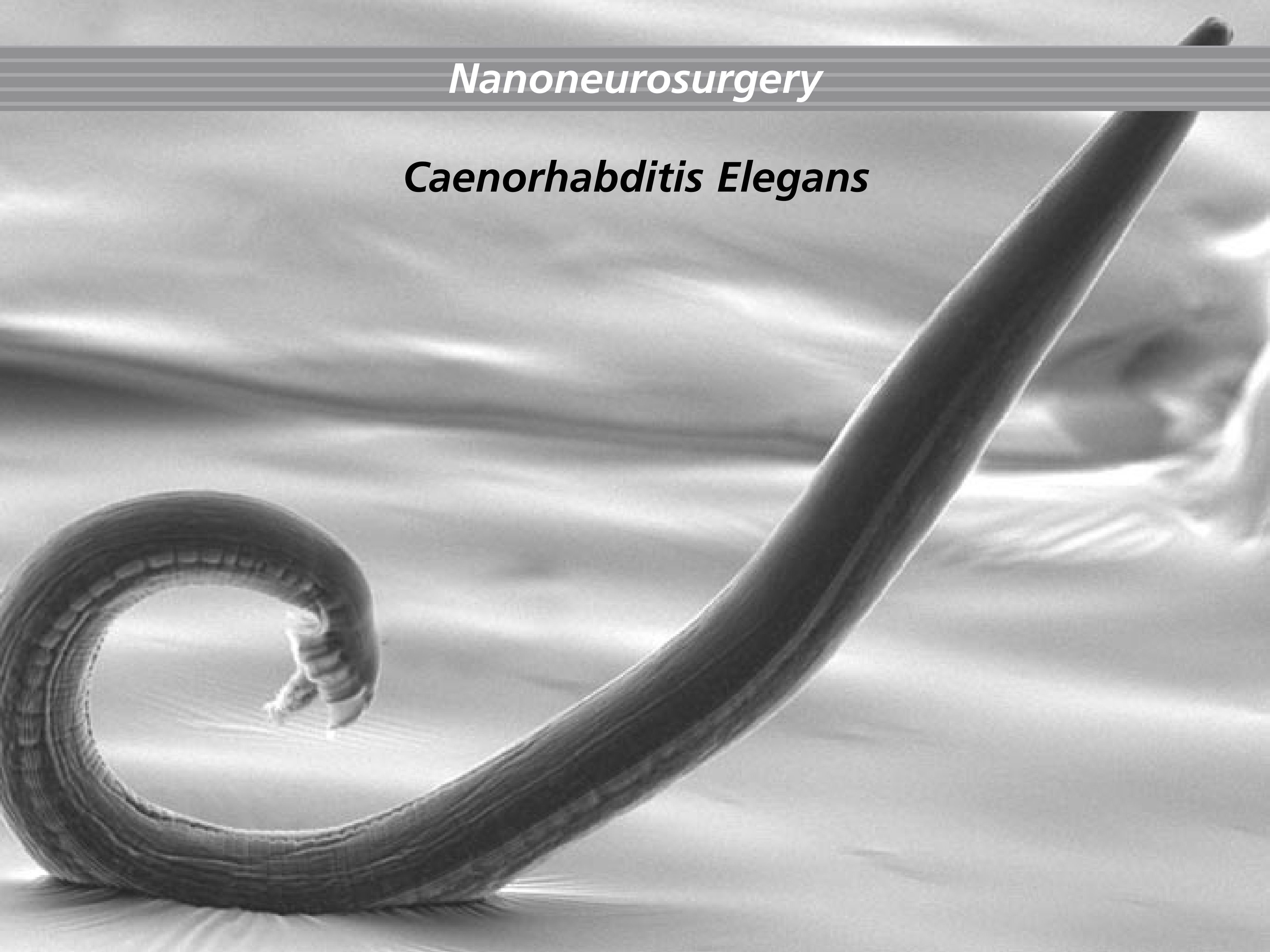
Caenorhabditis Elegans



Bob Goldstein, UNC Chapel Hill

Nanoneurosurgery

Caenorhabditis Elegans

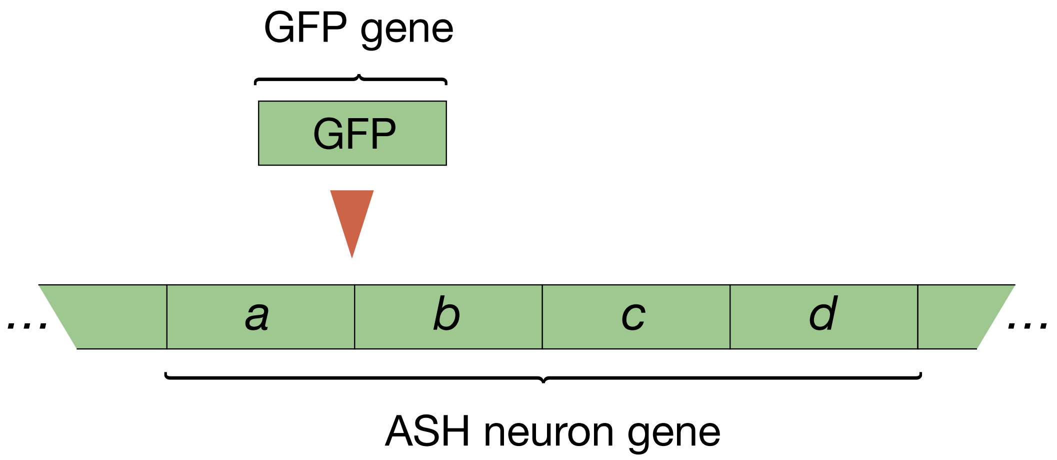


Nanoneurosurgery

ASH neurons

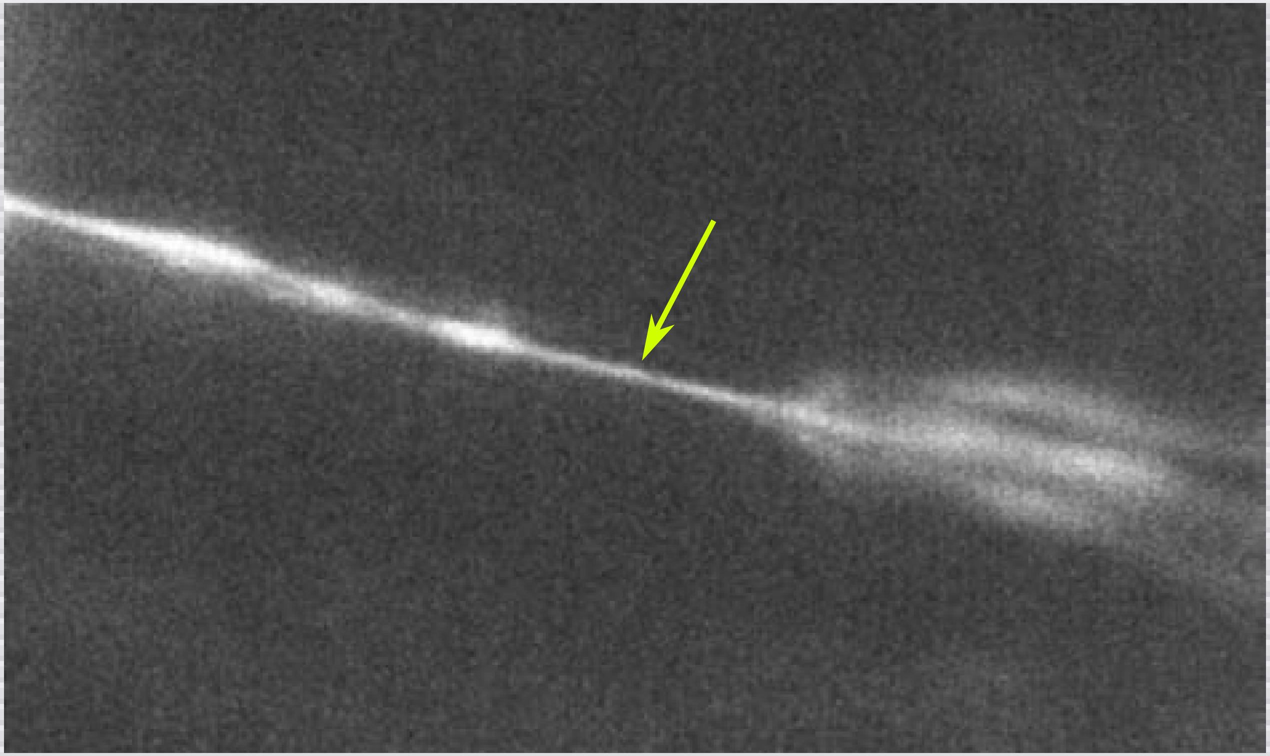
- responsible for osmotic avoidance
- ciliary projections extend through skin
- one on each side

make ASH neurons express GFP

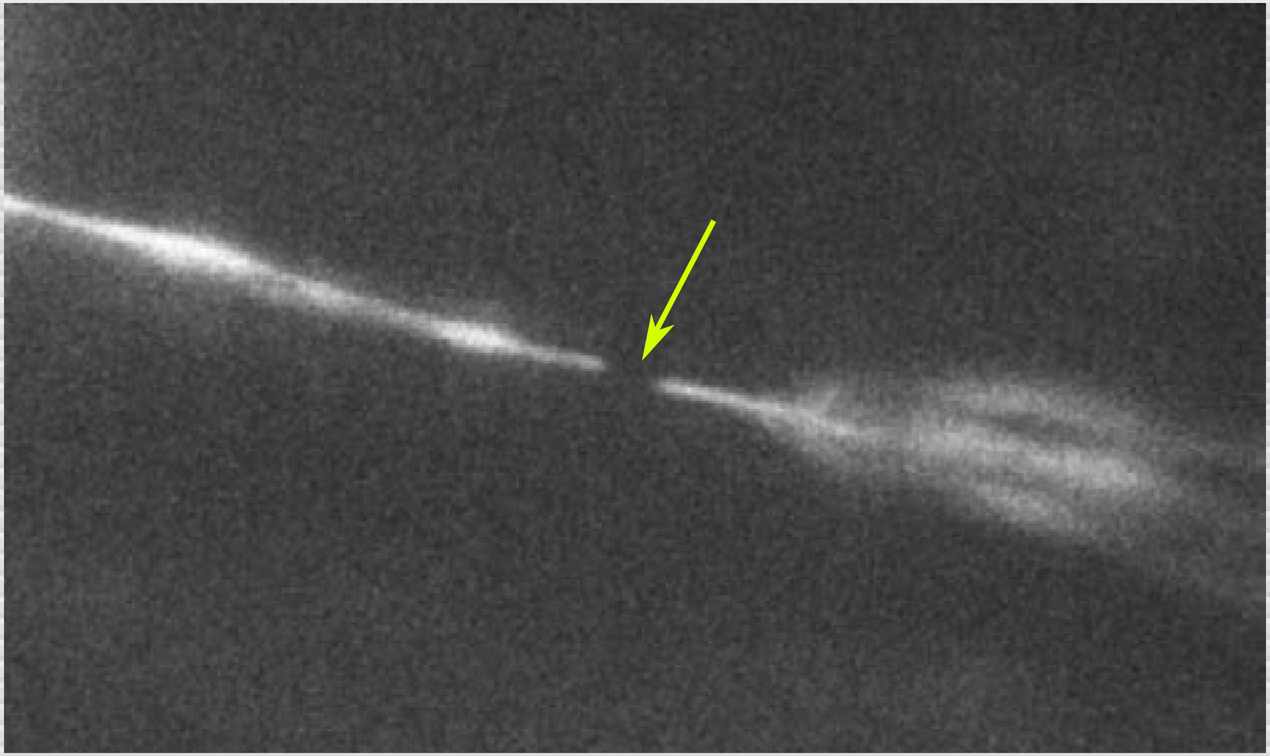


GFP: absorbs UV, emits green

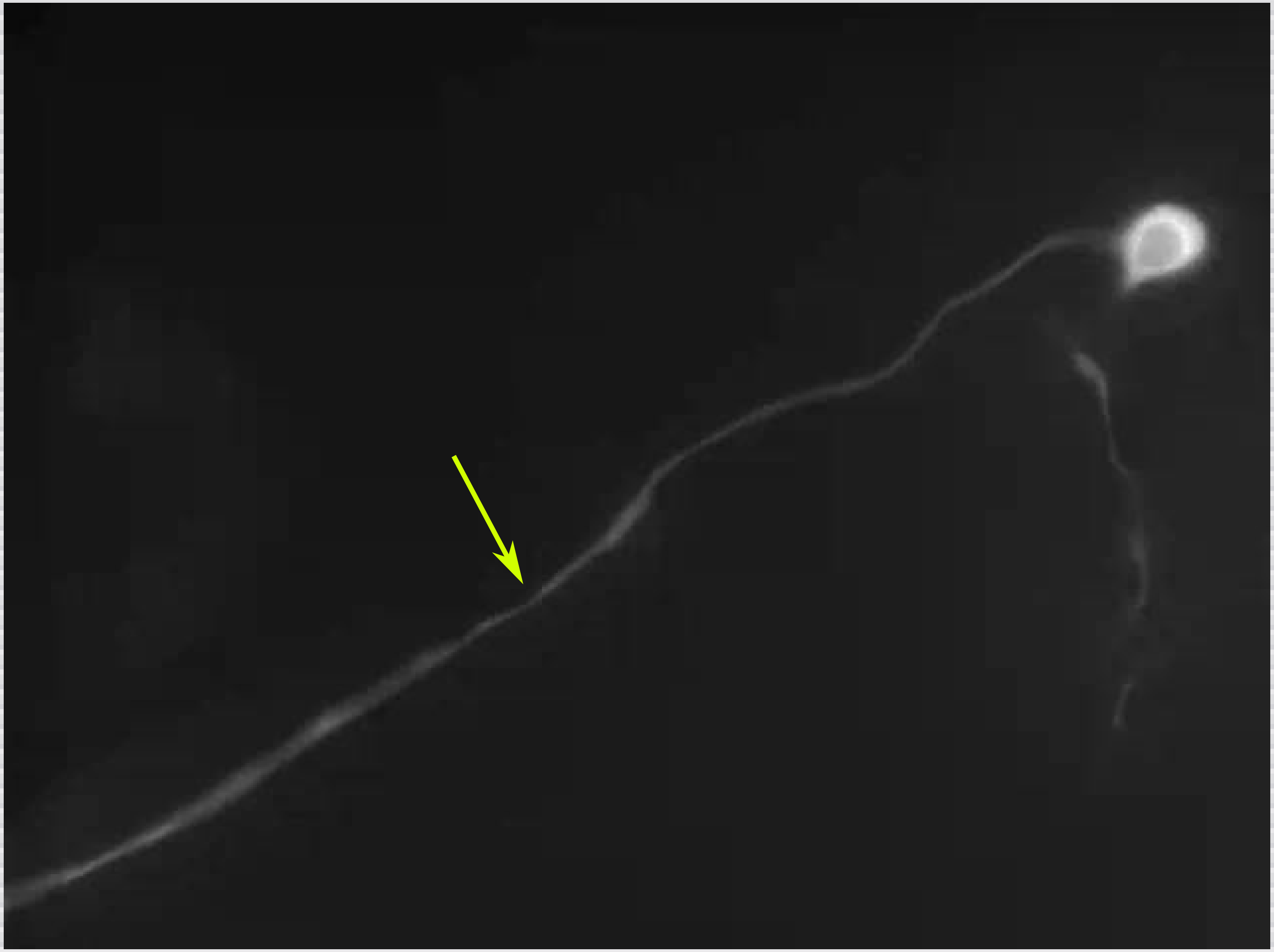
cutting an axon



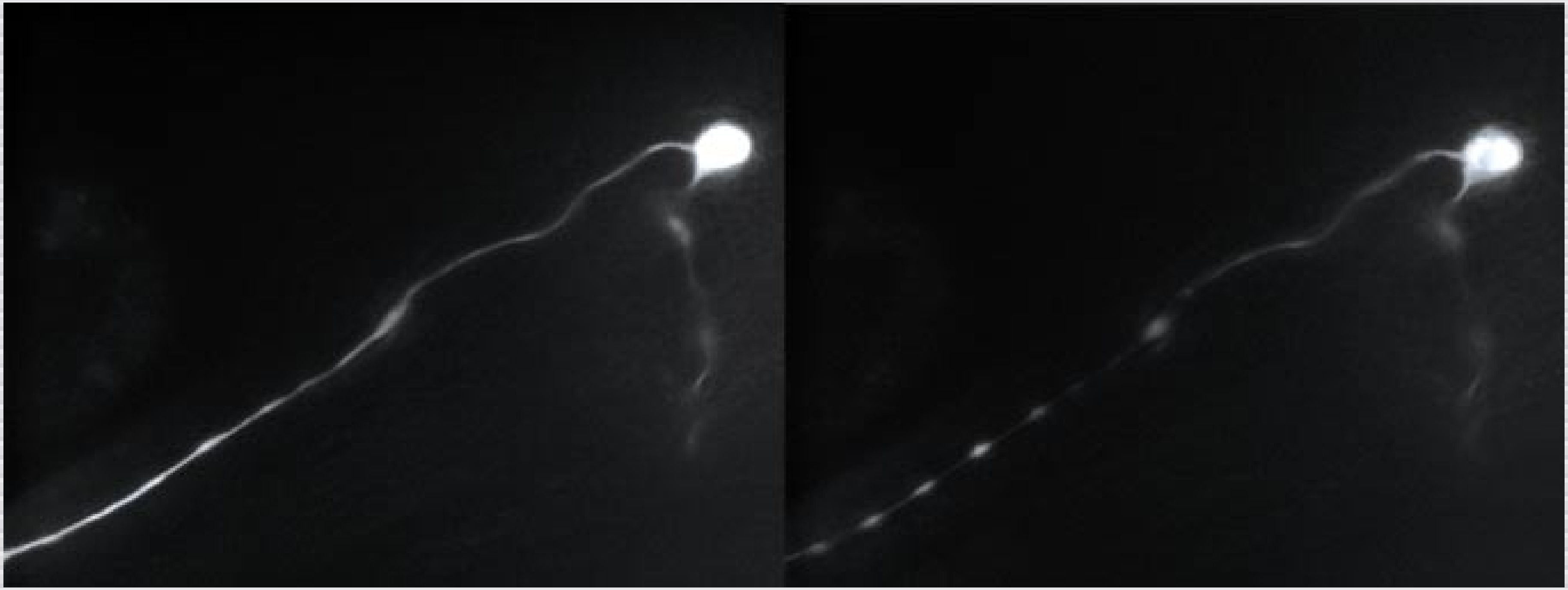
cutting an axon



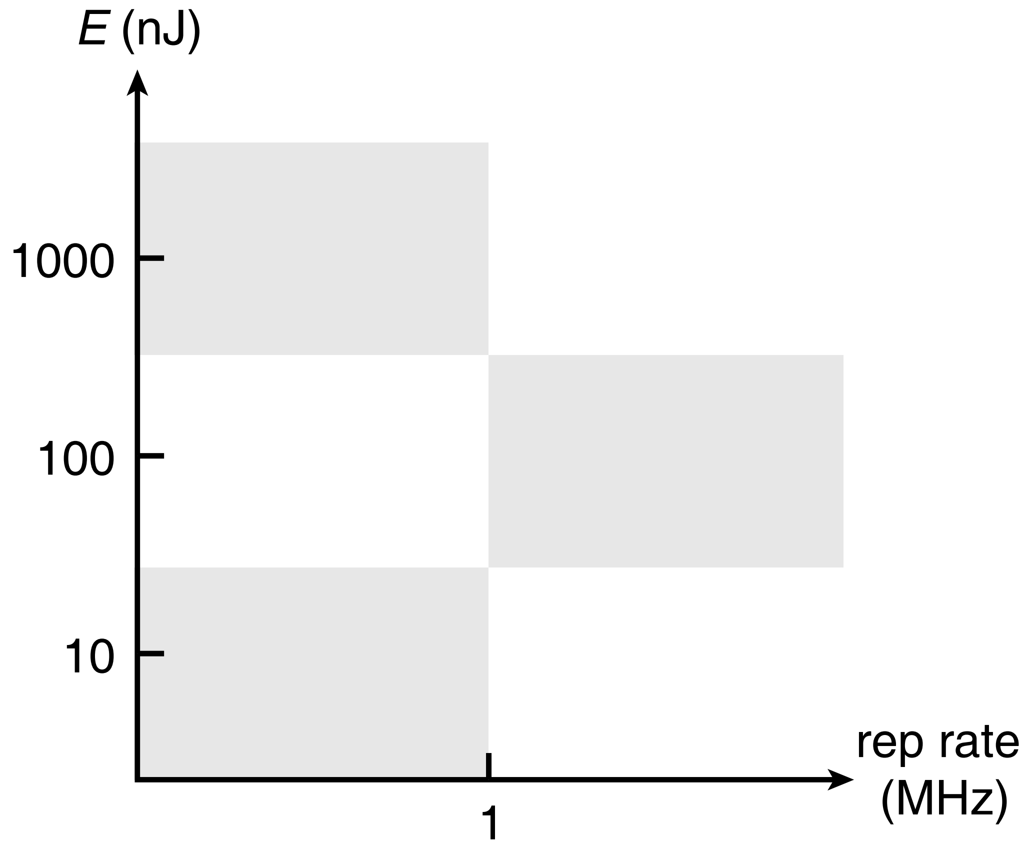
pearling instability



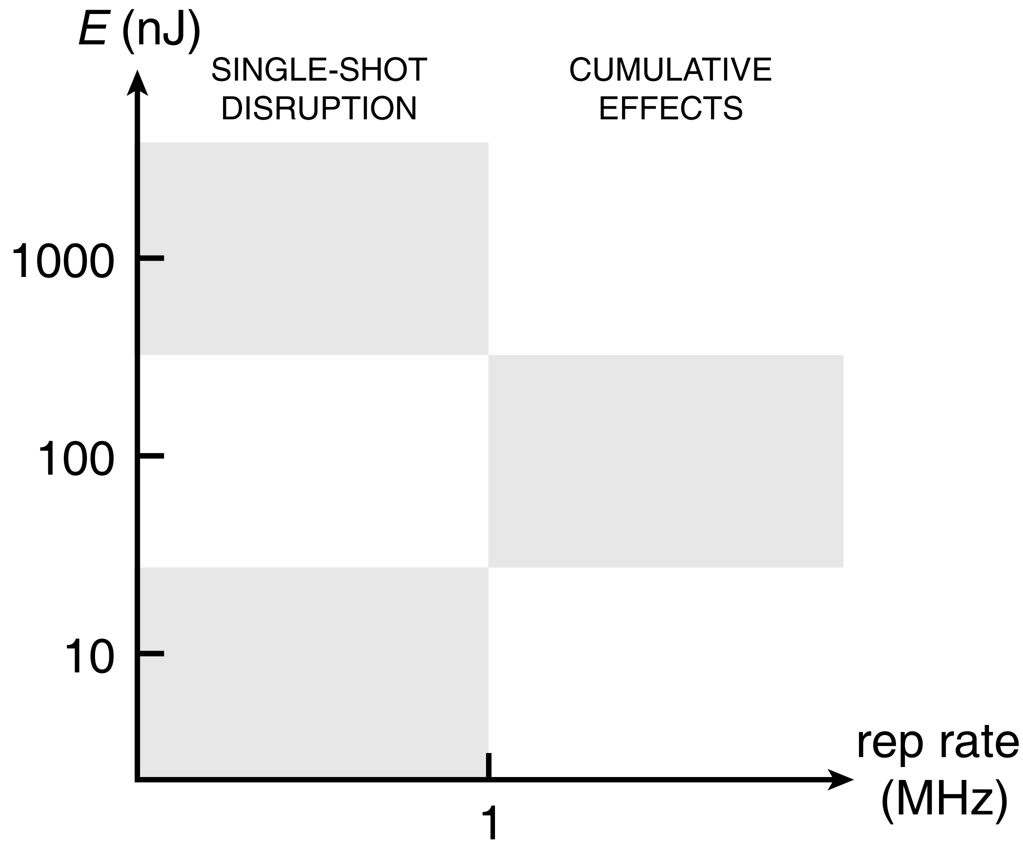
pearling instability



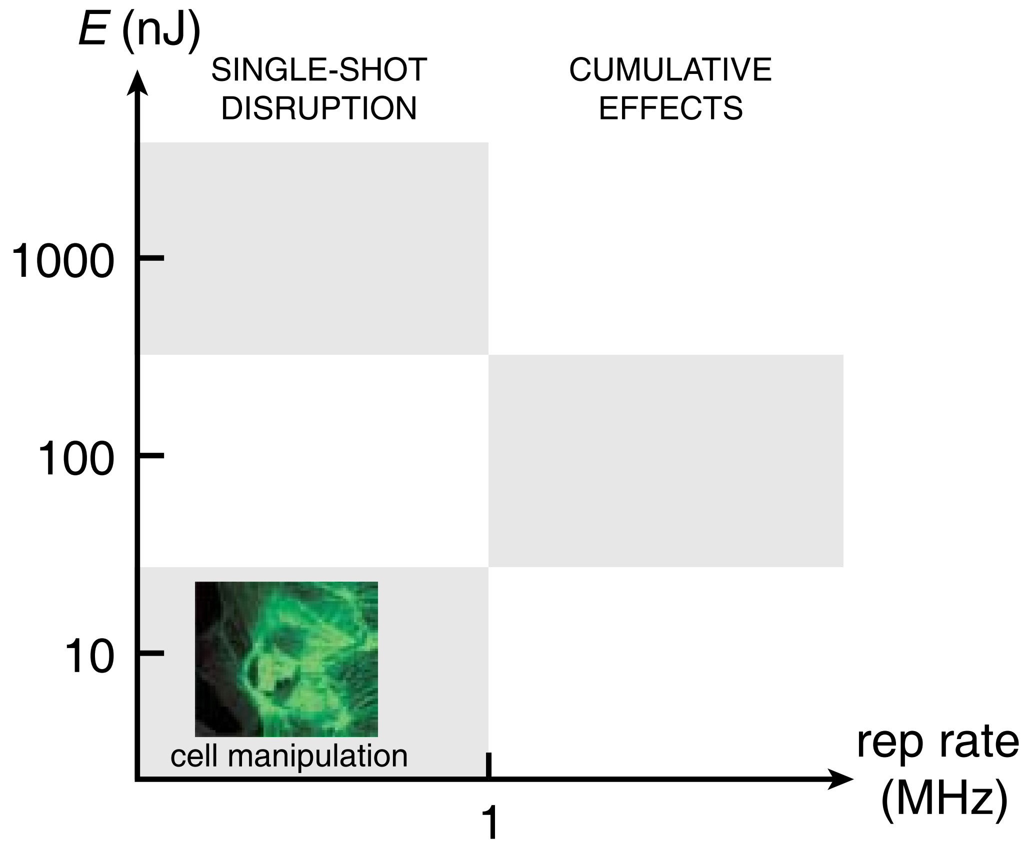
Summary



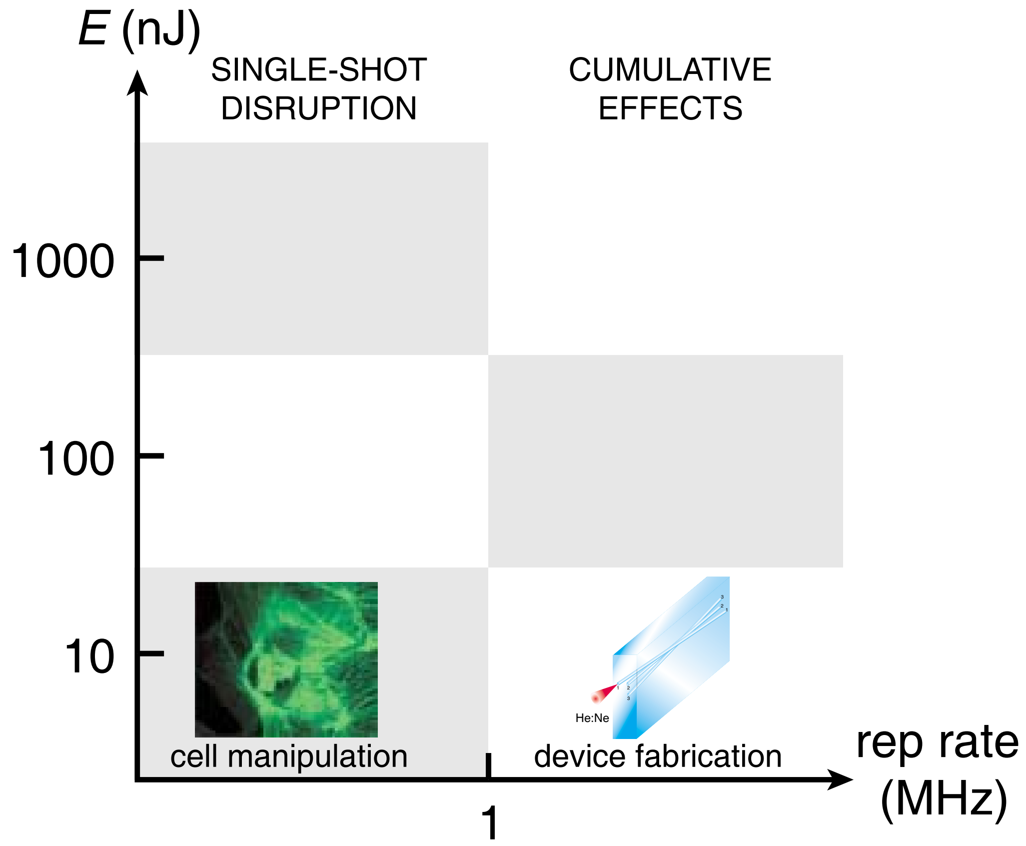
Summary


E (nJ)
SINGLE-SHOT
DISRUPTION
CUMULATIVE
EFFECTS
1000
100
10
1
rep rate
(MHz)

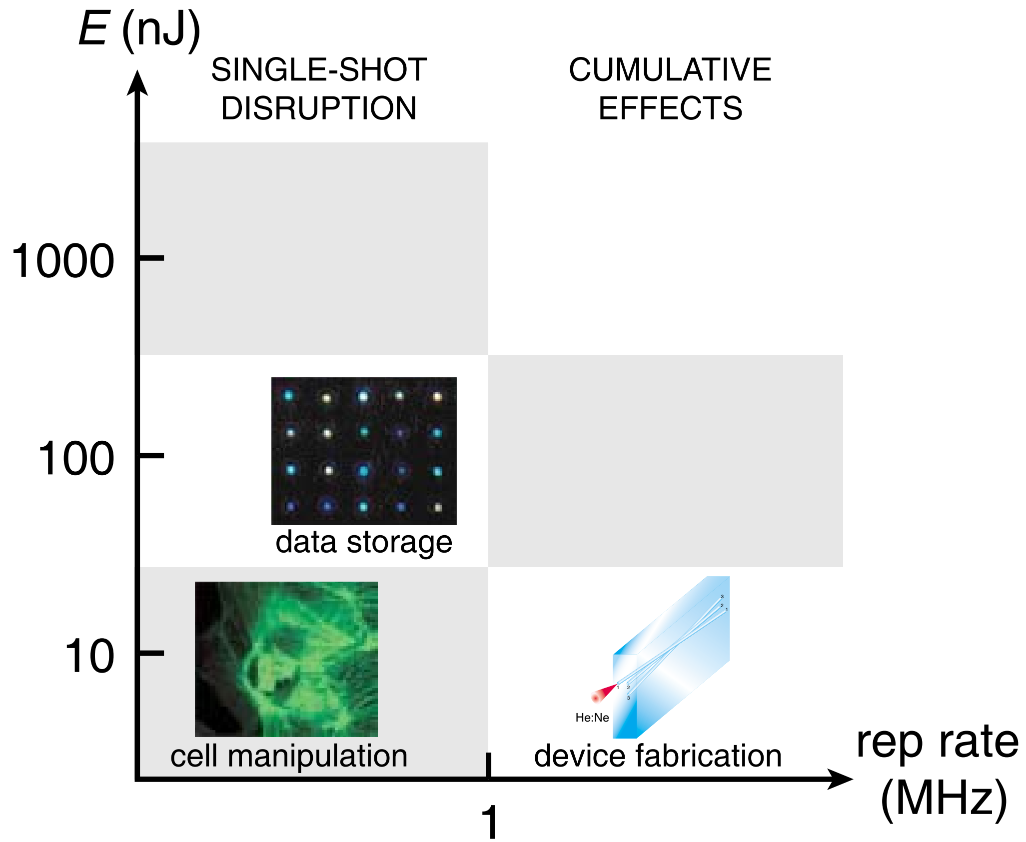
Summary


E (nJ)
SINGLE-SHOT DISRUPTION
CUMULATIVE EFFECTS
1000
100
10
cell manipulation
1
rep rate (MHz)

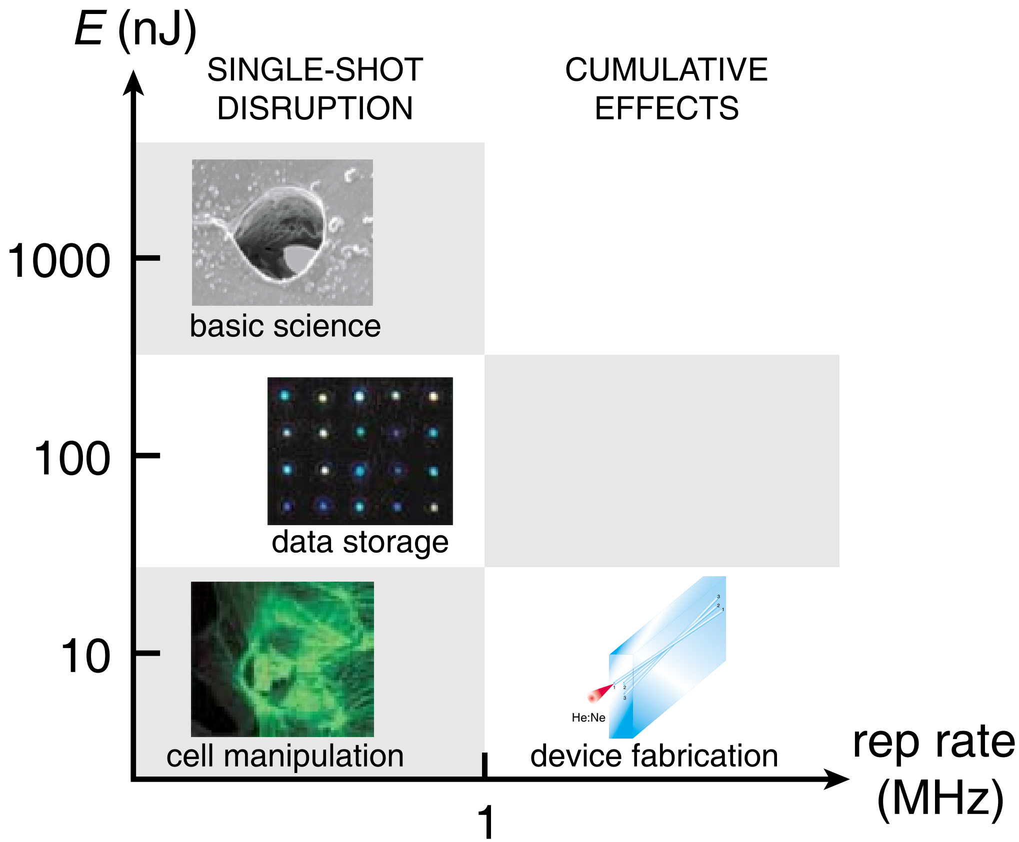
Summary


E (nJ)
SINGLE-SHOT
DISRUPTION
CUMULATIVE
EFFECTS
1000
100
10
He:Ne
cell manipulation
device fabrication
1
rep rate
(MHz)

Summary


E (nJ)
SINGLE-SHOT
DISRUPTION
CUMULATIVE
EFFECTS
1000
100
10
data storage
cell manipulation
He:Ne
device fabrication
1
rep rate
(MHz)

Summary


E (nJ)
SINGLE-SHOT DISRUPTION
CUMULATIVE EFFECTS
1000
100
10
basic science
data storage
cell manipulation
He:Ne
device fabrication
1
rep rate (MHz)

Conclusion

- **wiring optoelectronics circuits of the future**
- **manipulating the machinery of life**


GORDON McKAY
LABORATORY OF
APPLIED SCIENCE

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Harvard Office of Technology and Trademark Licensing

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Willie Leight (Yale University)
Yossi Chai (Sagitta, Inc.)

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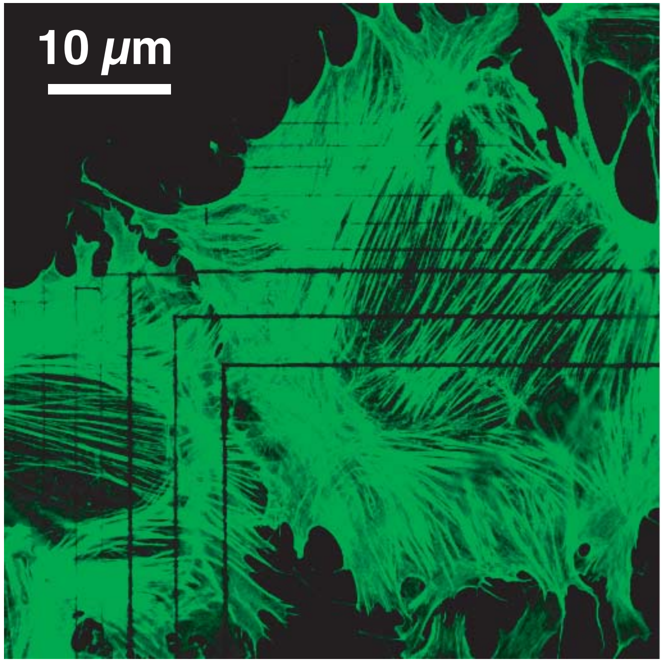
http://mazur-www.harvard.edu

bleaching or disruption?



bleaching or disruption?